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(54) **LIQUID CRYSTAL DISPLAY DEVICE**

Publication Classification

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(52) **U.S. Cl.** 345/87

(57) **ABSTRACT**

A liquid crystal display device can suppress the local temperature elevation of a liquid crystal in the vicinity of drivers. On a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via the switching element, and a reference electrode which generates an electric field between the reference electrode and the pixel electrode are mounted on each pixel region of the liquid-crystal-side surface. The video signals from the drain signal line are generated by a driver chip mounted on one substrate. A light transmittivity of the liquid crystal layer is set to take a minimum value when a voltage is not applied between the pixel electrode and the reference electrode. A maximum amplitude of voltage of the video signals is set to a value not more than a voltage necessary for setting a relative transmittivity of the liquid crystal layer to 90%.

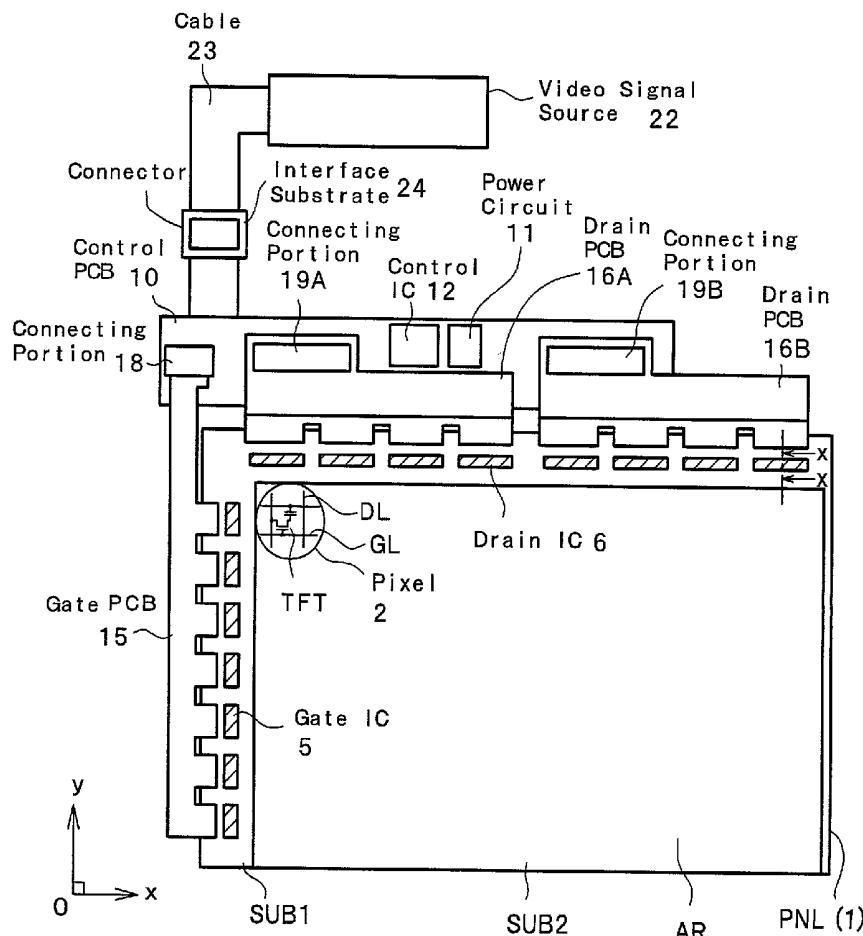
(73) Assignee: **Hitachi, Ltd.**

(21) Appl. No.: **09/948,953**

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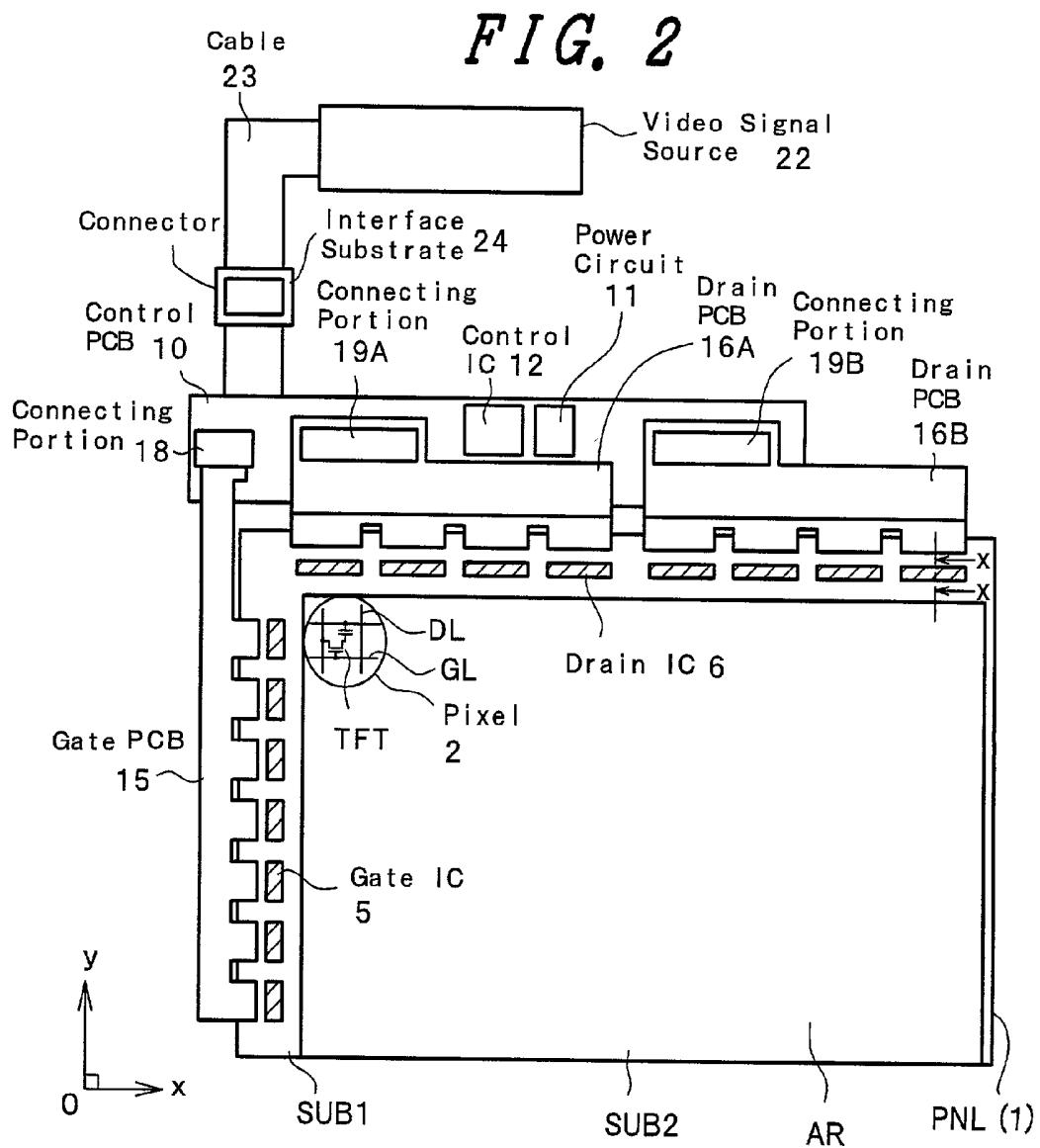
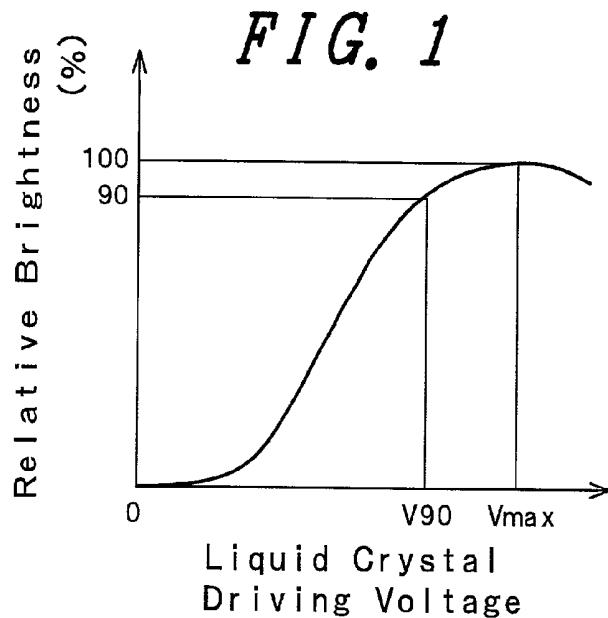


FIG. 3

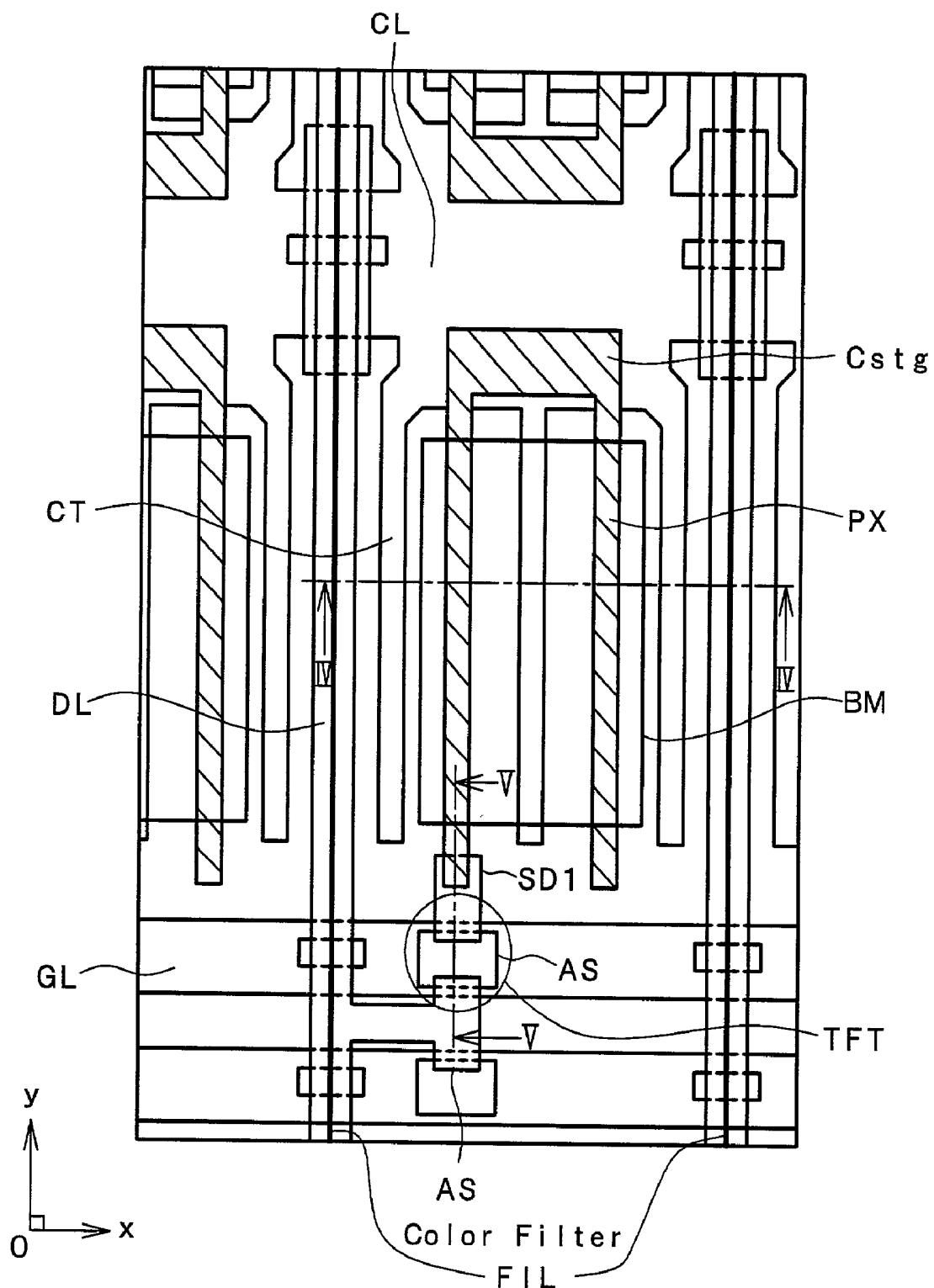


FIG. 4

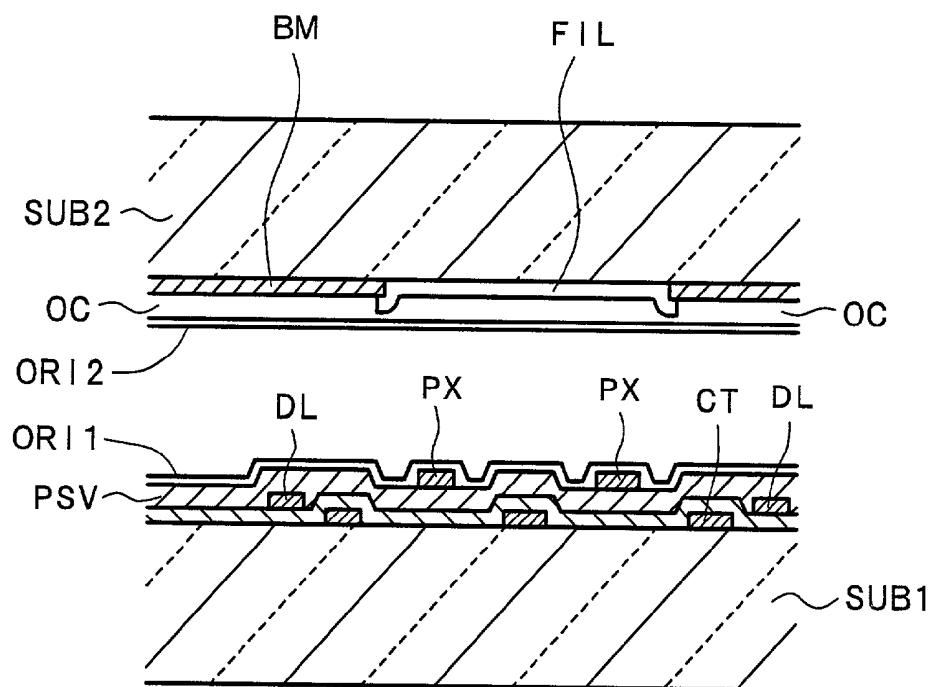


FIG. 5

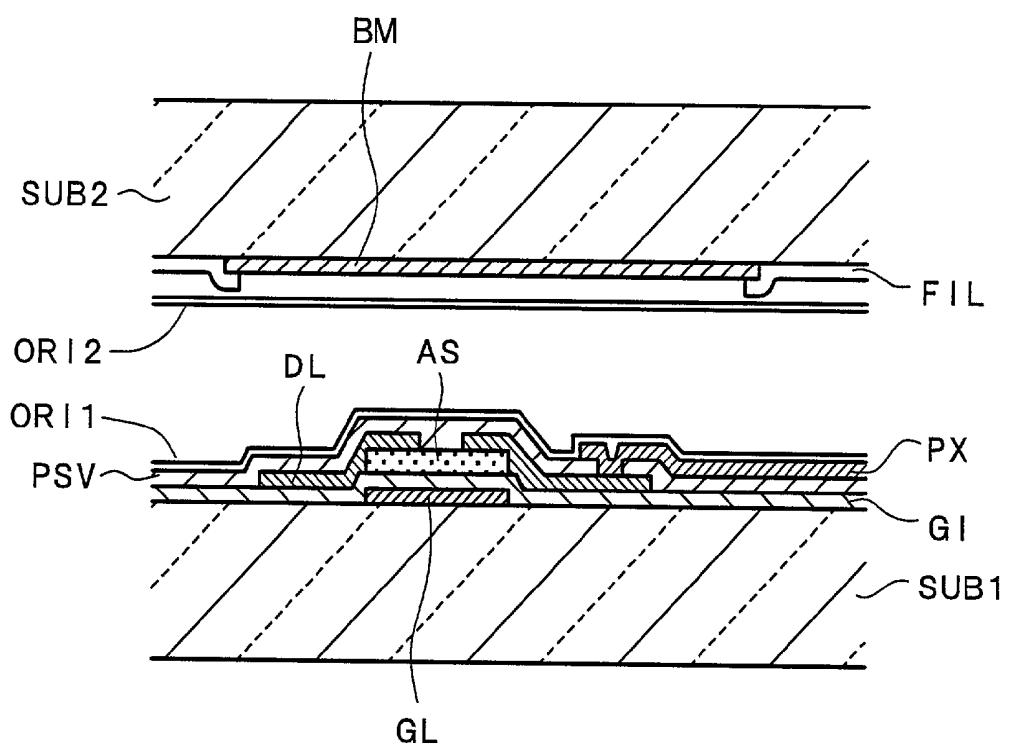


FIG. 6

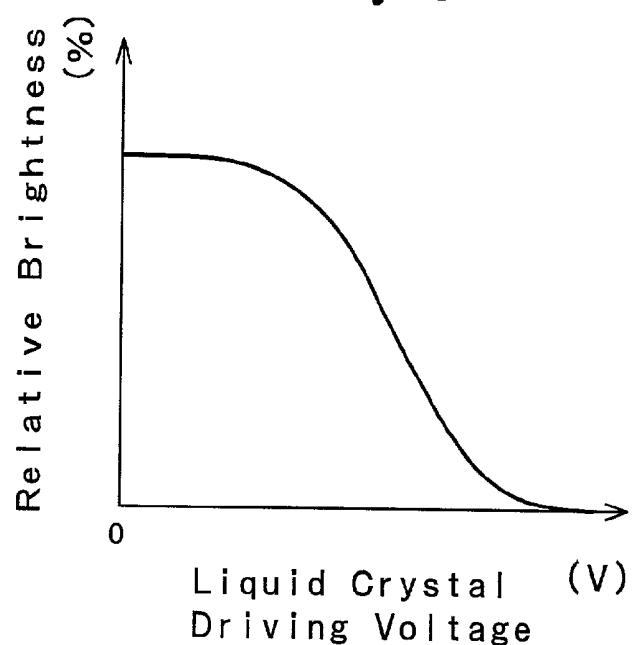


FIG. 7

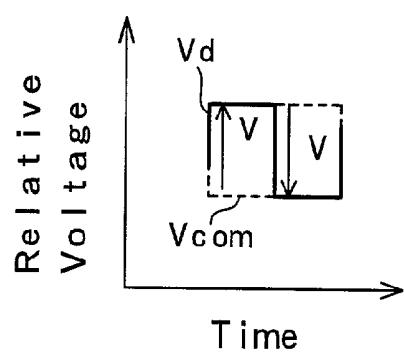


FIG. 8

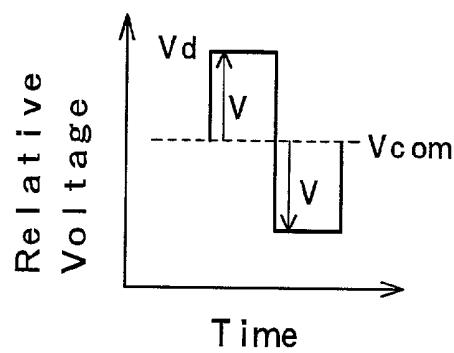


FIG. 9A *FIG. 9A*



FIG. 10A

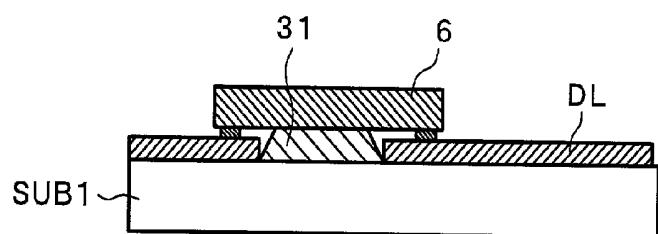


FIG. 10B

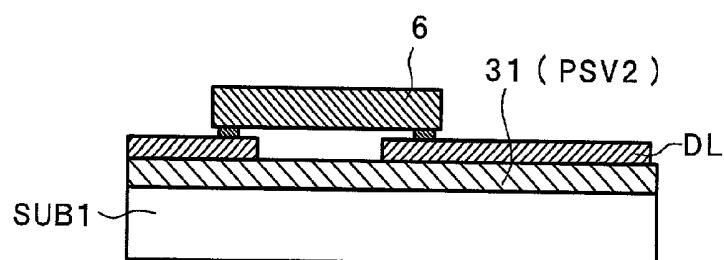


FIG. 11

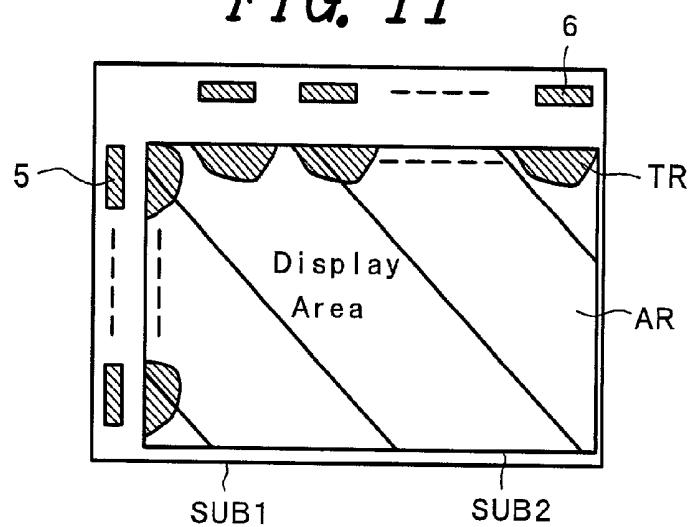


FIG. 12A

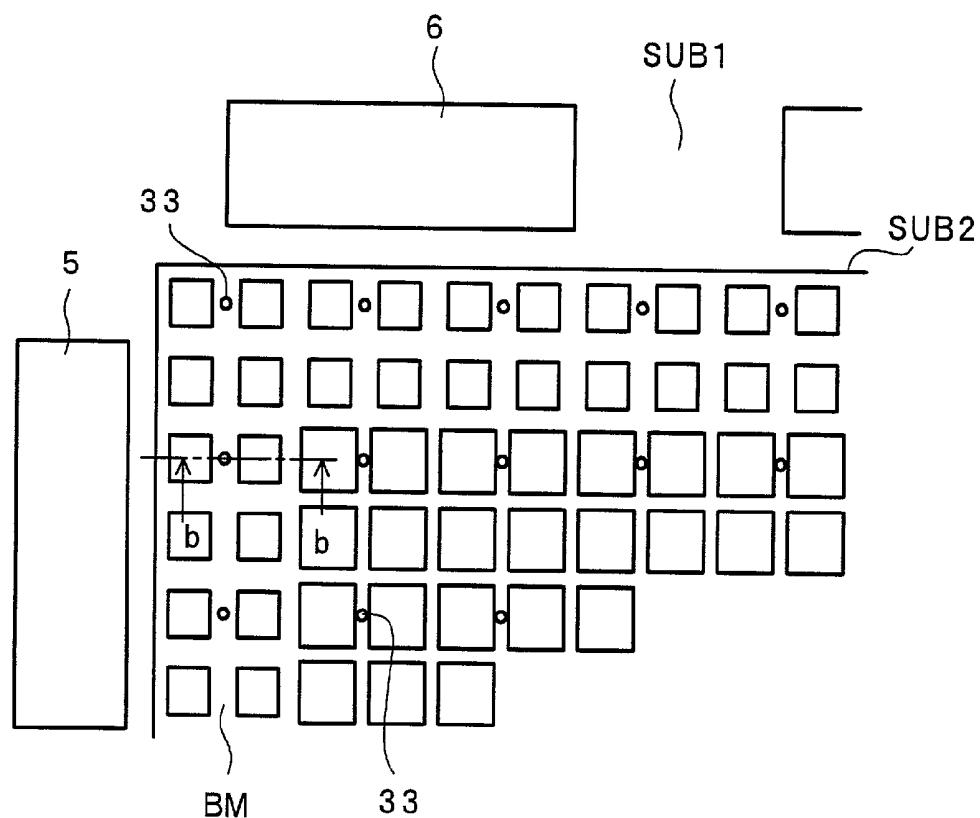


FIG. 12B

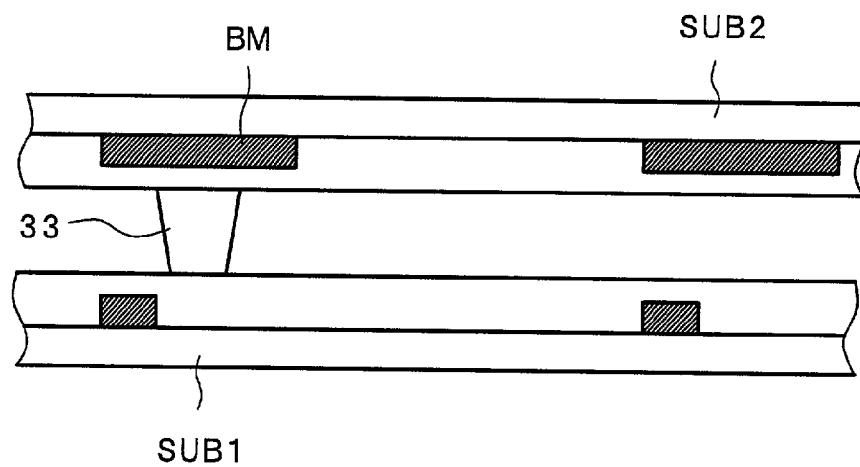


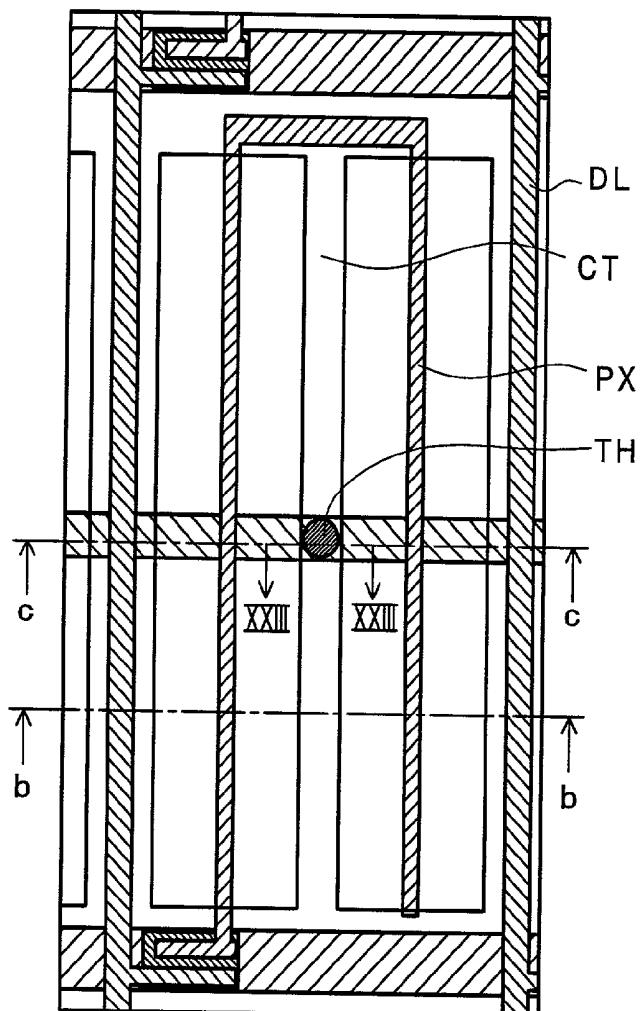
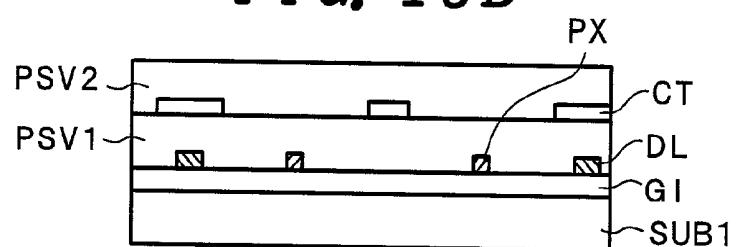
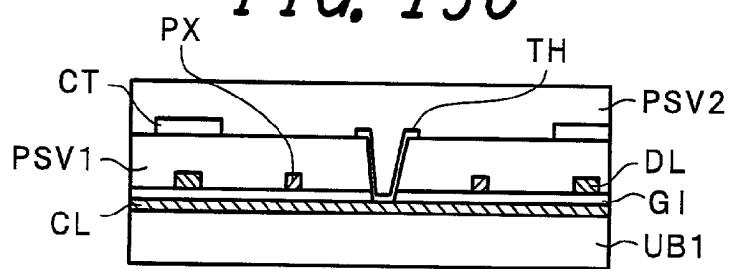
FIG. 13A*FIG. 13B**FIG. 13C*

FIG. 14

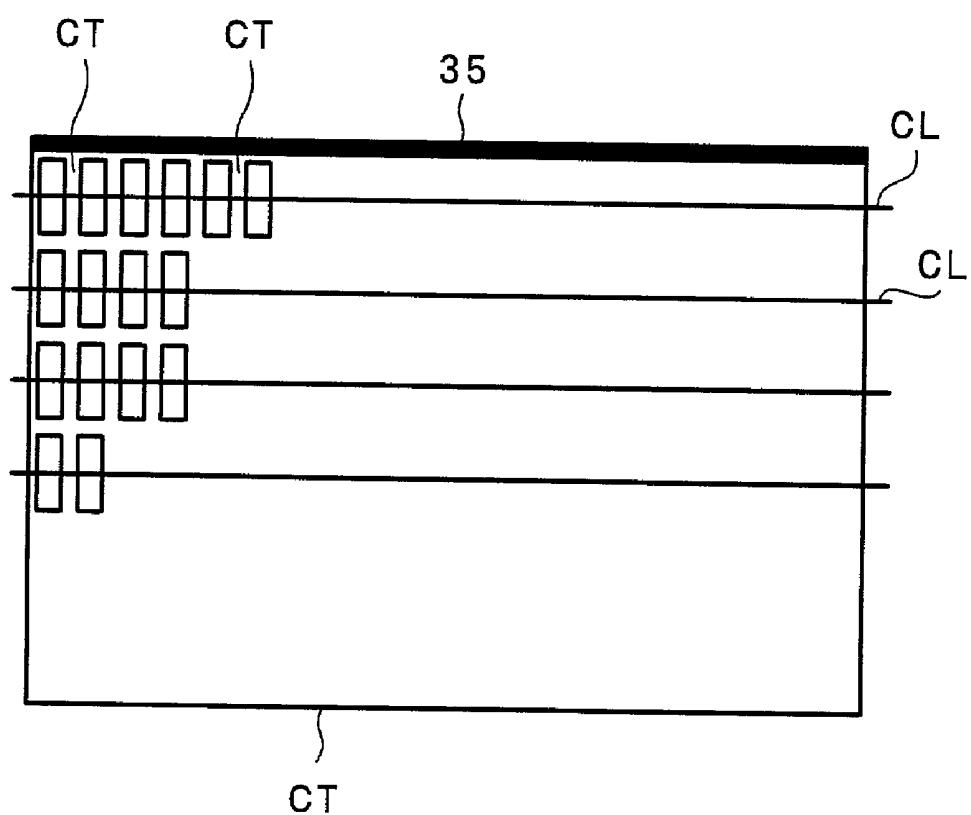


FIG. 15

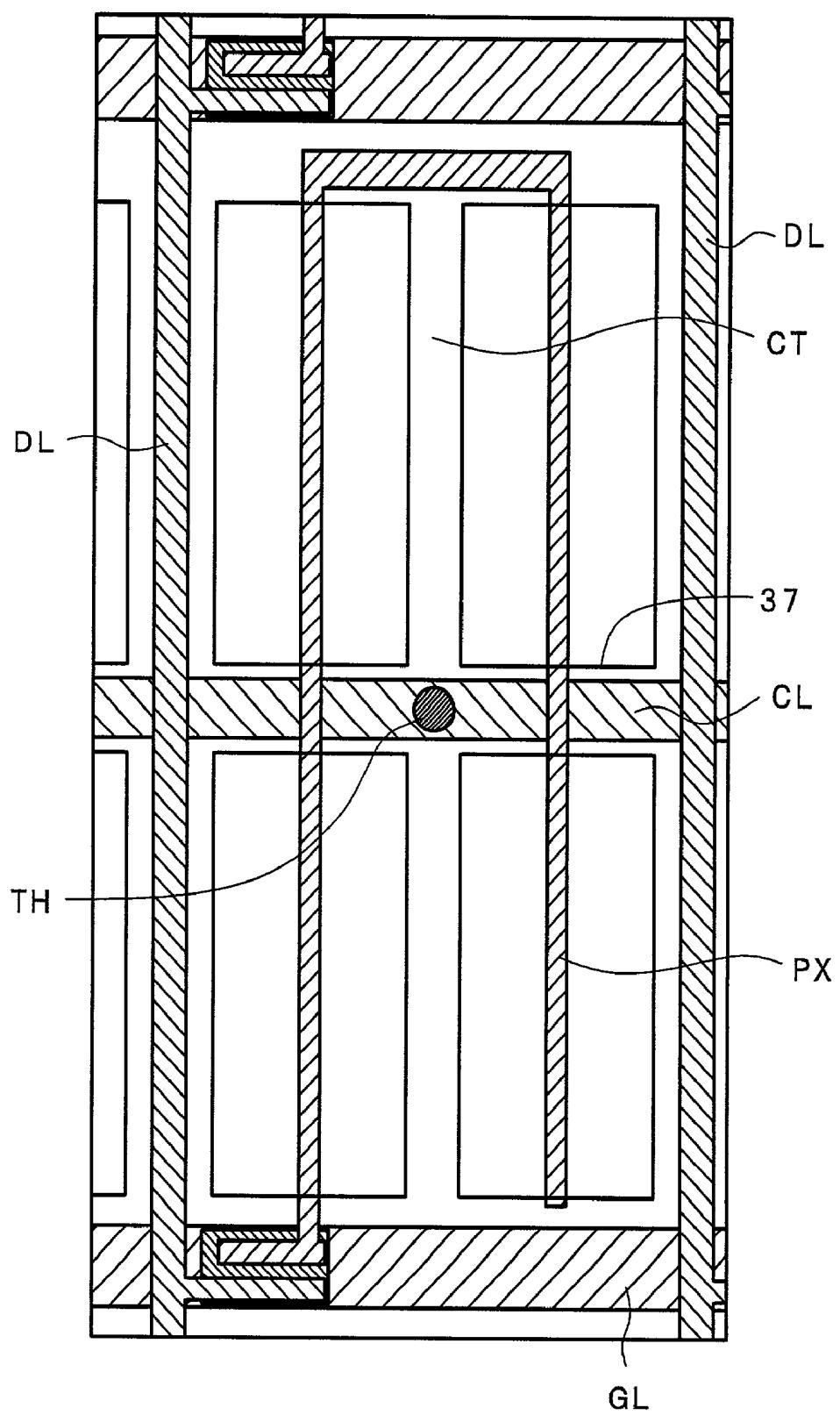


FIG. 16

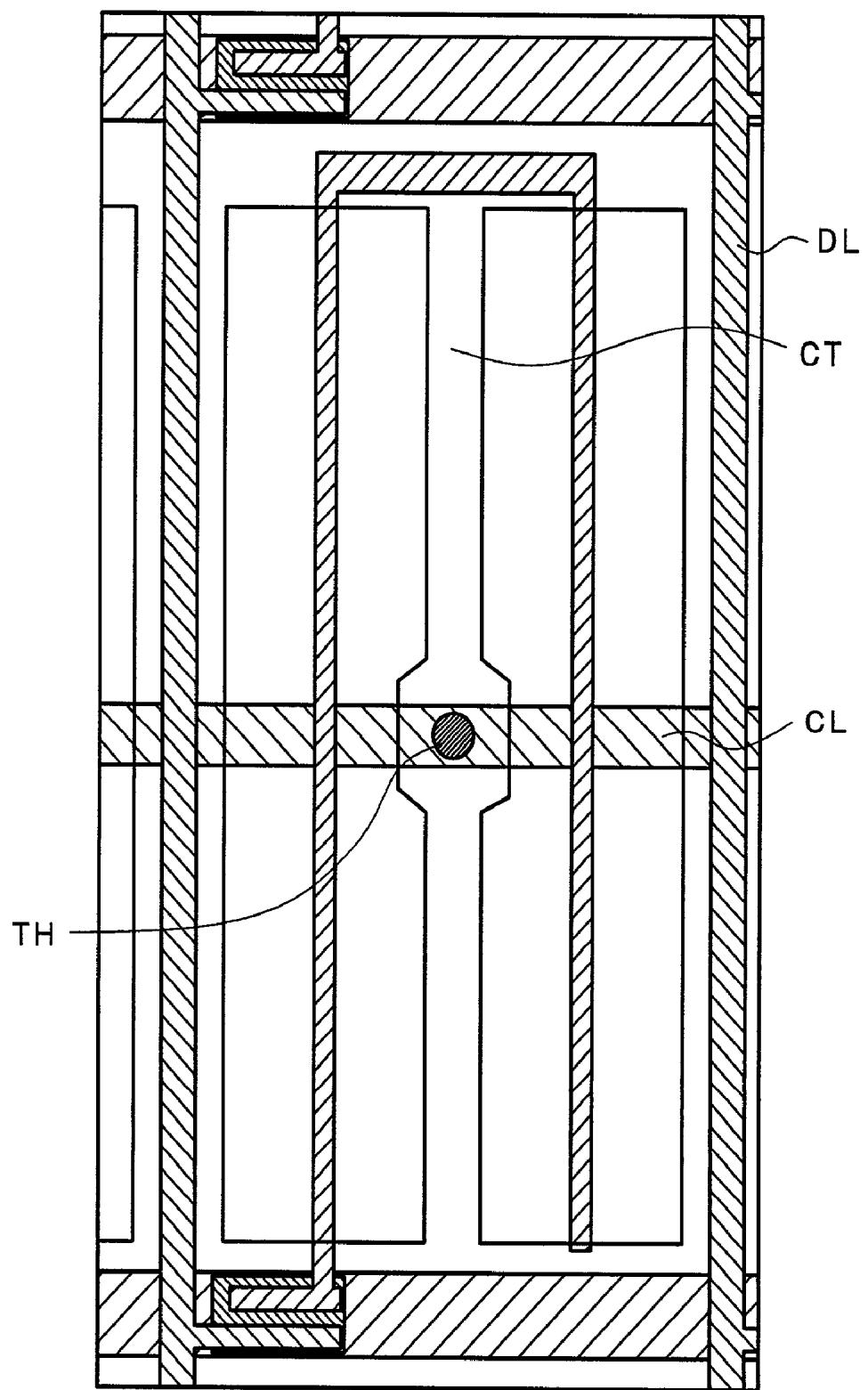


FIG. 17

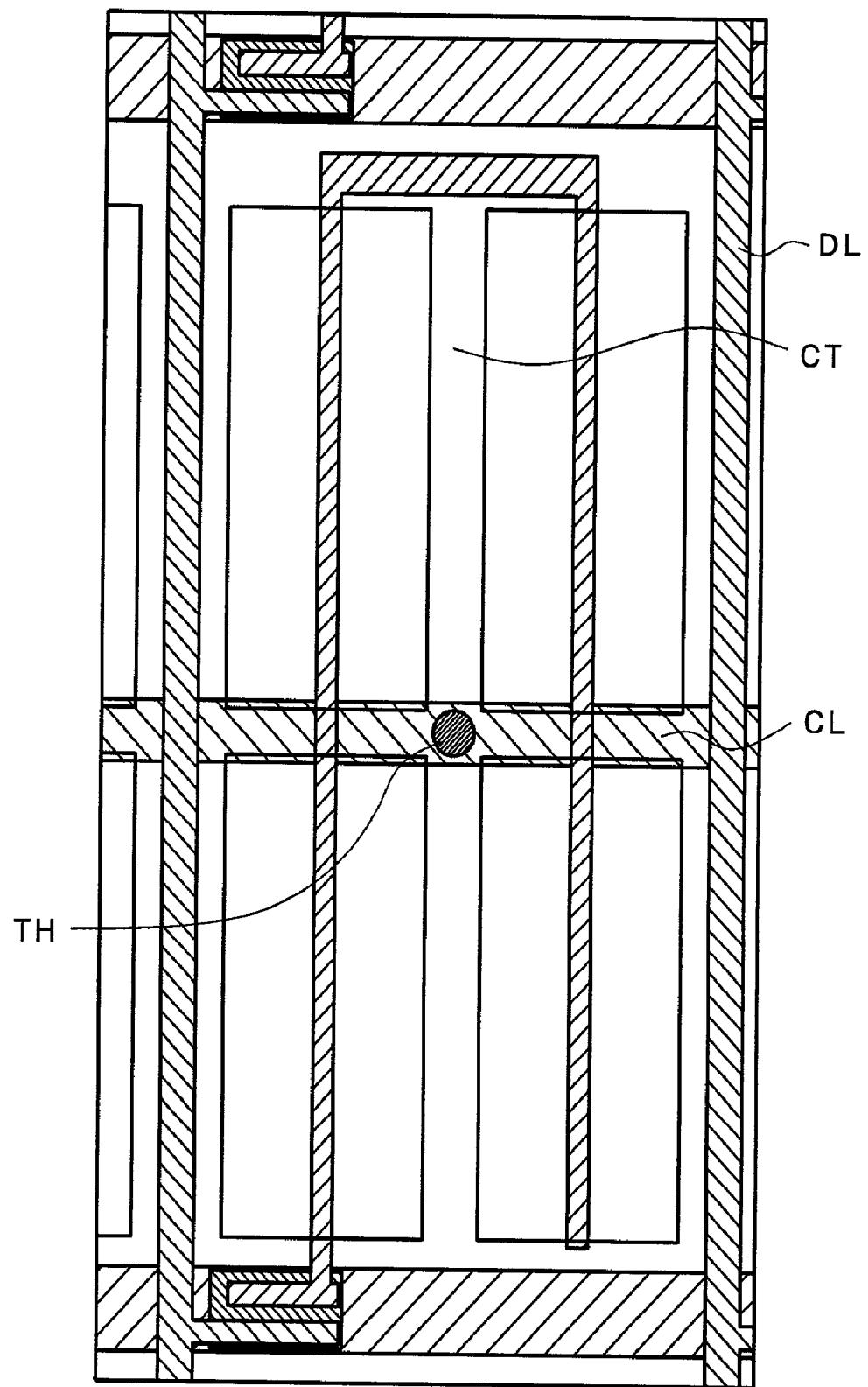


FIG. 18

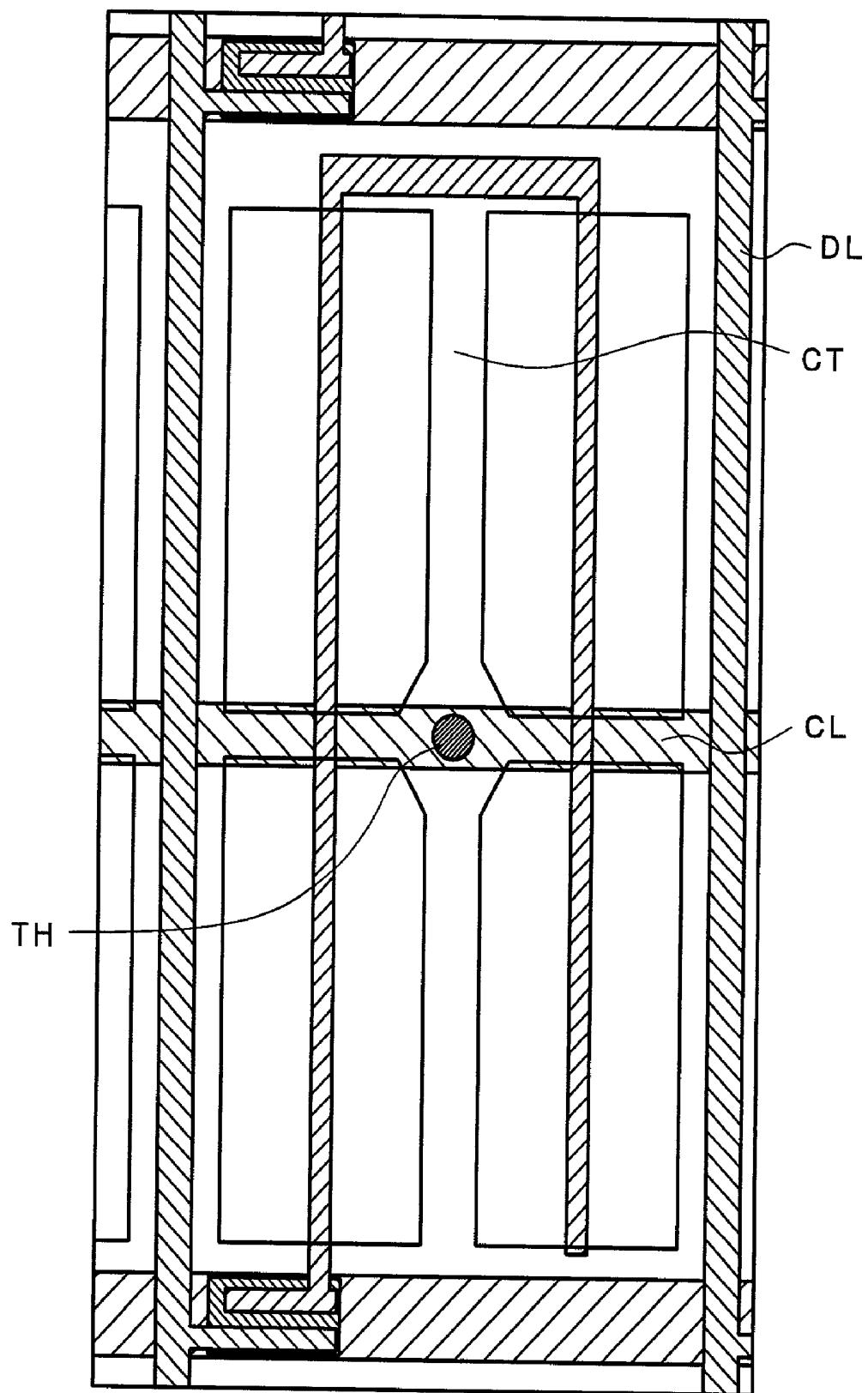


FIG. 19

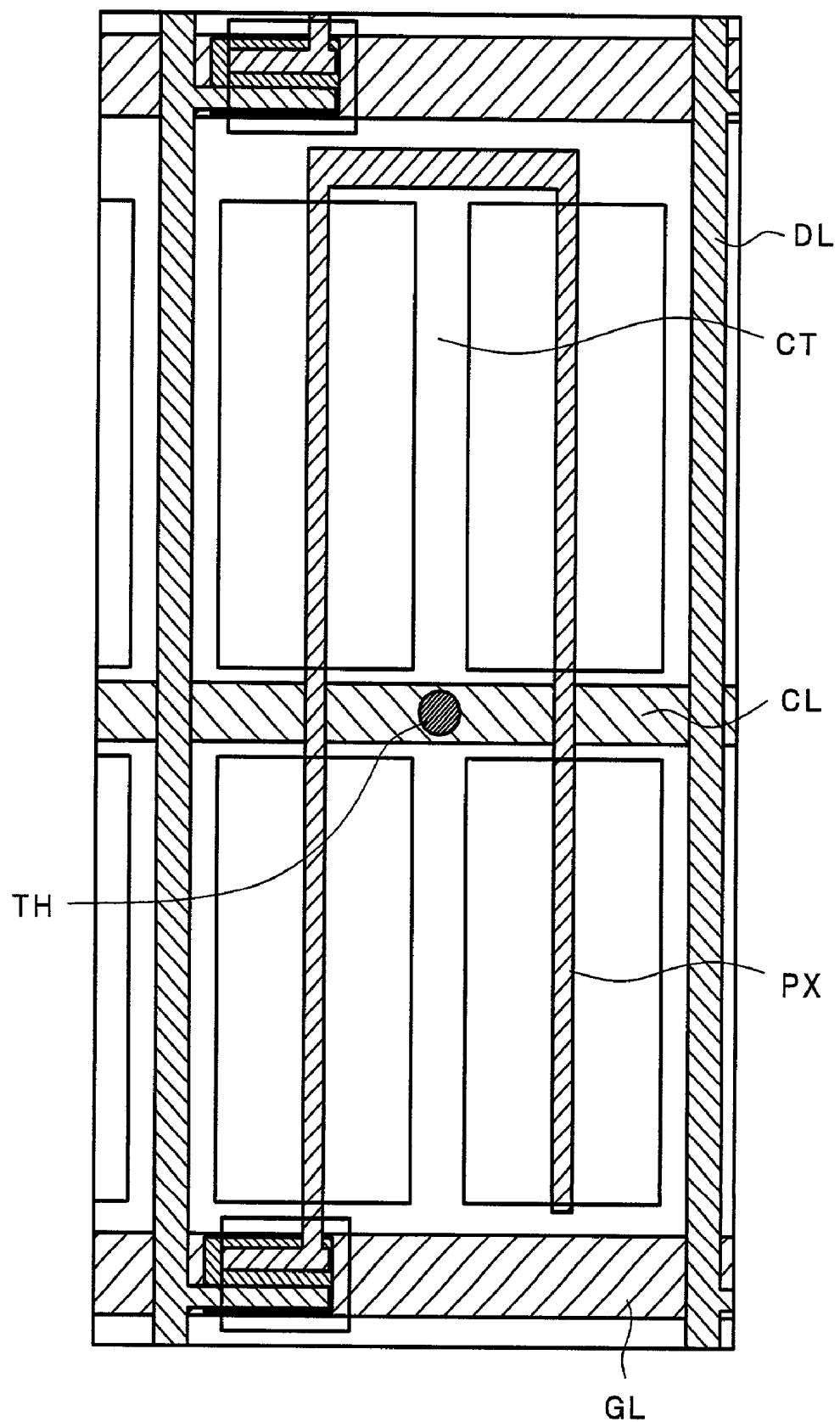


FIG. 20

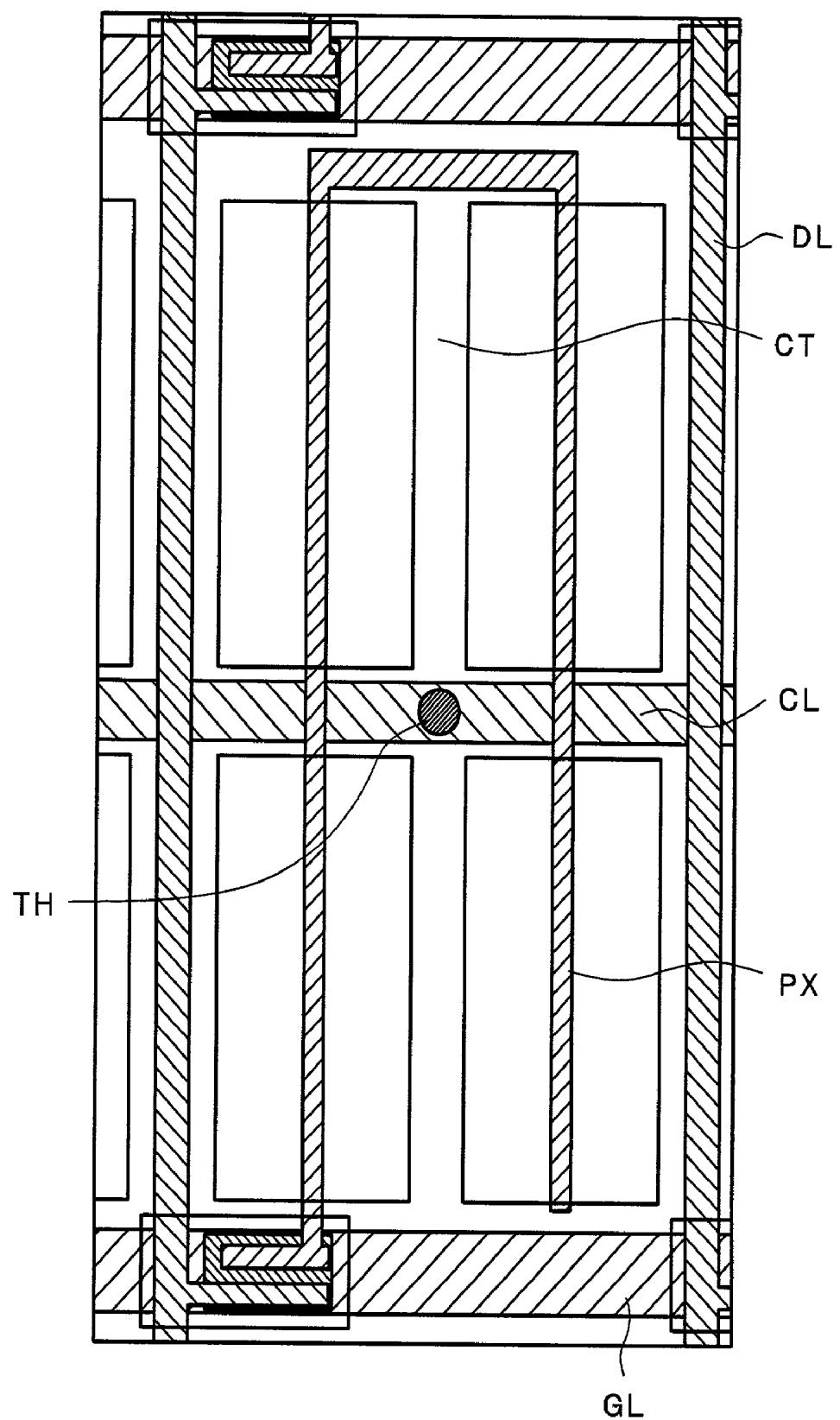


FIG. 21

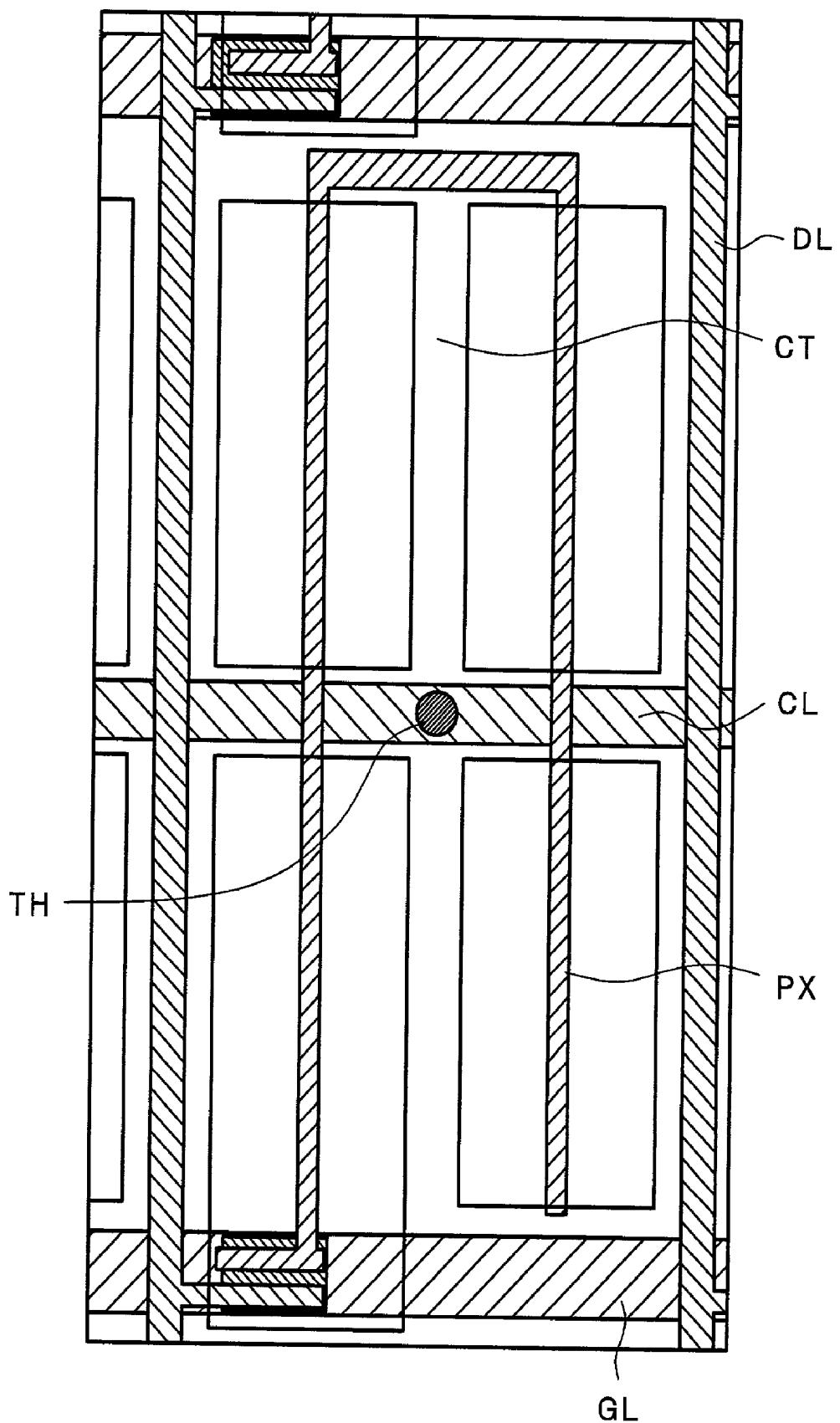


FIG. 22

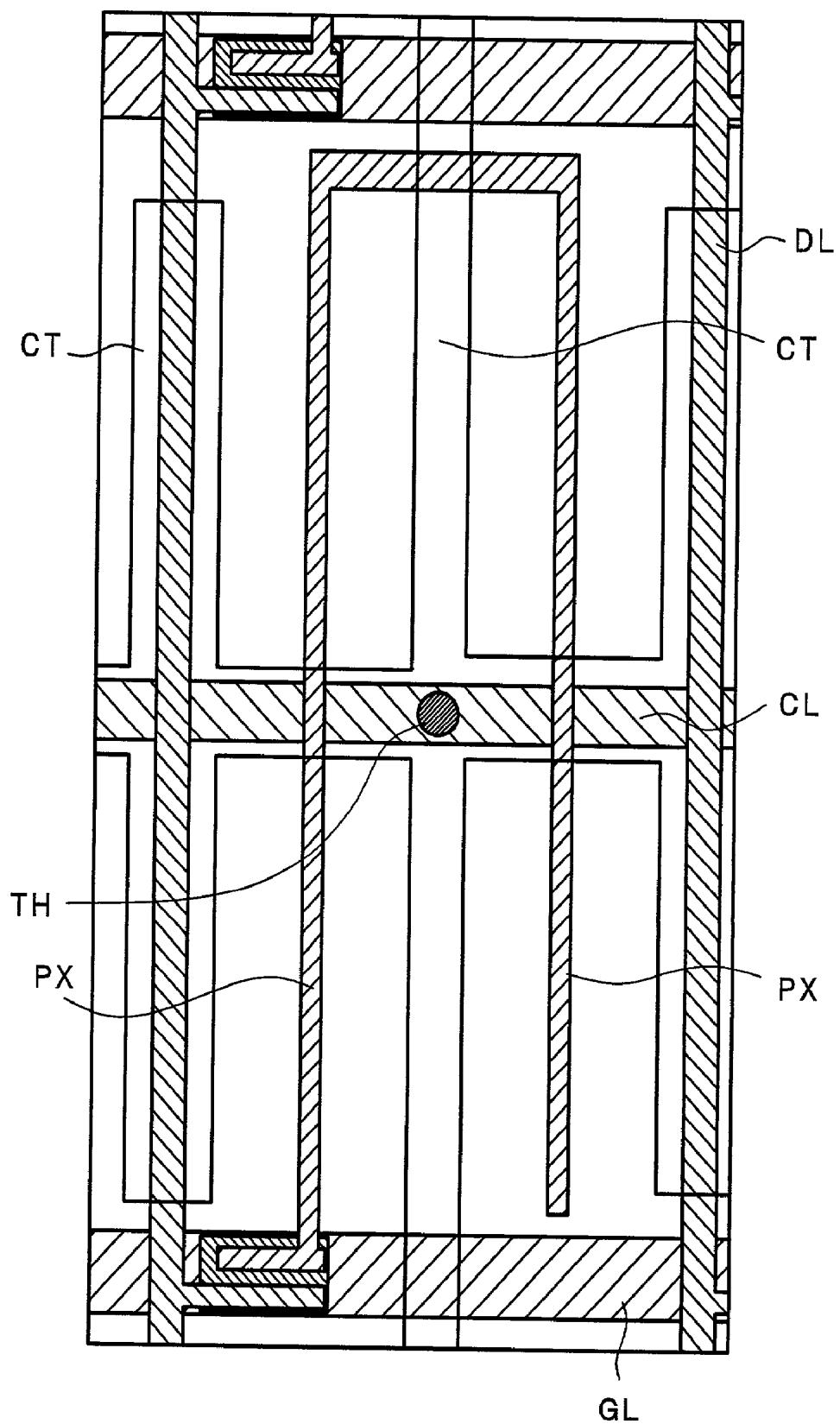


FIG. 23

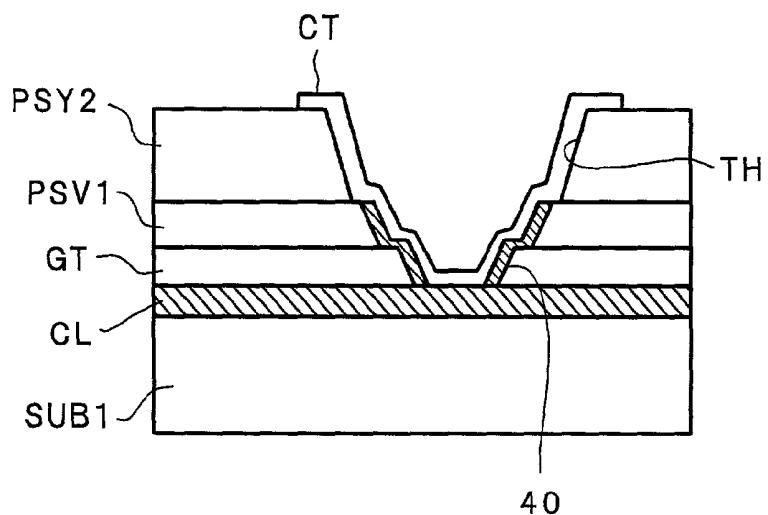


FIG. 24

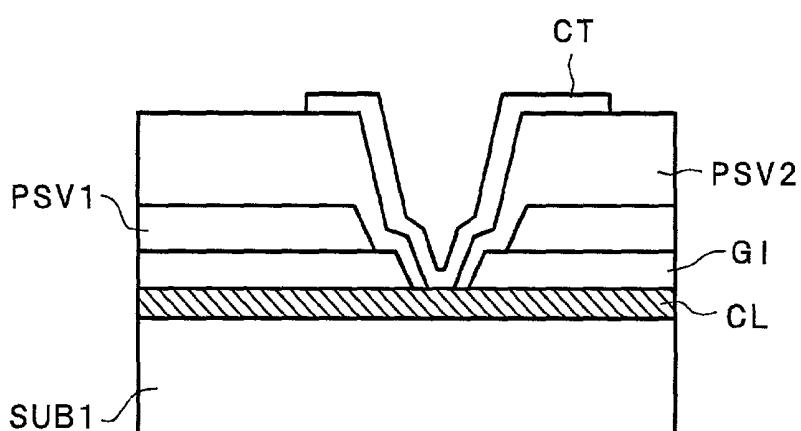


FIG. 25

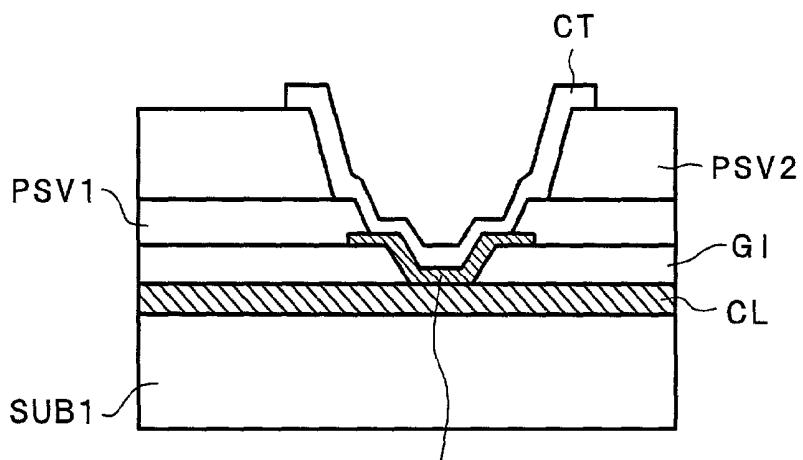


FIG. 26

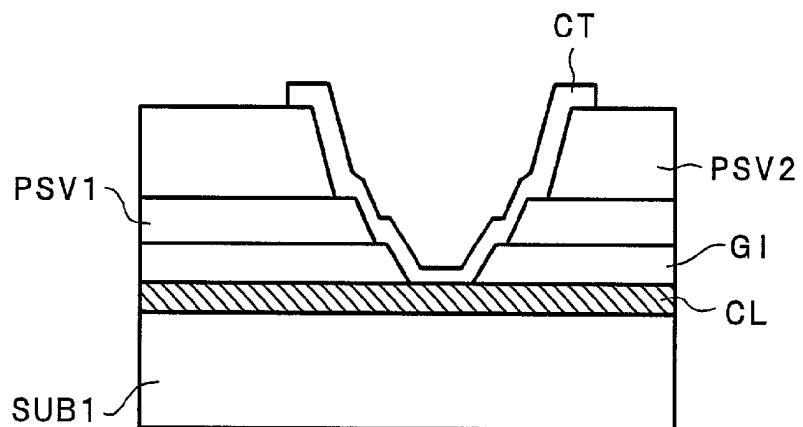


FIG. 27A

FIG. 27B

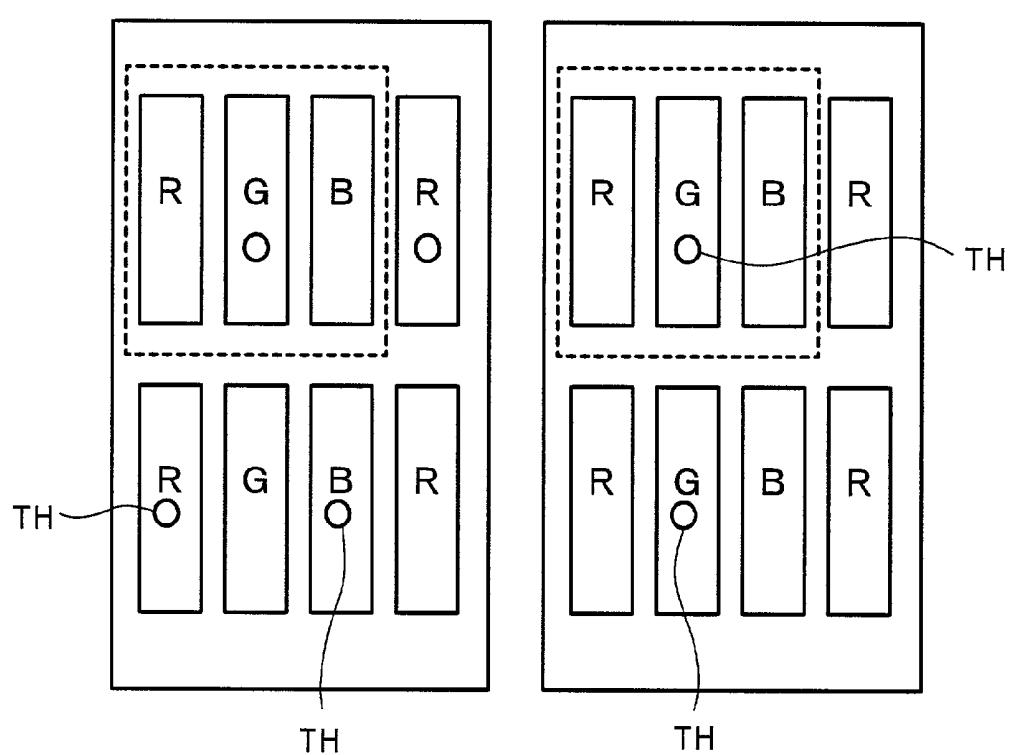


FIG. 28

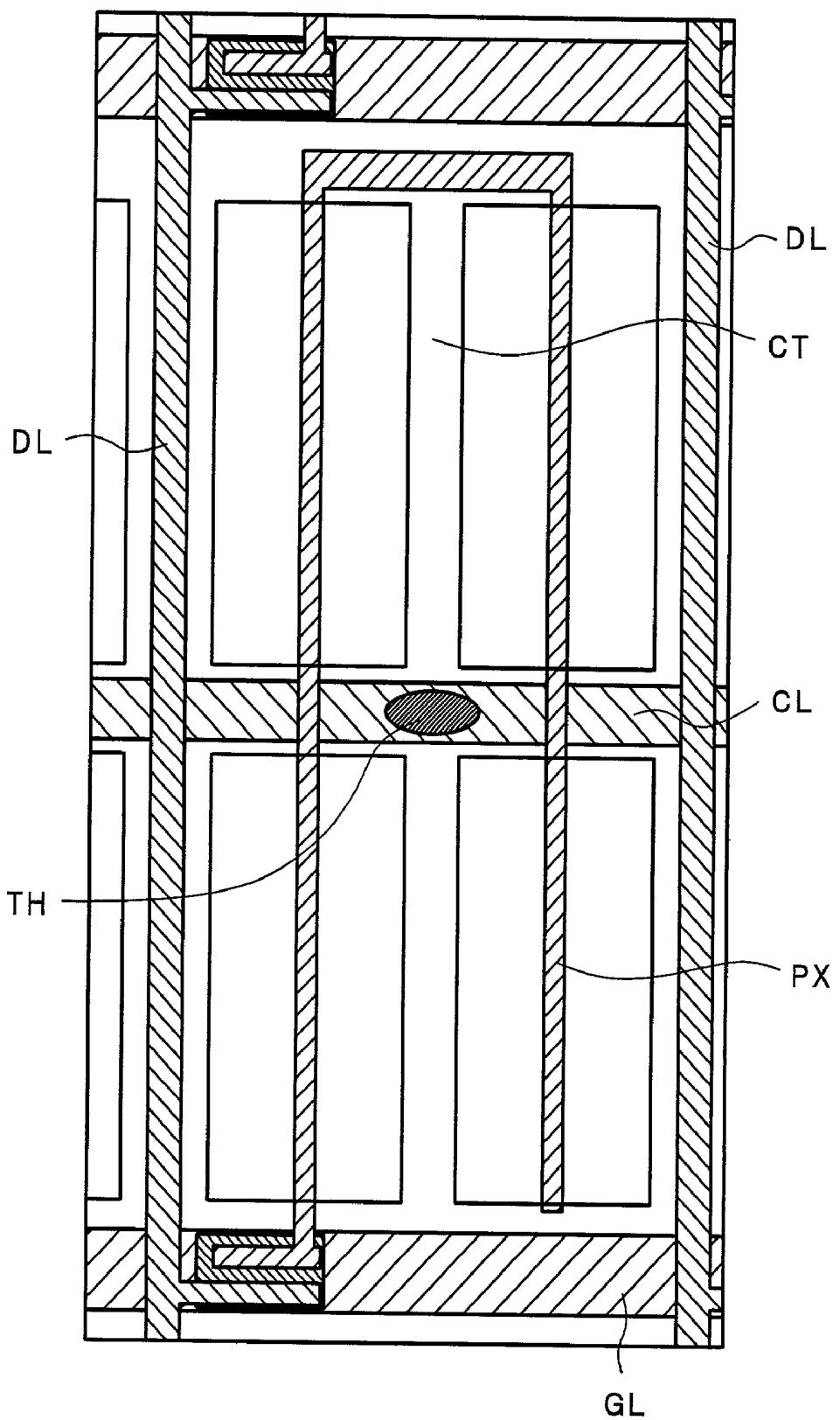


FIG. 29

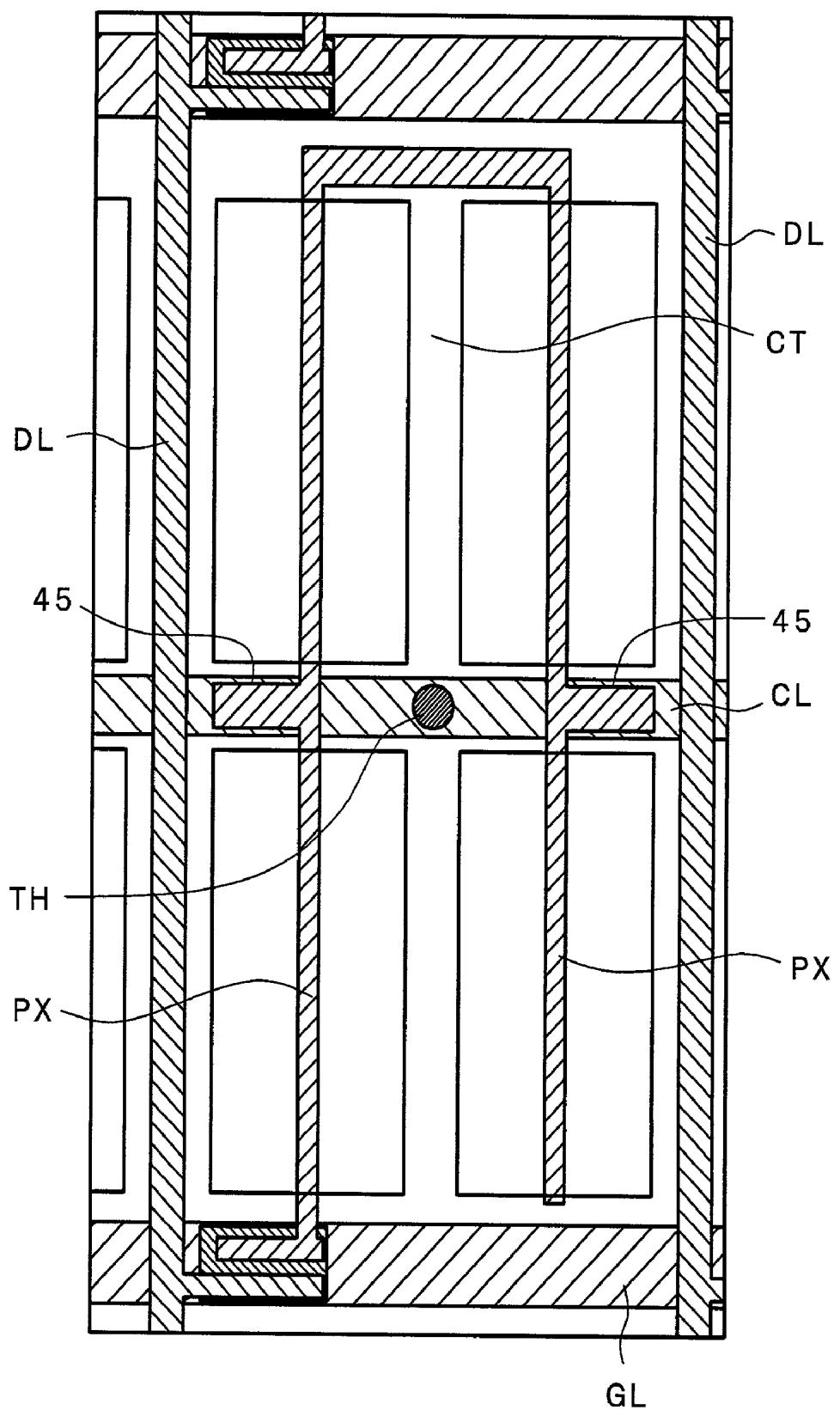


FIG. 30

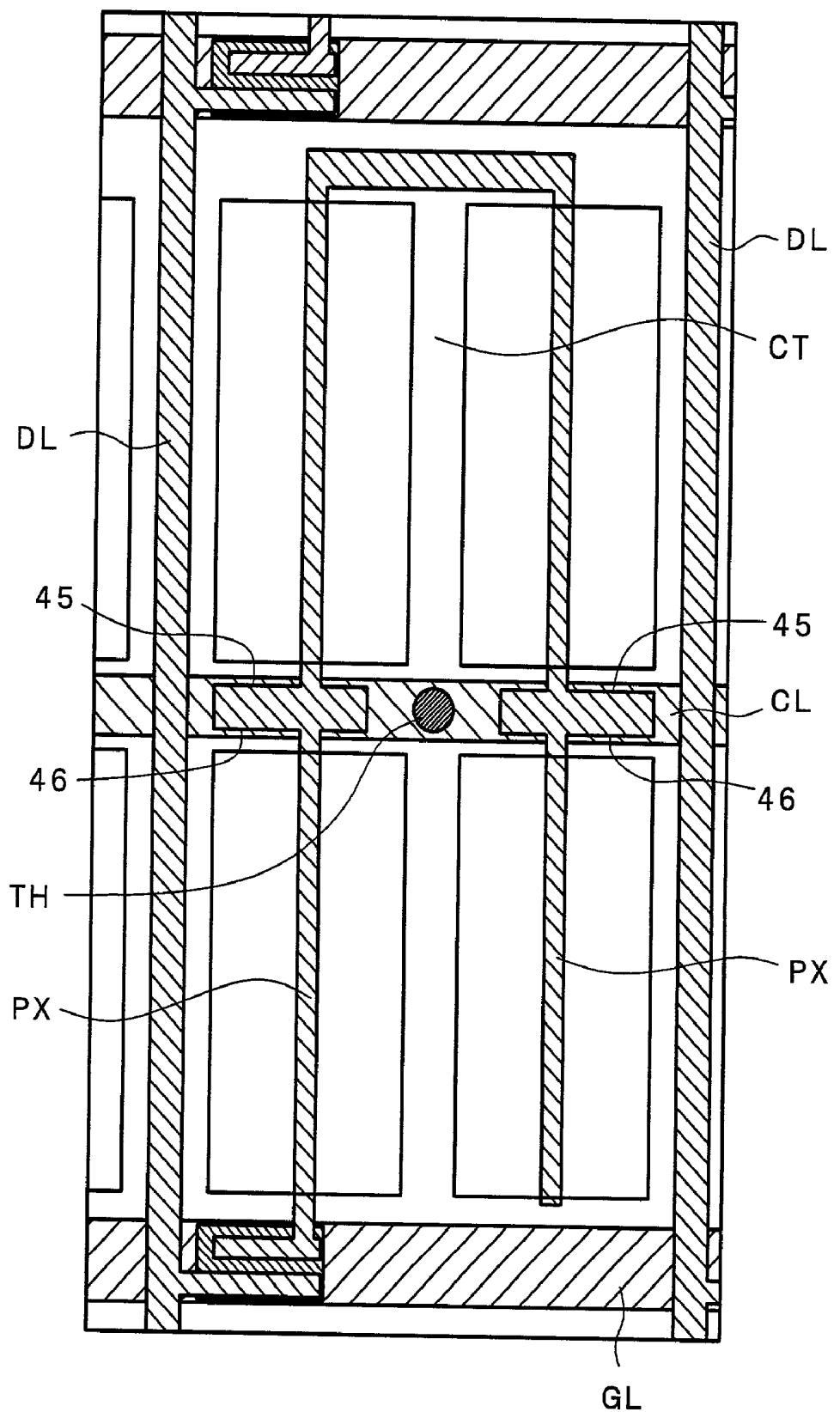


FIG. 31A

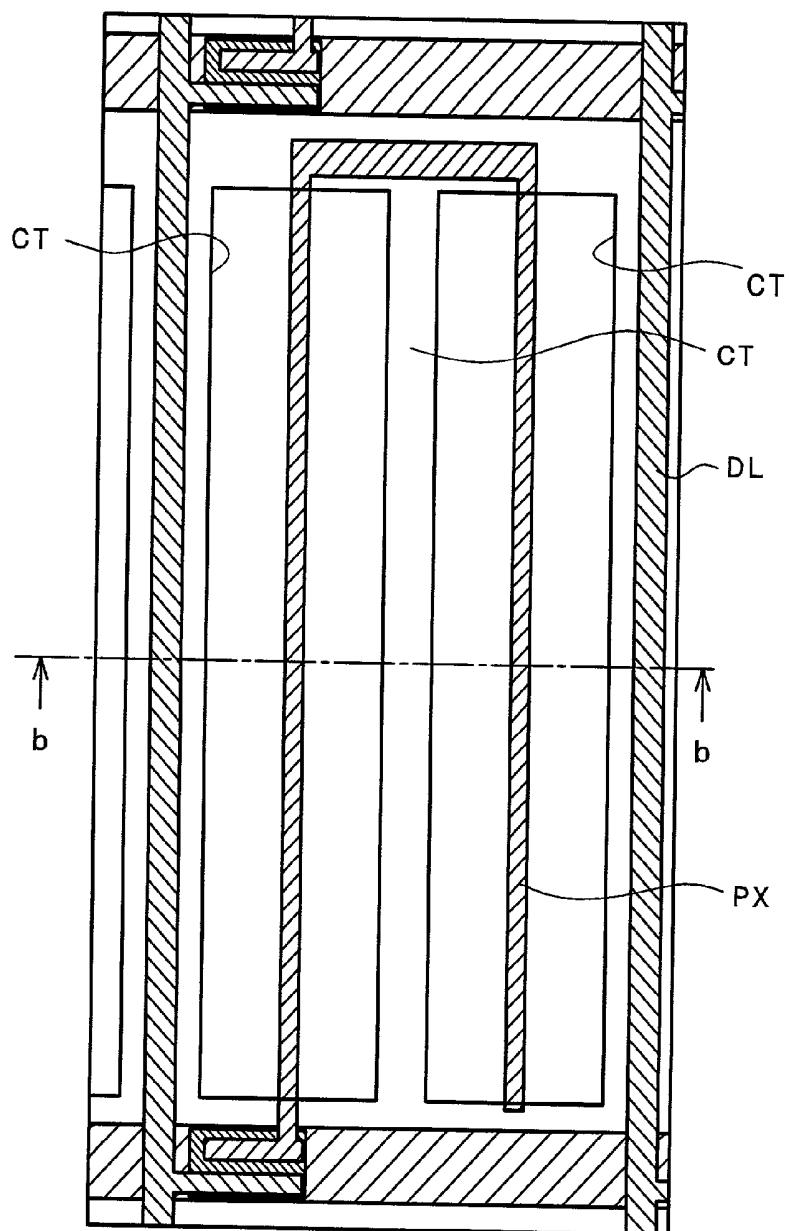


FIG. 31B

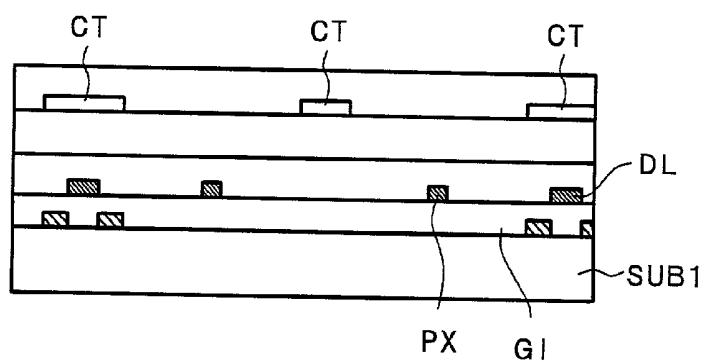


FIG. 32

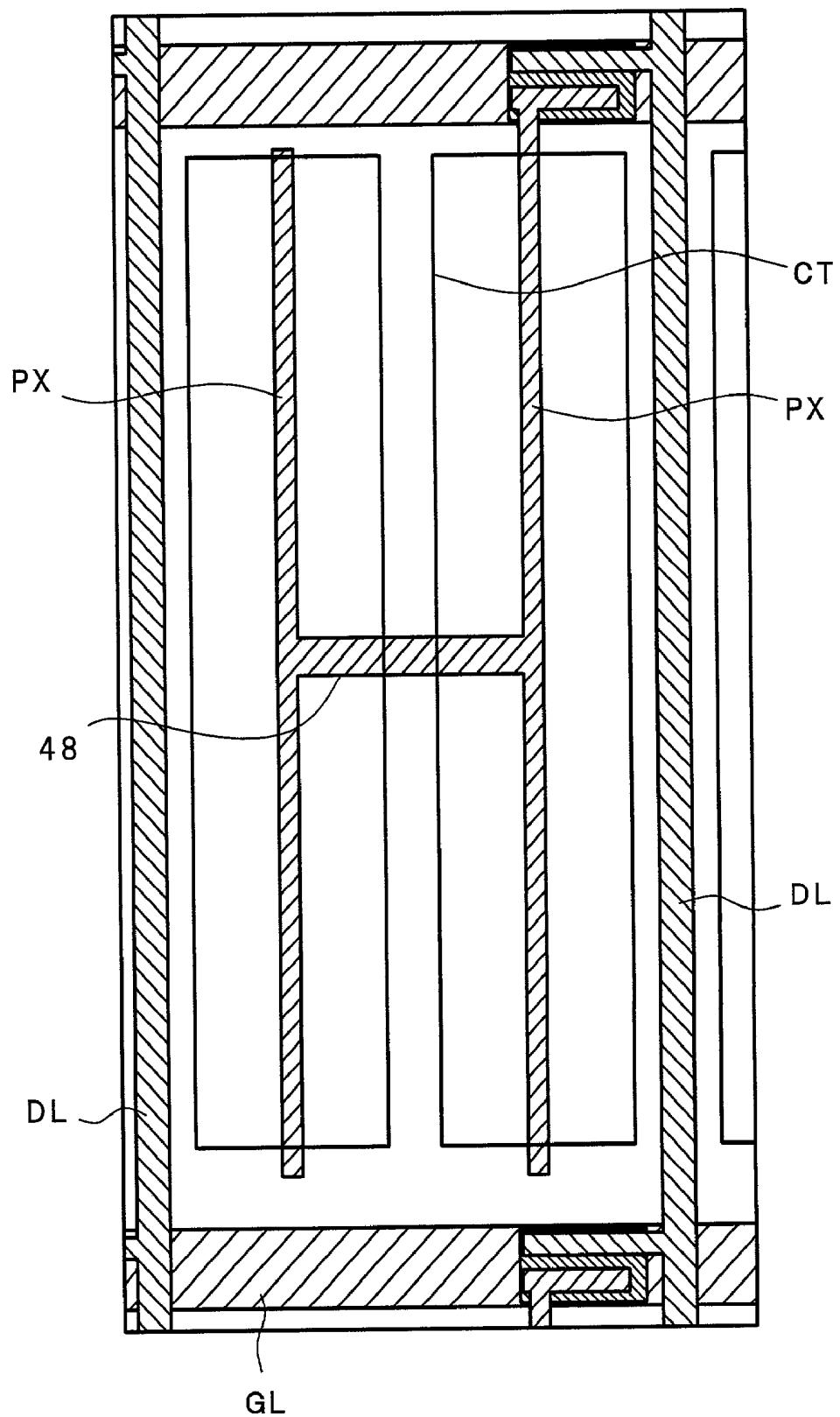


FIG. 33

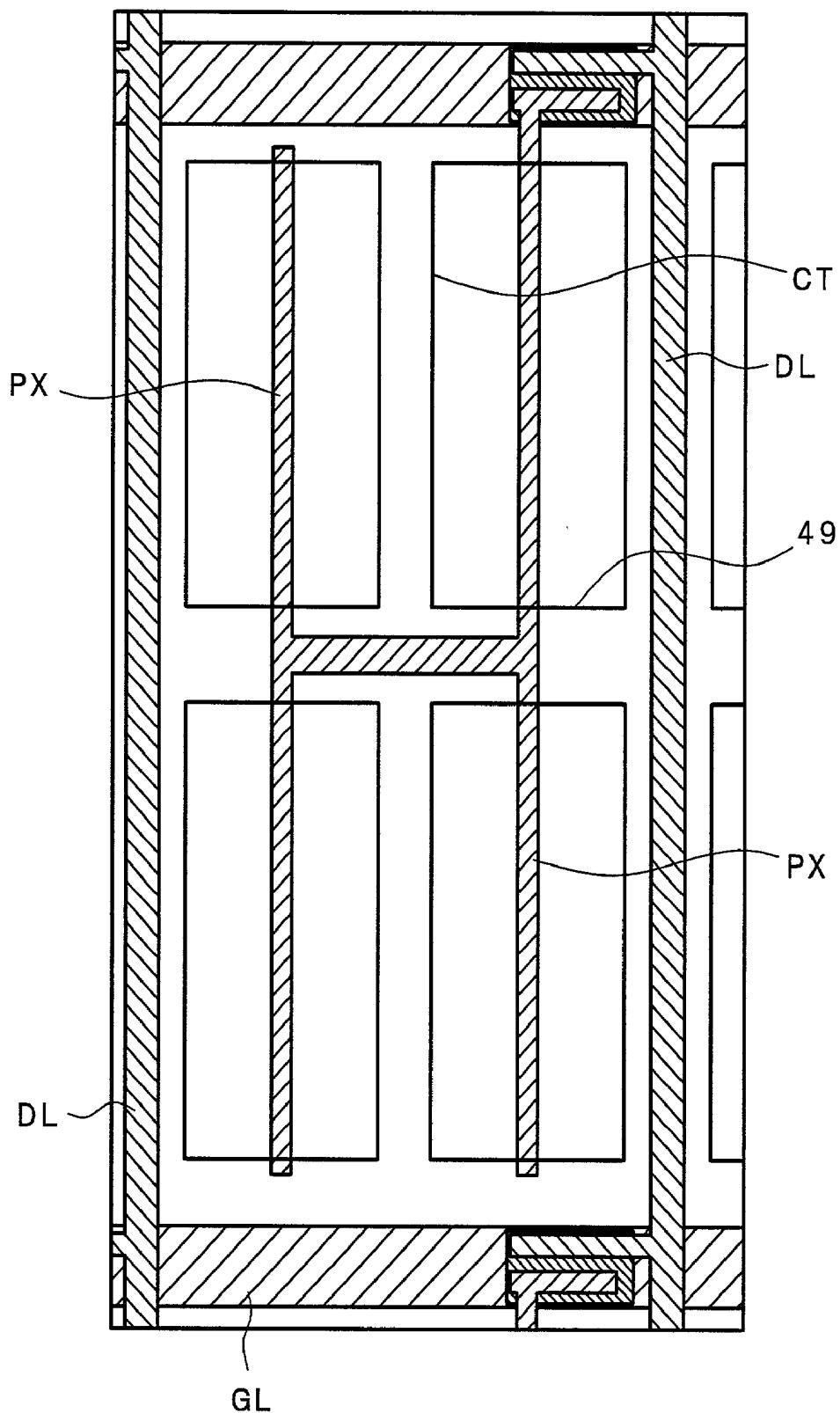


FIG. 34

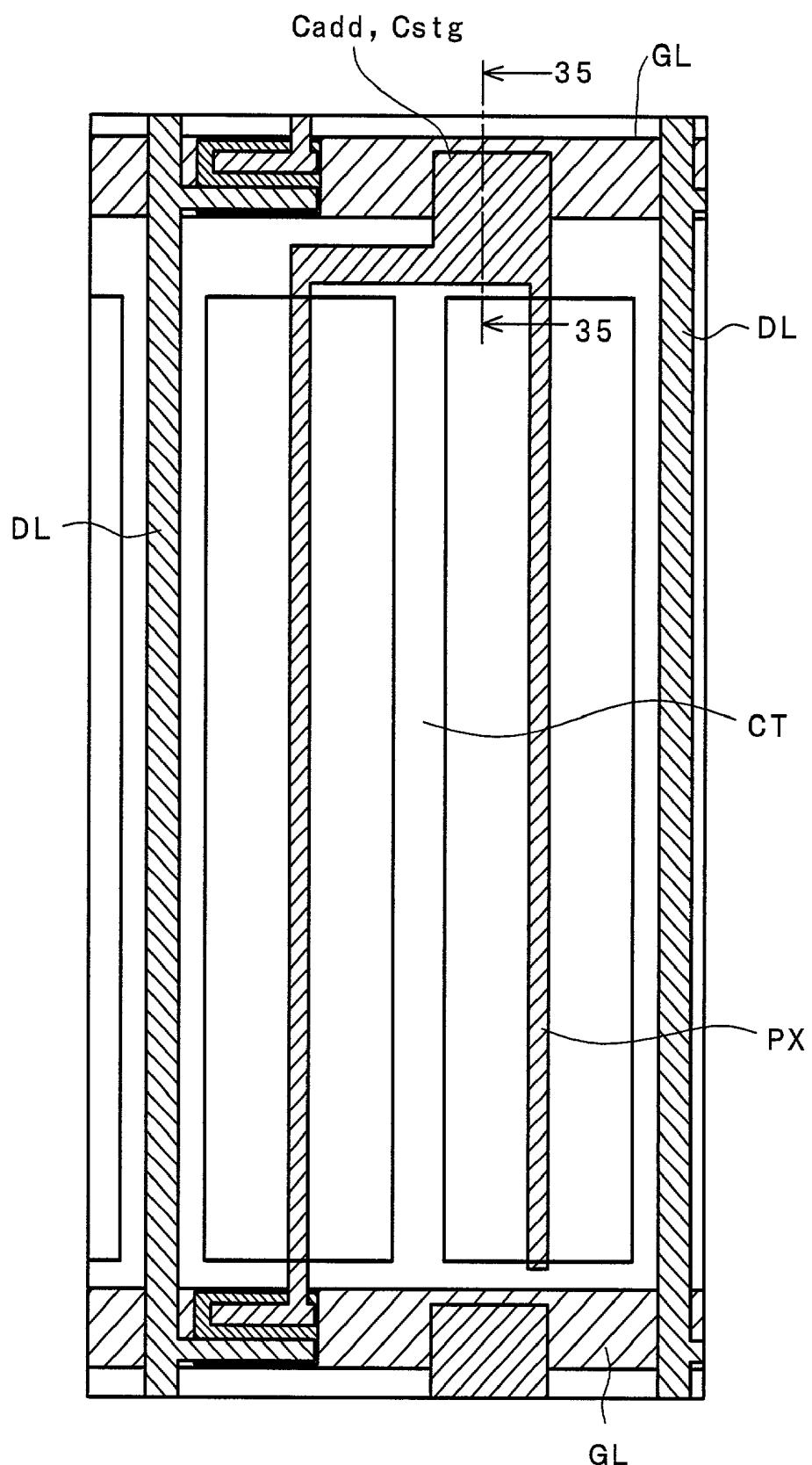


FIG. 35

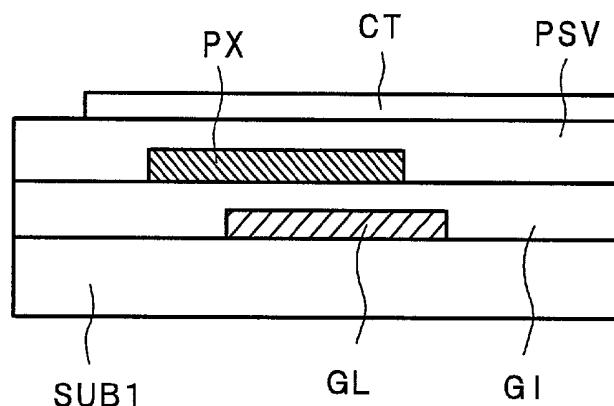


FIG. 36

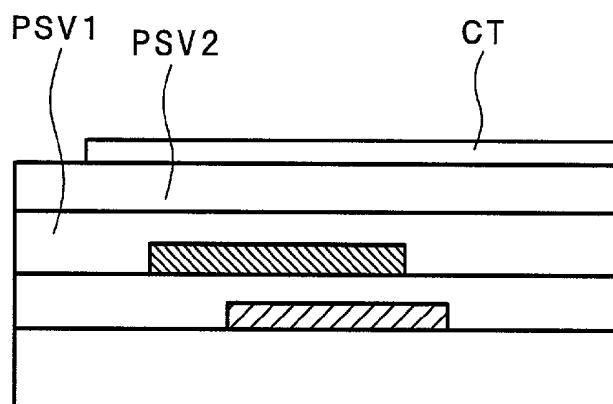


FIG. 37

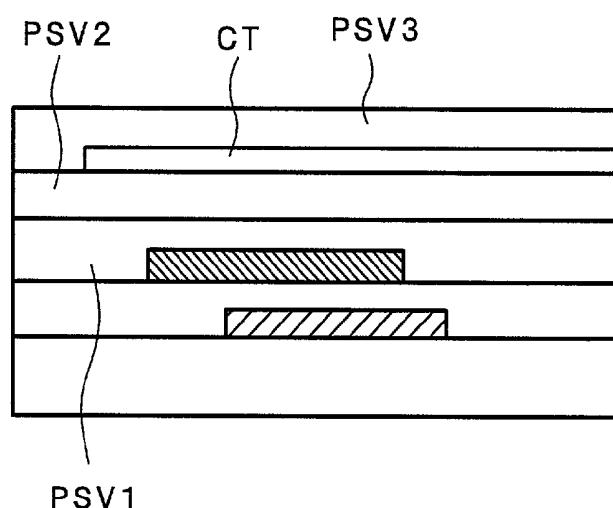


FIG. 38

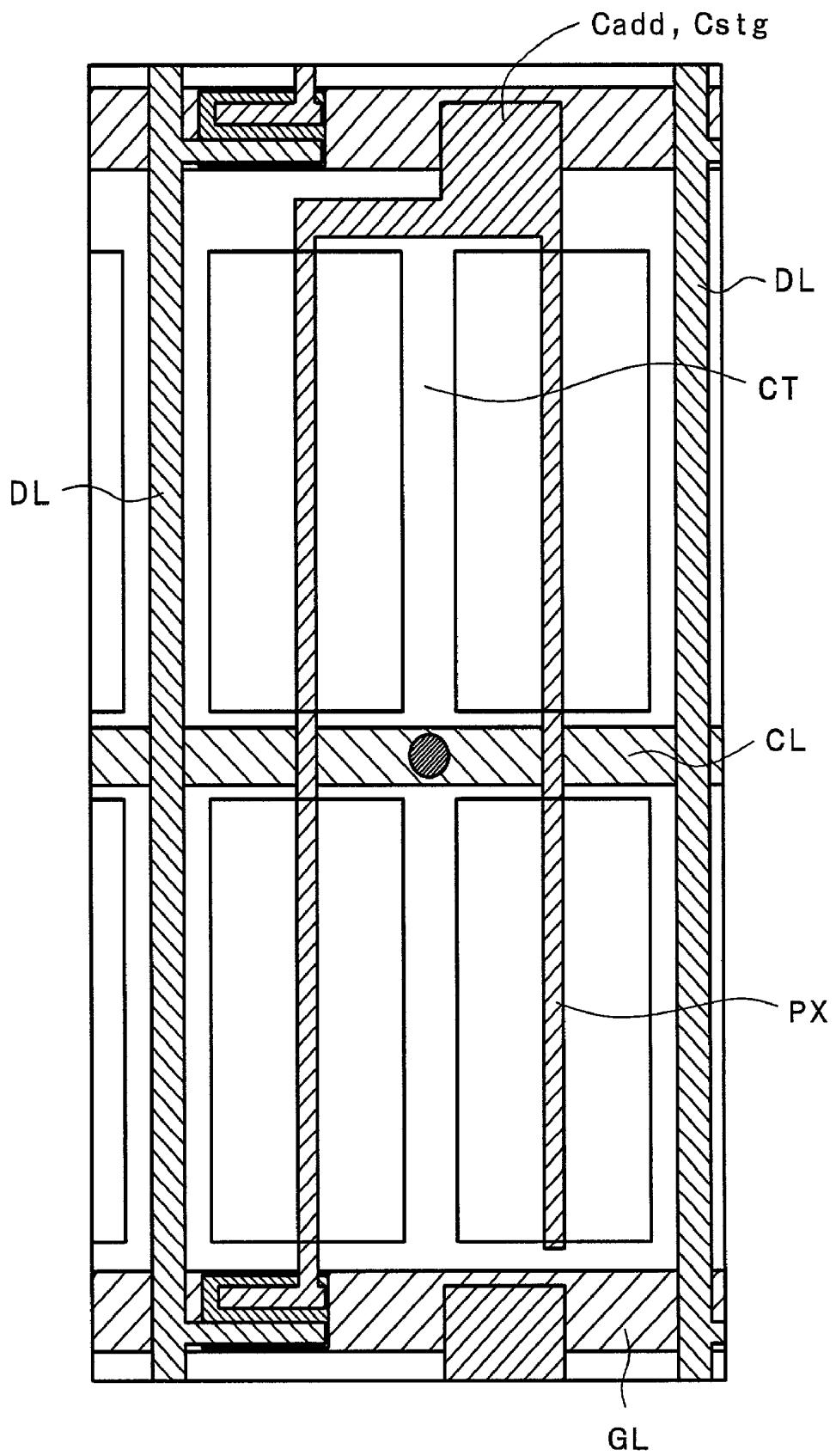


FIG. 39

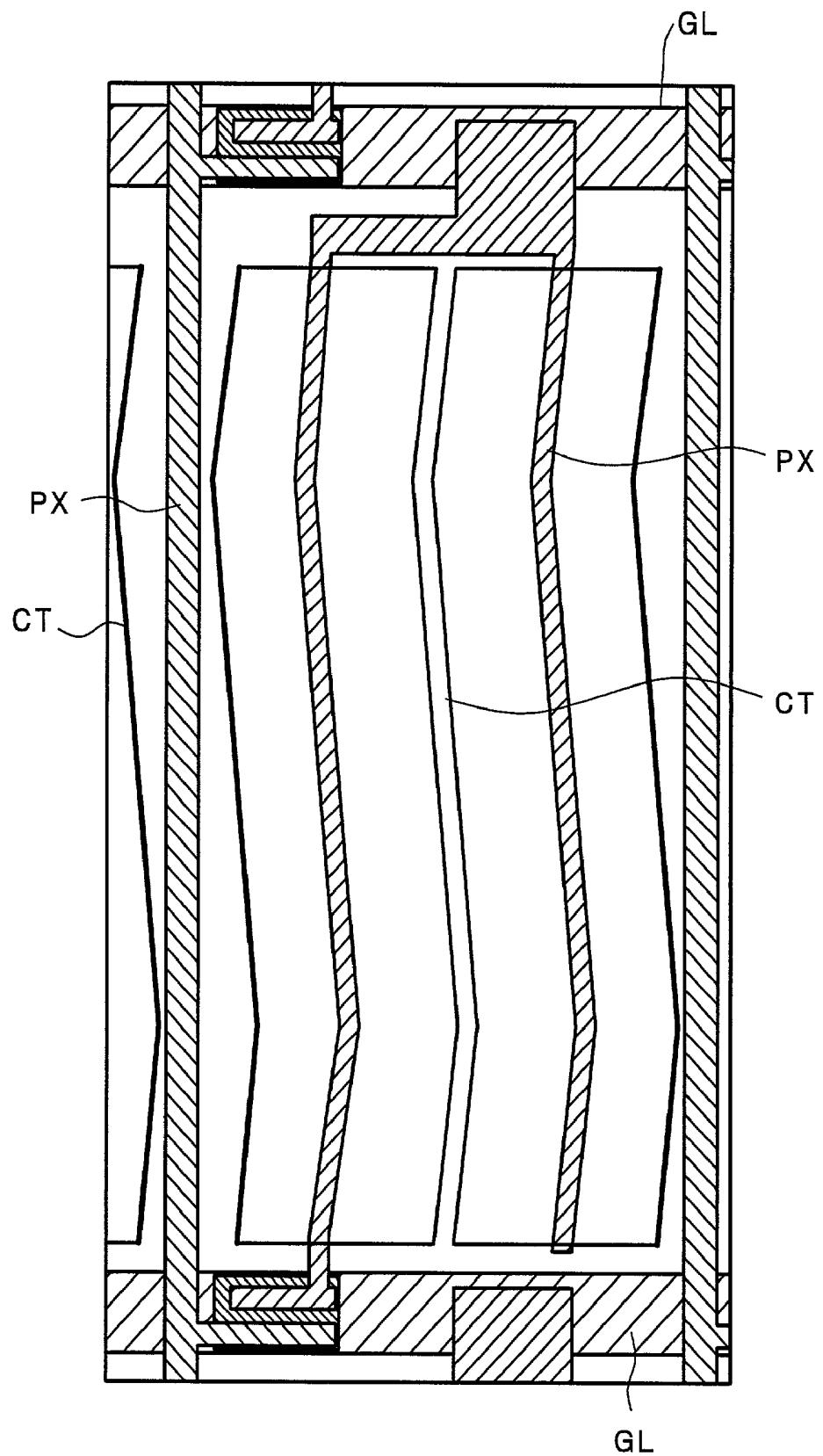


FIG. 40

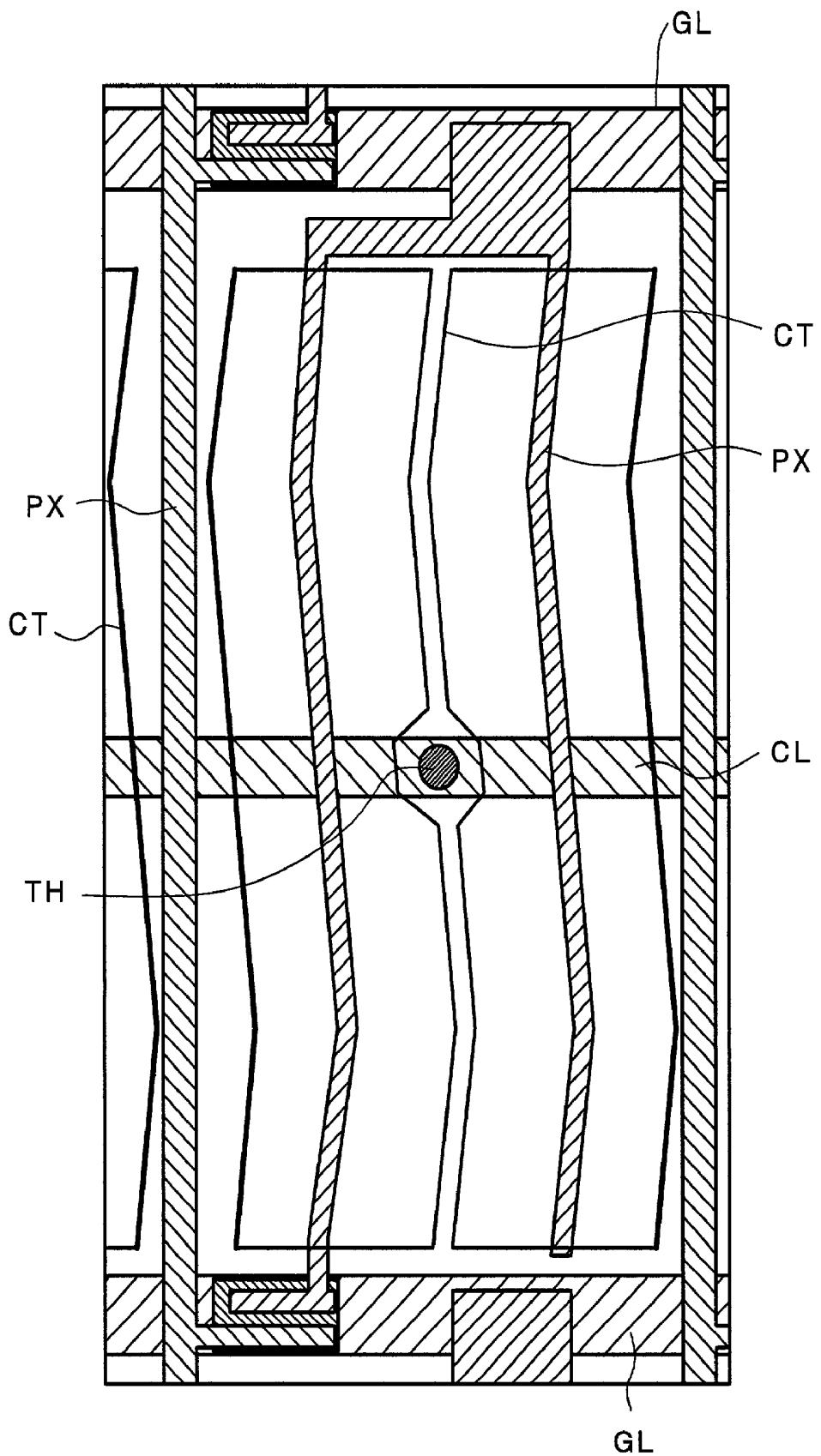


FIG. 41

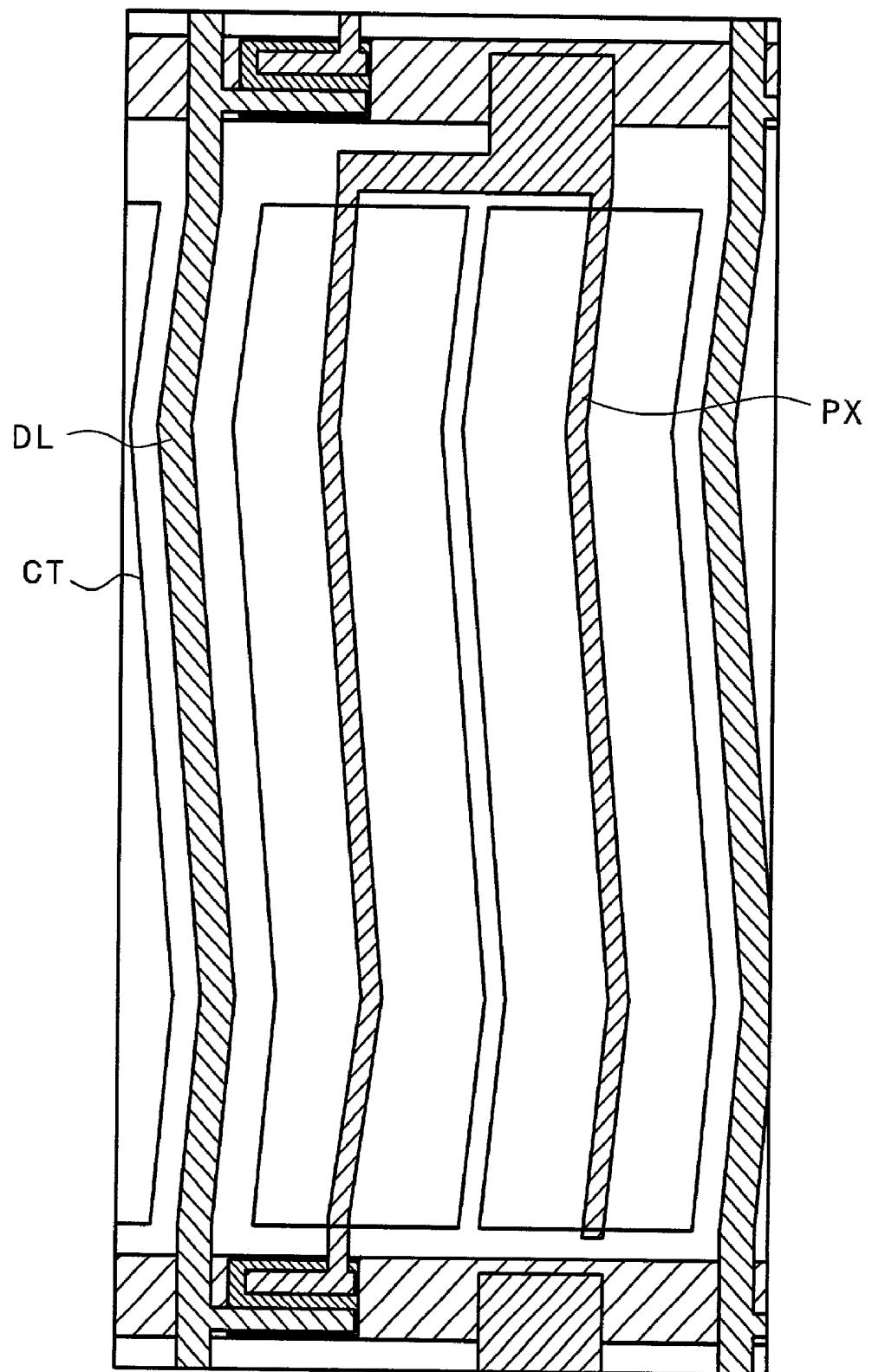


FIG. 42

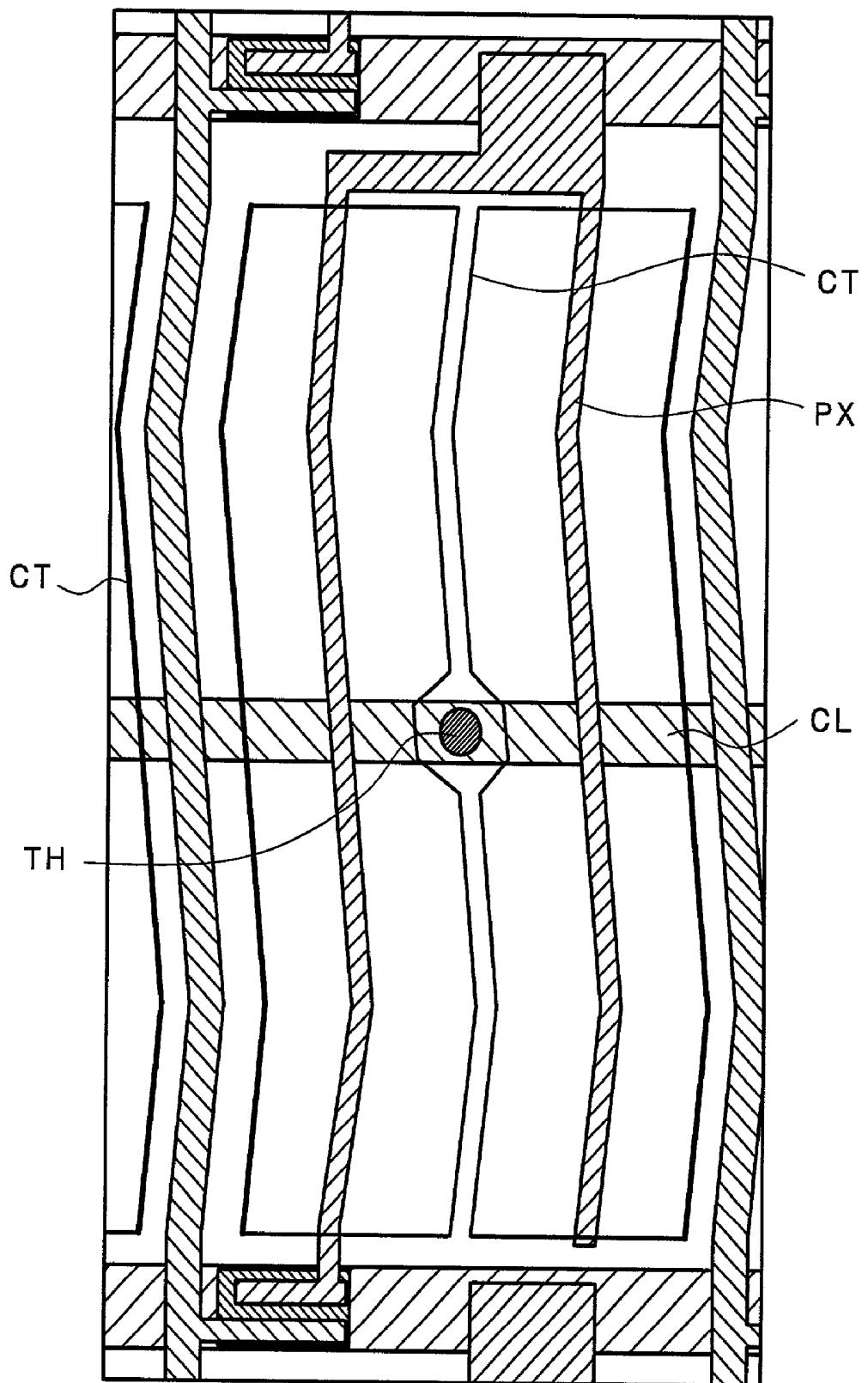


FIG. 43A

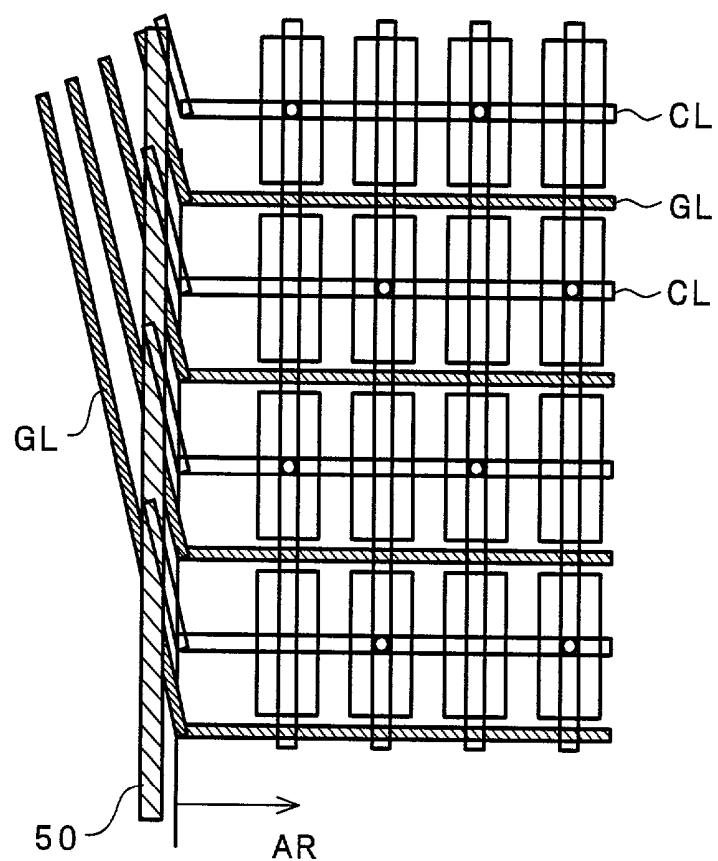


FIG. 43B

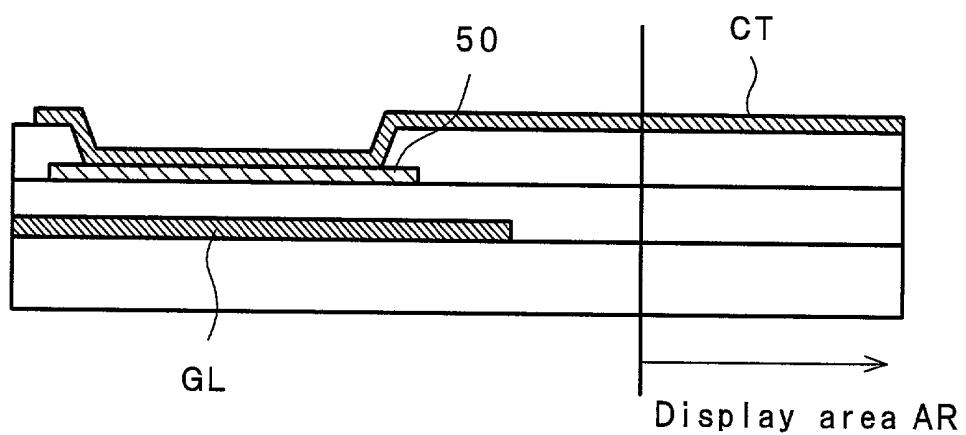


FIG. 44

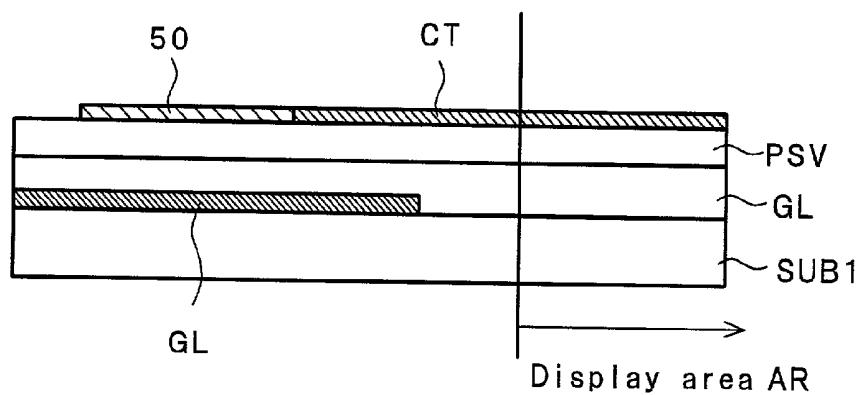


FIG. 45

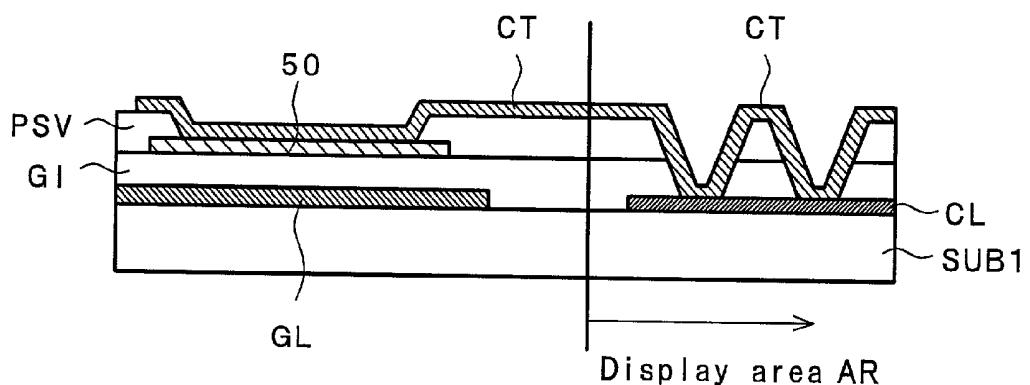


FIG. 46

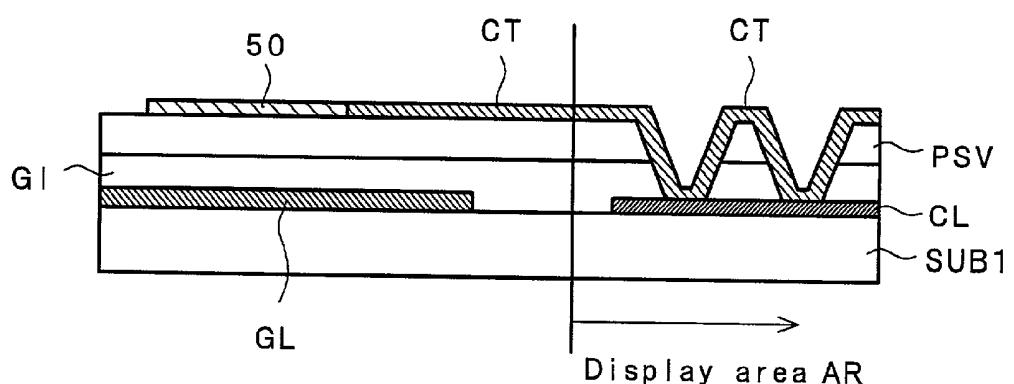


FIG. 47

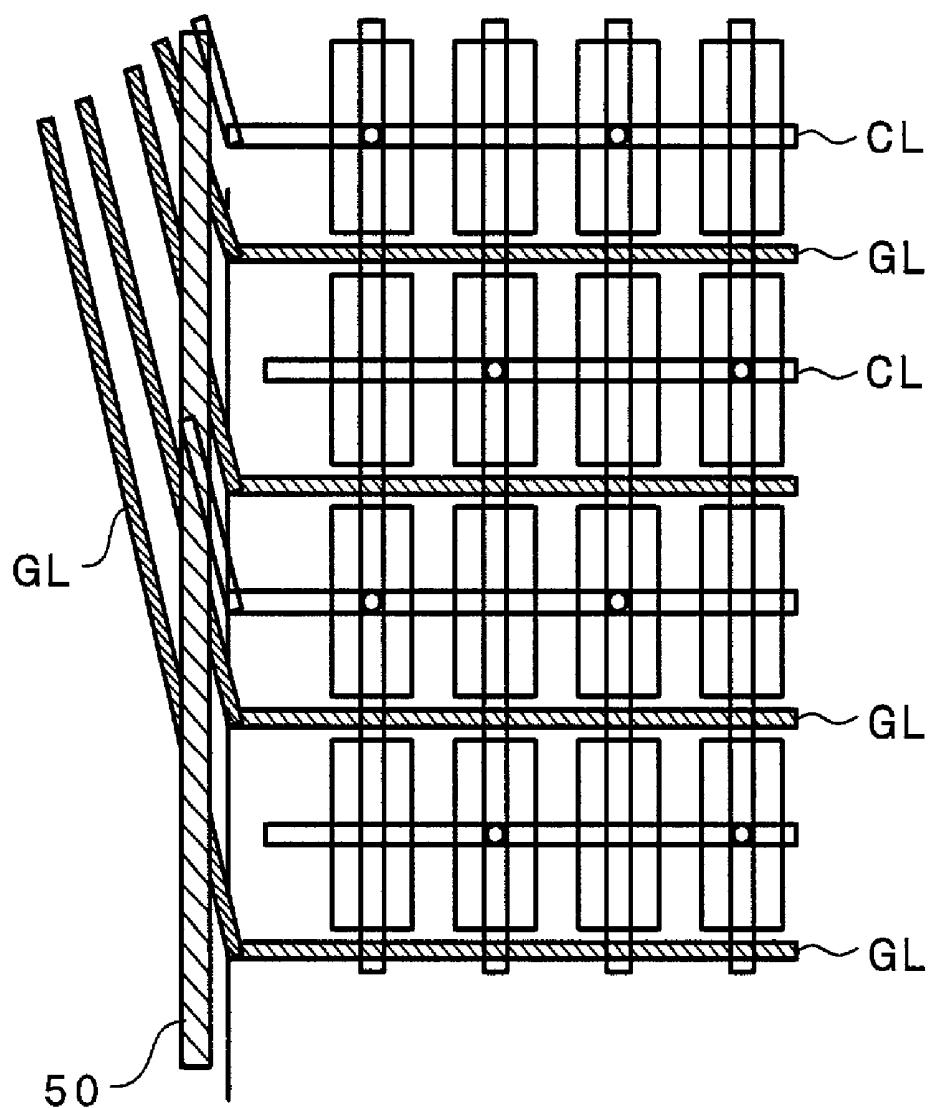


FIG. 48

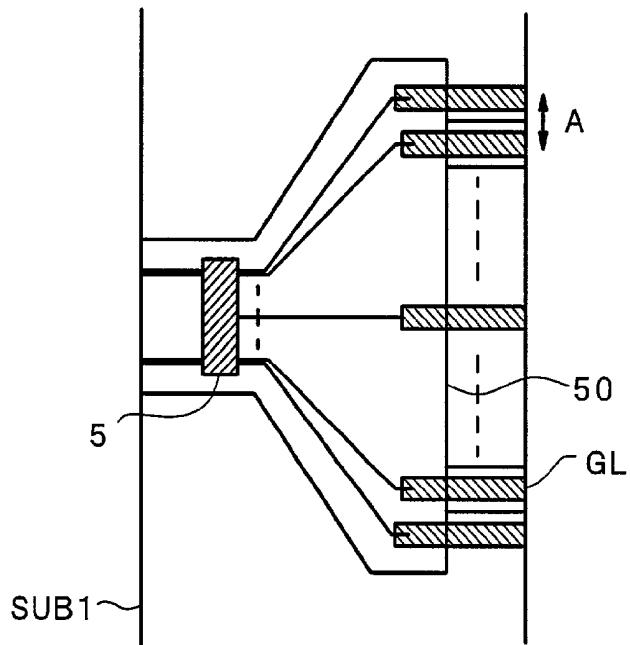


FIG. 49

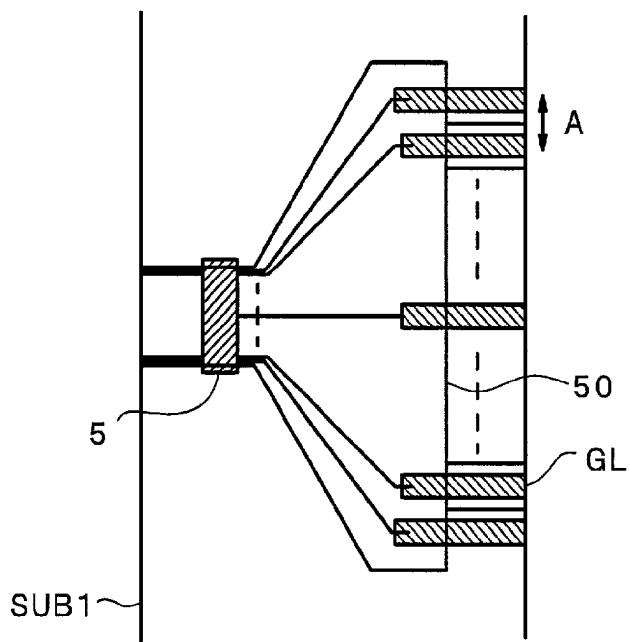


FIG. 50A

Phenomena of ionic image sticking
 After displaying lower pattern
 at display for 1 hour, measure
 changes of brightness with
 displaying middle level (V5%)
 pattern at measure.

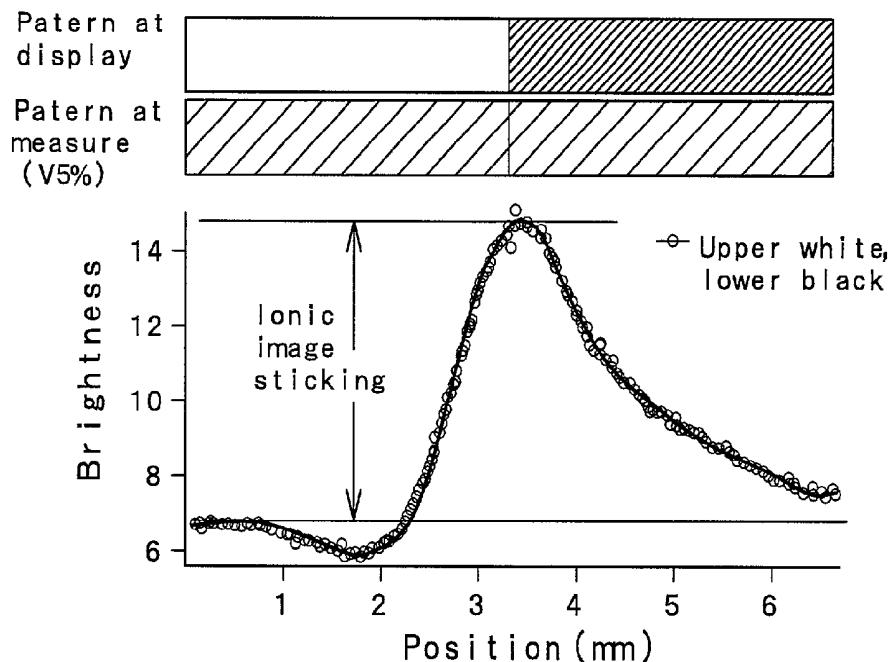


FIG. 50B

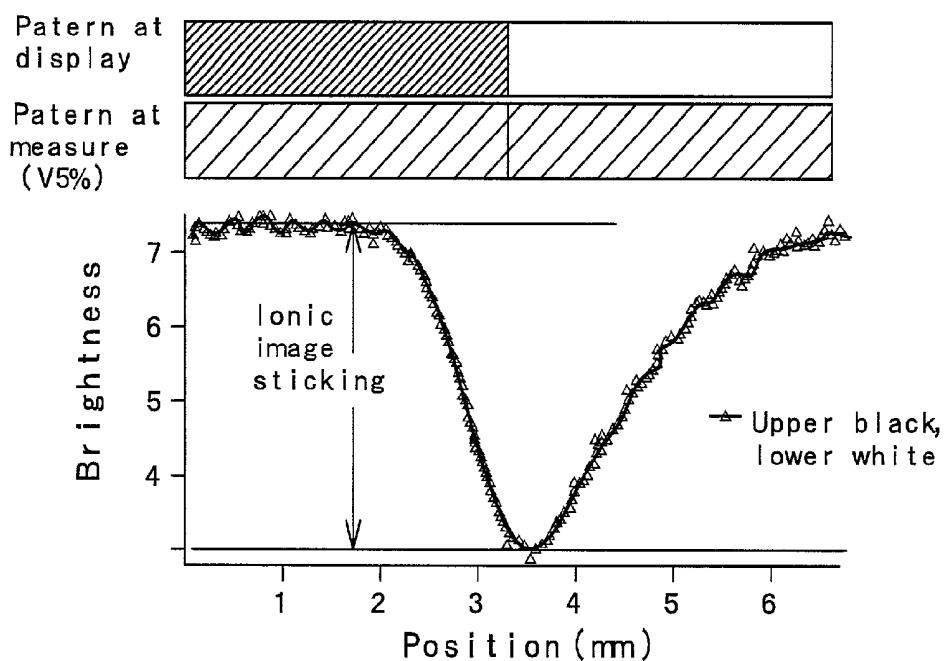


FIG. 51A

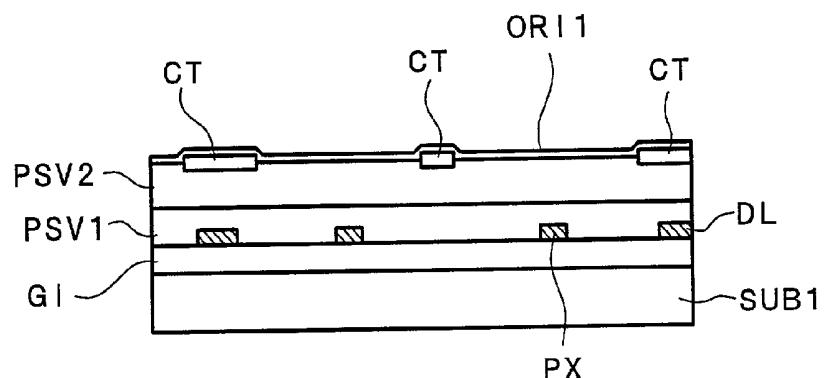


FIG. 51B

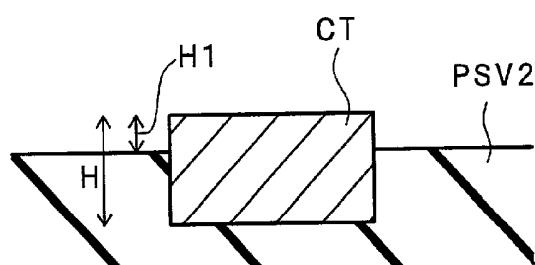


FIG. 52

H	H1	$(H-H1)/H$	Avoid unintended lighting at electrode edge
300nm	0	0	◎
↑	90nm	0.3	◎
↑	150nm	0.5	○
↑	300nm	1	✗

FIG. 53

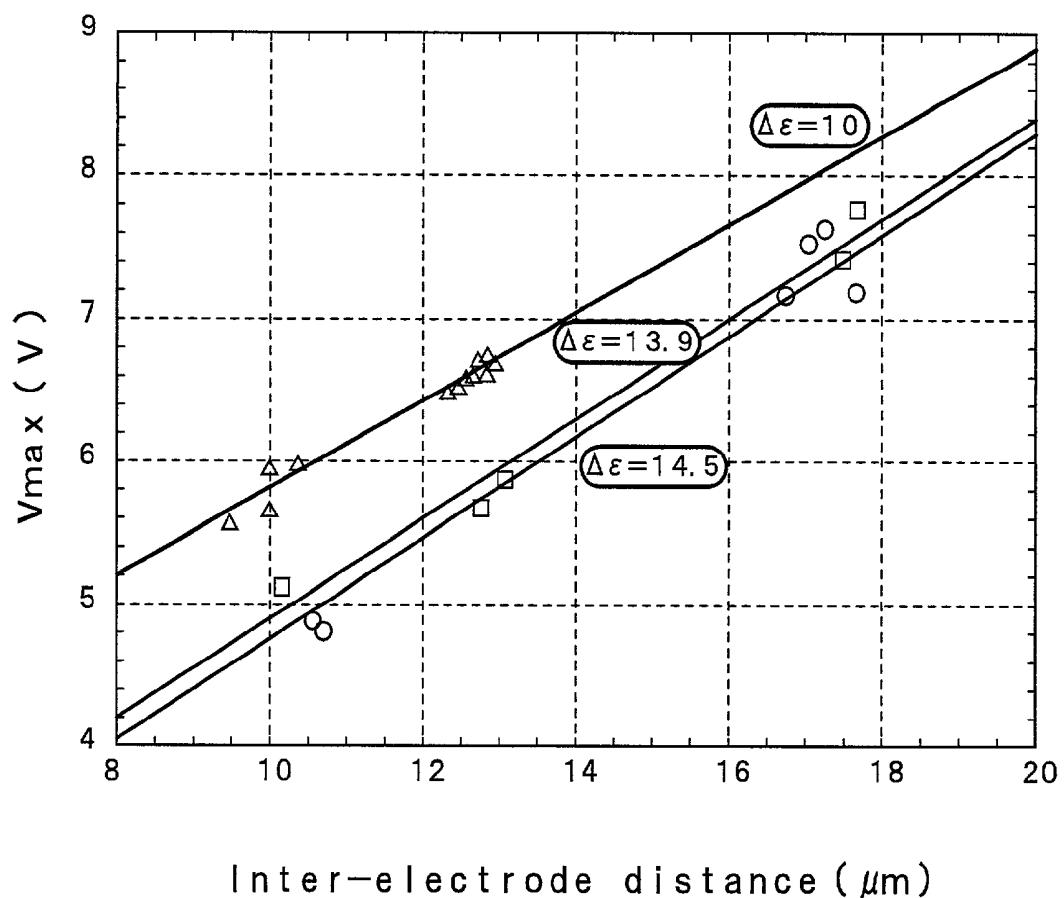
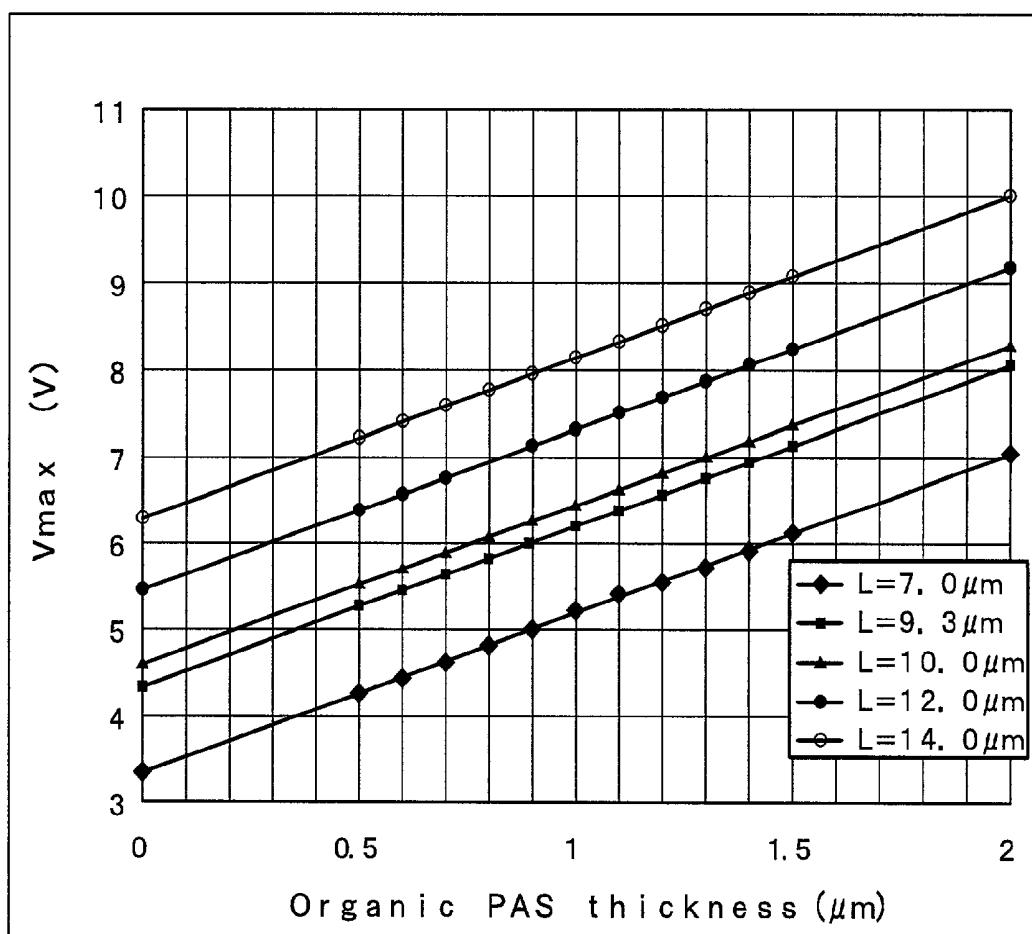
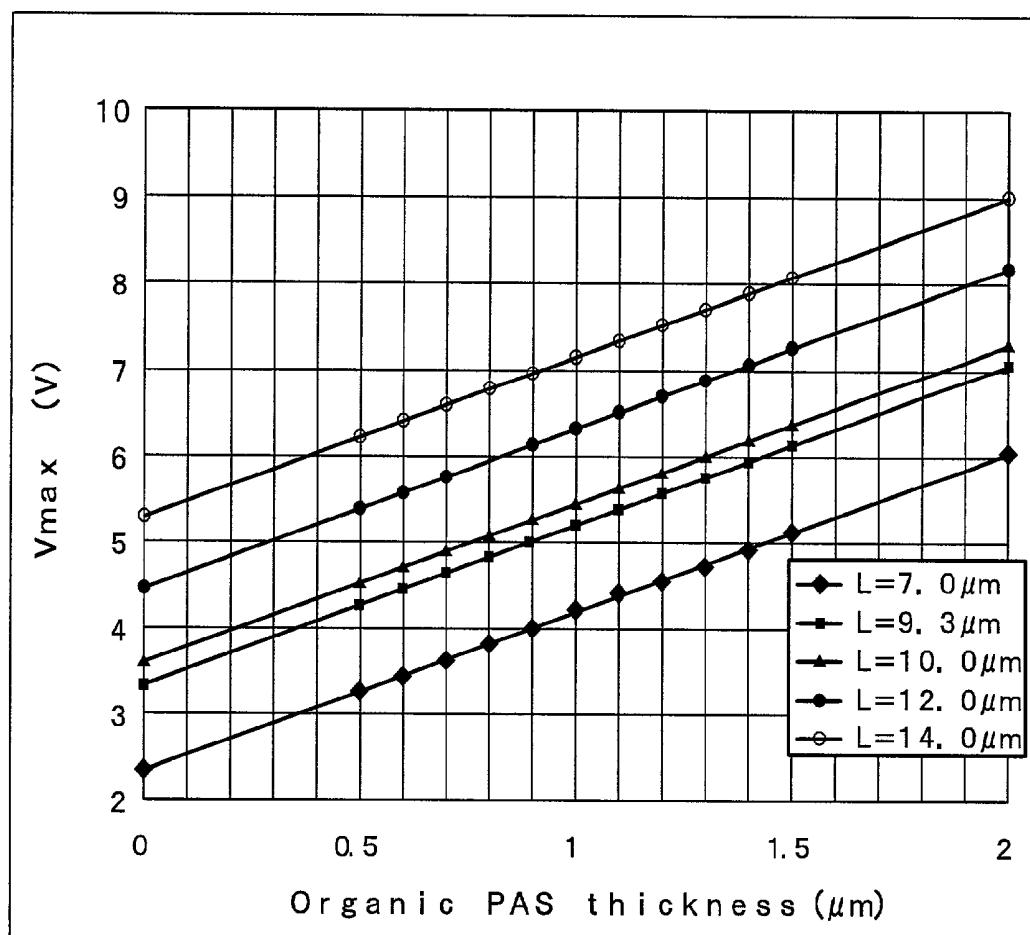


FIG. 54



Dependence of V_{max} to organic
PAS thickness and inter-
electrode distance
(at liquid crystal's $\Delta\epsilon=10$)

FIG. 55



Dependence of V_{max} to organic
PAS thickness and inter-
electrode distance
(at liquid crystal's $\Delta \epsilon = 10$)

FIG. 56

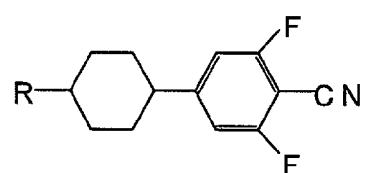


FIG. 57

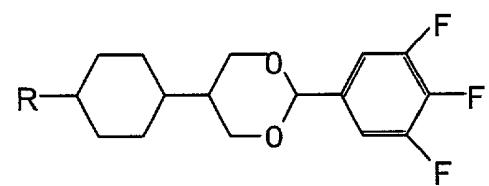
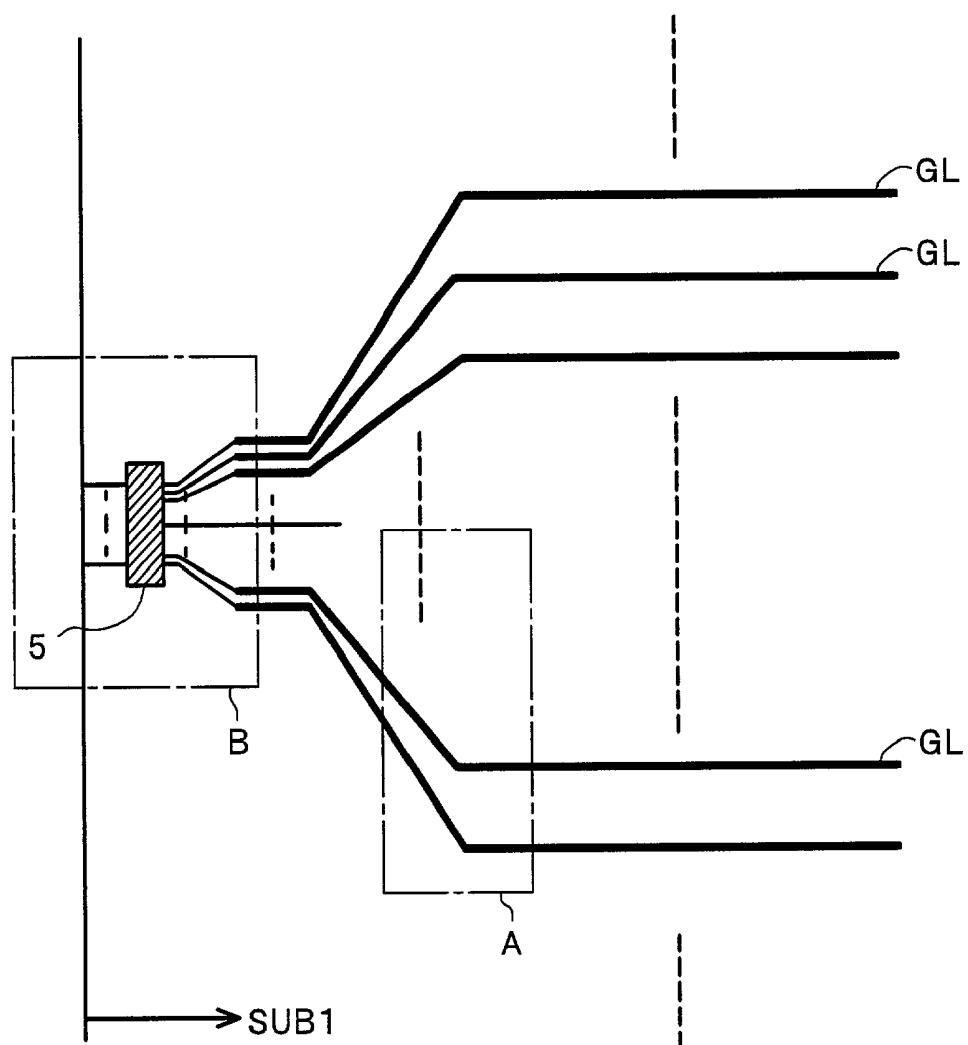


FIG. 58



LIQUID CRYSTAL DISPLAY DEVICE

BACKGROUND OF THE INVENTION

[0001] (1) Field of the Invention

[0002] The present invention relates to a liquid crystal display device, and more particularly, to an active-matrix type liquid crystal display device.

[0003] (2) Background Art

[0004] In an active-matrix type liquid crystal display device, on a liquid-crystal-side surface of one substrate out of respective substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, respective regions which are surrounded by gate signal lines which are extended in the x direction and are arranged in the y direction in parallel and drain signal lines which are extended in the y direction and are arranged in the x direction in parallel are formed as pixel regions. Each pixel region includes an active element which is operated in response to scanning signals from the gate signal line, a pixel electrode to which video signals from the drain signal line are supplied via the active element, and a capacity which is generated between the active element and the pixel electrode.

[0005] The liquid crystal display device having such a constitution realizes an image display by performing writing for a fixed time with the use of the active element and subsequent holding for a fixed time.

[0006] As holding methods, a Cadd (added capacity) method which generates a capacity between the gate signal line and the pixel electrode and Cstg (holding capacity) method which generates a capacity between a holding capacity signal line and the pixel electrode have been known.

[0007] Although the numerical aperture is lowered in the Cstg method since the method requires the holding capacity signal lines, the method can obtain a relatively high quality image since the holding potential can be made stable.

[0008] Further, as a liquid crystal display device using the Cstg method, a so-called lateral electric field type liquid crystal display device has been known. This type of liquid crystal display device is constituted such that on a substrate side on which pixel electrodes are formed, reference electrodes which generate an electric field between the pixel electrodes and the reference electrodes are mounted. Holding capacities are formed by superposing pixel electrodes on reference signal lines which supply reference signals to the reference electrodes via insulation films.

[0009] As liquid crystal display devices which can realize the broadening of a viewing angle of the display of the liquid crystal display device, liquid crystal display devices which adopt this Cstg method have been commercialized.

[0010] On the other hand, to ensure a uniform gap (cell gap) between respective substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, a constitution which disperses polymer stationary beads in the inside of the liquid crystal or a constitution which provides support columns made of organic material to one substrate surface by a selective etching with the use of a photolithography technique has been known.

[0011] Although the leaking of light is generated in the periphery of the beads or the support columns, the technique which arranges the support columns in the inside of the screen can preliminarily set their positions and hence, the technique can realize the enhancement of the contrast ratio compared to the technique which uses the dispersion of beads.

[0012] Further, as a mounting method of drivers (semiconductor chips) which supply signals to the active elements, a TCP method and a FCA (also referred to as "COG") method have been known.

[0013] The TCP method has a feature that the method can manufacture the liquid crystal display devices more easily than the FCP method and can enhance the yield. On the other hand, the FCP method can decrease the number of wiring which are pulled out to the outside so that the method is suitable for a high definition.

SUMMARY OF THE INVENTION

[0014] (First Problem to be Solved by the Present Invention)

[0015] First of all, to realize a liquid crystal display device having a broad viewing angle and a high definition, it has been considered desirable to adopt the FCA method as the abovementioned lateral electric field method.

[0016] However, the lateral electric field method adopts a birefringence refraction mode as a display mode of a liquid crystal thereof and hence, the mode is sensitive to the fluctuation of a thickness of a liquid crystal layer compared to the TN mode whereby there arises a drawback that the liquid crystal layer appears more colored with respect to the same fluctuation quantity of the thickness of the liquid crystal layer.

[0017] Further, inventors of the present invention have found out that, in the FCA method, the drivers are directly mounted on the substrate of the liquid crystal display device and hence, the generated heat from the drivers are directly transmitted to the substrate of the liquid crystal display device so that there arises a drawback that the liquid crystal in the vicinity of the drivers exhibits the local temperature elevation and this portion appears discolored.

[0018] (Second Problem to be Solved by the Present Invention)

[0019] Further, the inventors also have found that when the FCA method is adopted, it is often the case that drivers which are exclusively made of semiconductor chips are directly mounted on the substrate of the liquid crystal display device so that a stress is liable to be generated in the substrate at the peripheries of the semiconductor chips.

[0020] Then, the inventors have found that there arises a drawback that portions of the display surface in the vicinity of the drivers appears discolored due to this stress.

[0021] Here, that is, in a normally black mode, it has been confirmed that the leaking of light is generated at the time of black display and this results in the lowering of the contrast ratio. Here, the normally black mode means a mode in which an electric field is not applied to the liquid crystal and hence, the liquid crystal exhibits the minimum light transmittivity.

[0022] (Third Problem to be Solved by the Present Invention)

[0023] Further, when the support columns are formed on one-side substrate to make the gap formed between respective substrates which are arranged to face each other in an opposed manner while sandwiching the liquid crystal therebetween uniform, it has been found that because of the stress explained in the above-mentioned second problem, the alignment displacement between the upper and the lower substrates is worsened at regions in the vicinity of the chips than other regions.

[0024] It has been found that, when the beads are used, since their shape is a spherical body and they are not firmly secured, when a local stress is applied to the beads, the beads are rearranged in the direction to alleviate the stress and, as a result, the alignment displacement of the upper and the lower substrates in the vicinity of semiconductor chips can be decreased.

[0025] When the support columns are used, however, a following phenomenon is found. That is, the support columns and the substrate are brought into face contact so that the contact area is large. Further, the support columns per se are fixedly secured to one-side substrate. Accordingly, the local alignment displacement in the vicinity of the semiconductor chips due to the stress remains as it is so that it is difficult to alleviate the stress.

[0026] (Fourth Problem to be Solved by the Present Invention)

[0027] Further, it has been known that, in the lateral electric field method, out of the pixel electrodes and the reference electrodes which generate electric fields each other, the reference electrodes are arranged close to the video signal line.

[0028] This provision is provided to terminate the electric field from the video signal line at the reference electrode side so as to prevent the electric field from influencing the pixel electrode side.

[0029] Here, a gap is formed between the video signal line and the reference electrode and a so-called domain is generated by driving the liquid crystal in this gap portion. Accordingly, a light shielding film has been formed on this portion.

[0030] However, it has been pointed out that the formation of the light shielding film impedes the enhancement of the numerical aperture of the pixel.

[0031] (Fifth Problem to be Solved by the Present Invention)

[0032] Further, with respect to the connection of the driver with the gate signal line or the drain signal line, the signal line in the vicinity of the drivers is formed in a pattern which narrows the signal line to the size of the semiconductor chip.

[0033] In this case, it is required to pull out signal lines such as the reference signal lines besides the above-mentioned signal lines to the semiconductor chip side and to connect these signal lines to a separate wiring layer at the narrowed portions of respective signal lines so that it becomes necessary to ensure the contact regions.

[0034] However, to ensure such regions, there arises a drawback that the shrinkage of a so-called picture frame (portion which is formed of a width from an outer profile of the substrate to a display screen) can not be ensured.

[0035] Accordingly, it is an object of the present invention to provide a liquid crystal display device which can solve the drawback which is explained in conjunction with the above-mentioned first problem, that is, which can suppress the local temperature elevation of a liquid crystal in the vicinity of drivers.

[0036] It is another object of the present invention to provide a liquid crystal display device which can solve the drawback which is explained in conjunction with the above-mentioned second problem, that is, which can suppress the transmission of the stress from drivers to the substrate.

[0037] It is still another object of the present invention to provide a liquid crystal display device which can solve the drawback which is explained in conjunction with the above-mentioned third problem, that is, which can suppress the alignment displacement on the display surface in the vicinity of the drivers.

[0038] It is a further object of the present invention to provide a liquid crystal display device which can solve the drawback which is explained in conjunction with the above-mentioned fourth problem, that is, which can enhance the numerical aperture.

[0039] It is a still further object of the present invention to provide a liquid crystal display device which can solve the drawback which is explained in conjunction with the above-mentioned fifth problem, that is, which can achieve a so-called shrinkage of the picture frame.

[0040] To briefly explain the summary of typical inventions among inventions disclosed here, they are as follows.

[0041] As typical means for solving the above-mentioned first problem, there is provided a liquid crystal display device being characterized in that

[0042] on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

[0043] a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via the switching element, and a reference electrode which generates an electric field between the reference electrode and the pixel electrode are mounted in each pixel region,

[0044] the video signals from the drain signal line are generated by a driver chip mounted on one substrate,

[0045] a light transmittivity of the liquid crystal layer is set to take a minimum value when a voltage is not applied between the pixel electrode and the reference electrode, and

[0046] a maximum amplitude of voltage of the video signals is set to a value not more than a voltage necessary for setting a relative transmittivity of the liquid crystal layer to 90%.

[0047] As typical means for solving the above-mentioned second problem, there is provided a liquid crystal display device being characterized in that

[0048] on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, for example,

[0049] a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via the switching element, and a reference electrode which generates an electric field between the reference electrode and the pixel electrode are mounted in each pixel region,

[0050] the video signals from the drain signal line are generated by a driver chip mounted on one substrate, and

[0051] a stress buffer layer is interposed between the driver chip and one substrate.

[0052] As typical means for solving the above-mentioned third problem, there is provided a liquid crystal display device being characterized in that

[0053] on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, for example,

[0054] a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via the switching element, and a reference electrode which generates an electric field between the reference electrode and the pixel electrode are mounted in each pixel region,

[0055] the signals from the respective signal lines are generated by a driver chip mounted on one substrate,

[0056] support columns which ensure a gap formed between one substrate and the other substrate which faces one substrate in an oppose manner is mounted on a liquid-crystal-side surface of either one of the respective substrates, and

[0057] the support columns are arranged with the density of one or less per two neighboring pixel regions.

[0058] As typical means for solving the above-mentioned fourth problem, there is provided a liquid crystal display device being characterized in that

[0059] on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, for example,

[0060] a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via the switching element, and a plurality of reference electrodes which generate an electric field between the reference electrode and the pixel electrode are mounted in each pixel region, and

[0061] one of the respective reference electrodes is formed in a superposed manner with the drain signal line via an insulation film having a dielectric constant lower than a dielectric constant of inorganic material and has a width thereof set larger than a width of the drain signal line.

[0062] As typical means for solving the above-mentioned fifth problem, there is provided a liquid crystal display device being characterized in that

[0063] on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, for example,

[0064] a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via the switching element, and a reference electrode which is arranged in a spaced-apart manner from the pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region,

[0065] the video signals from the drain signal line are generated by a driver chip mounted on one of the substrates, and

[0066] the gate signal line, the drain signal line and the reference signal line are respectively formed as layers which are different from each other via insulation films.

BRIEF DESCRIPTION OF THE DRAWINGS

[0067] FIG. 1 is an explanatory view showing one embodiment of a liquid crystal display device according to the present invention, and more particularly to a graph which shows the relationship between a liquid crystal driving voltage and a relative brightness in a normally black mode.

[0068] FIG. 2 is an entire constitutional view showing one embodiment of the liquid crystal display device according to the present invention.

[0069] FIG. 3 is a plan view showing one embodiment of a pixel of the liquid crystal display device according to the present invention.

[0070] FIG. 4 is a cross-sectional view taken along a line IV-IV of FIG. 3.

[0071] FIG. 5 is a cross-sectional view taken along a line V-V of FIG. 3.

[0072] FIG. 6 is a graph showing the relationship between a liquid crystal driving voltage and a relative brightness in a normally white mode.

[0073] FIG. 7 is a graph showing a voltage value between a pixel electrode and a reference electrode in a common inversion in relation to time.

[0074] FIG. 8 is a graph showing a voltage value between a pixel electrode and a reference electrode in a fixed common voltage in relation to time.

[0075] FIG. 9 is an explanatory view showing the generation of distortion of signals at the time of transmitting signals to a signal line.

[0076] **FIG. 10** is a side view showing drivers (gate drive IC, drain drive IC) which are connected to the signal lines and the constitution in the vicinity of the drivers.

[0077] **FIG. 11** is an explanatory view showing a phenomenon that portions close to drivers in a display region of a liquid crystal display device are discolored.

[0078] **FIG. 12** is a constitutional view showing one embodiment of support columns which are arranged between respective substrates which are arranged to face each other via liquid crystal of a liquid crystal display device.

[0079] **FIG. 13** is a constitutional view showing another embodiment of a pixel of the liquid crystal display device according to the present invention.

[0080] **FIG. 14** is a plan view showing one embodiment of a reference electrode which is formed on a liquid crystal display device according to the present invention.

[0081] **FIG. 15** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0082] **FIG. 16** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0083] **FIG. 17** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0084] **FIG. 18** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0085] **FIG. 19** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0086] **FIG. 20** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0087] **FIG. 21** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0088] **FIG. 22** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0089] **FIG. 23** is a cross-sectional view showing one embodiment of a through hole formed in the inside of the pixel of the liquid crystal display device according to the present invention.

[0090] **FIG. 24** is a cross-sectional view showing another embodiment of a through hole formed in the inside of the pixel of the liquid crystal display device according to the present invention.

[0091] **FIG. 25** is a cross-sectional view showing another embodiment of a through hole formed in the inside of the pixel of the liquid crystal display device according to the present invention.

[0092] **FIG. 26** is a cross-sectional view showing another embodiment of a through hole formed in the inside of the pixel of the liquid crystal display device according to the present invention.

[0093] **FIG. 27** is a cross-sectional view showing one embodiment of the arrangement of a through hole formed in the inside of the pixel of the liquid crystal display device according to the present invention.

[0094] **FIG. 28** is a cross-sectional view showing another embodiment of a through hole formed in the inside of the pixel of the liquid crystal display device according to the present invention.

[0095] **FIG. 29** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0096] **FIG. 30** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0097] **FIG. 31** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0098] **FIG. 32** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0099] **FIG. 33** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0100] **FIG. 34** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0101] **FIG. 35** is a cross-sectional view of **FIG. 34** taken along a line 35-35.

[0102] **FIG. 36** is a view showing another embodiment of the liquid crystal display device according to the present invention and is a view which corresponds to **FIG. 35**.

[0103] **FIG. 37** is a view showing another embodiment of the liquid crystal display device according to the present invention and is a view which corresponds to **FIG. 35**.

[0104] **FIG. 38** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0105] **FIG. 39** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0106] **FIG. 40** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0107] **FIG. 41** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0108] **FIG. 42** is a constitutional view showing another embodiment of the pixel of the liquid crystal display device according to the present invention.

[0109] **FIG. 43** is a constitutional view showing another embodiment of the liquid crystal display device according to the present invention and more specifically to a plan view showing a portion where respective reference voltage signal lines are pulled out.

[0110] **FIG. 44** is a constitutional view showing another embodiment of the liquid crystal display device according to

the present invention and more specifically to a cross-sectional view showing a portion where respective reference voltage signal lines are pulled out.

[0111] FIG. 45 is a constitutional view showing another embodiment of the liquid crystal display device according to the present invention and more specifically to a cross-sectional view showing a portion where respective reference voltage signal lines are pulled out.

[0112] FIG. 46 is a constitutional view showing another embodiment of the liquid crystal display device according to the present invention and more specifically to a cross-sectional view showing a portion where respective reference voltage signal lines are pulled out.

[0113] FIG. 47 is a constitutional view showing another embodiment of the liquid crystal display device according to the present invention and more specifically to a cross-sectional view showing a portion where respective reference voltage signal lines are pulled out.

[0114] FIG. 48 is a constitutional view showing another embodiment of the liquid crystal display device according to the present invention and is more specifically a plan view showing a portion in the vicinity of a driver mounting portion.

[0115] FIG. 49 is a constitutional view showing another embodiment of the liquid crystal display device according to the present invention and is more specifically is a plan view showing a portion in the vicinity of a driver mounting portion.

[0116] FIG. 50 is an explanatory view showing an ionic image sticking phenomenon in the inside of the liquid crystal and the ionic image sticking strength.

[0117] FIG. 51 is a constitutional view showing another embodiment of the liquid crystal display device according to the present invention.

[0118] FIG. 52 is a graph showing the relationship between the electrode embedded state to an insulation film and the leaking of light in the vicinity of the electrode in the constitution shown in FIG. 51.

[0119] FIG. 53 is a graph showing the relationship among the dielectric anisotropy of the liquid crystal, the distance between the pixel electrode and the reference electrode, and inter-electrode voltage Vmax.

[0120] FIG. 54 is a graph showing the relationship among a film thickness of a protective film made of organic material with the dielectric anisotropy of the liquid crystal set to 10, the distance between the pixel electrode and the reference electrode and the inter-electrode voltage Vmax.

[0121] FIG. 55 is a graph showing the relationship among a film thickness of a protective film made of organic material, the distance between the pixel electrode and the reference electrode and the inter-electrode voltage Vmax with the dielectric anisotropy of the liquid crystal set to 14.5.

[0122] FIG. 56 is a structural formula showing one embodiment of a liquid crystal contained in the liquid crystal used in the liquid crystal display device according to the present invention.

[0123] FIG. 57 is a structural formula showing one embodiment of a liquid crystal contained in the liquid crystal used in the liquid crystal display device according to the present invention.

[0124] FIG. 58 is a plan view showing a portion in the vicinity of a region on which drivers of the liquid crystal display device according to the present invention is mounted.

DESCRIPTION OF THE PREFERRED EMBODIMENTS

[0125] Embodiments of a liquid crystal display device according to the present invention are explained hereinafter in conjunction with attached drawings.

[0126] (Embodiment 1)

[0127] (Equivalent Circuit of Liquid Crystal Display Device)

[0128] FIG. 2 is an equivalent circuit block diagram showing one embodiment of a liquid crystal display device according to the present invention. Although this drawing is a circuit block diagram, they are drawn corresponding to the actual geometric arrangement.

[0129] In this embodiment, the present invention is applied to a liquid crystal display device which adopts a so-called lateral electric field method which is known as a method having a broad viewing angle.

[0130] First, the liquid crystal display device includes a liquid crystal display panel PNL and this liquid crystal display panel PNL uses transparent substrates SUB1, SUB2 which are arranged to face each other in an opposed manner while sandwiching a liquid crystal between them as an envelope. In this case, one transparent substrate (in the drawing, a lower-side substrate: a matrix substrate) is formed slightly larger than the other transparent substrate (in the drawing, an upper-side substrate: a color filter substrate). In the drawing, the transparent substrates are arranged such that lower-side and right-side peripheral ends are disposed substantially on a coplanar plane.

[0131] As a result, the left-side periphery in the drawing and the upper-side periphery in the drawing of one transparent substrate SUB1 are extended outwardly from the other transparent substrate SUB2. As will be explained later in detail, this portion defines a region where a gate drive circuit (IC) 5 and a drain drive circuit (IC) 6 are mounted.

[0132] In a region where respective transparent substrate SUB1, SUB2 are superposed, pixels 2 which are arranged in a matrix array are formed. The pixels 2 are formed in regions which are surrounded by gate signal lines GL which are extended in the x direction and are arranged in parallel in the y direction in the drawing and drain signal lines DL which are extended in the y direction and are arranged in parallel in the x direction. Each pixel 2 is provided with at least a switching element TFT which is driven by the supply of scanning signals from one-side gate signal line GL and a pixel electrode to which video signals supplied from one-side drain signal line DL via the switching element TFT are applied.

[0133] Here, as mentioned previously, since the liquid crystal display device adopts the so-called lateral electric field method, as will be explained in detail later, each pixel 2 includes a reference electrode CT and a holding capacity Cstg besides the above-mentioned switching element TFT and pixel electrode PX.

[0134] Then, each gate signal line GL has one end thereof (left-side end portion in the drawing) extended to the outside of the transparent substrate SUB1 and connected to an output terminal of the gate drive circuit 5 mounted on the transparent substrate SUB1.

[0135] In this case, a plurality of gate drive circuits 5 are provided and the gate signal line GL and neighboring gate signal lines are formed into a group (see FIG. 58) and these respective grouped gate signal lines GL are respectively connected to respective gate drive circuits 5 which are disposed close to the gate signal lines GL.

[0136] Further, in the same manner, respective drain signal lines DL have one ends thereof (upper-side end portions in the drawing) extended to the outside of the transparent substrate SUB1 and connected to an output terminal of the drain drive circuit 6.

[0137] Also in this case, a plurality of drain drive circuits 6 are provided and the above-mentioned drain signal line DL and neighboring drain signal lines are formed into a group and these respective grouped drain signal lines DL are respectively connected to respective drain drive circuits 6 which are disposed close to the drain signal lines DL.

[0138] On the other hand, the liquid crystal display device includes a printed circuit board 10 (control circuit board 10) which is arranged adjacent to the liquid crystal display panel PNL on which the gate drive circuits 5 and the drain drive circuits 6 are mounted. In addition to a power supply circuit 11 and the like, a control circuit (IC) 12 for supplying input signals to the gate drive circuits 5 and the drain drive circuits 6 is mounted on the printed circuit board 10.

[0139] Signals outputted from this control circuit 12 are supplied to the gate drive circuits 5 and the drain drive circuits 6 via a flexible wiring board (a gate circuit board 15, a drain circuit board 16A, a drain circuit board 16B).

[0140] That is, at the gate drive circuits 5 side, the flexible wiring board (gate circuit board 15) provided with terminals which are respectively connected to input-side terminals of respective gate drive circuits 5 in an opposed manner is provided.

[0141] The gate circuit board 15 has a portion thereof extended to the above-mentioned control circuit board 10 side and an extension portion thereof is connected to the control circuit board 10 via a connecting portion 18.

[0142] Output signals from the control circuit 12 which is mounted on the control circuit board 10 are inputted to respective gate drive circuits 5 via a wiring layer formed on the control circuit board 10, the above-mentioned connecting portion 18 and a wiring layer formed on the gate circuit board 15.

[0143] Further, at the drain drive circuits 6 side, the drain circuit boards 16A, 16B provided with terminals which are respectively connected with input-side terminals of respective drain drive circuits 6 in an opposed manner are arranged.

[0144] These drain circuit boards 16A, 16B have portions thereof extended to the above-mentioned control circuit board 10 side and these extension portions are connected with the control circuit board 10 via connecting portions 19A, 19B.

[0145] Output signals from the control circuit 12 which is mounted on the control circuit board 10 are inputted to respective drain drive circuits 6 via a wiring layer formed on the control circuit board 10, the above-mentioned connecting portions 19A, 19B and wiring layers formed on the drain circuit boards 16A, 16B.

[0146] As shown in the drawing, the drain circuit boards 16A, 16B at the drain drive circuit 6 side are divided in two elements. This provision is made to prevent a problem brought about by making the liquid crystal display panel 1 large-sized, for example, a problem caused by a thermal expansion due to the increase of the length of the drain circuit board in the x direction in the drawing.

[0147] Then, output signals from the control circuit 12 on the control circuit board 10 are inputted to the corresponding drain drive circuits 6 via the connecting portion 19A of the drain circuit board 16A and the connecting portion 19B of the drain circuit board 16B respectively.

[0148] Further, video signals are supplied from a video signal source 22 to the control circuit board 10 via an interface board 24 through a cable 23 and the video signals are inputted to the control circuit 12 which is mounted on the control circuit board 10.

[0149] In the drawing, although the liquid crystal display panel PNL, the gate circuit board 15, the drain circuit boards 16A, 16B and the control circuit board 10 are depicted as being positioned substantially on the same plane, in reality, the control circuit board 10 is bent at portions of the gate circuit board 15 and the drain circuit boards 16A, 16B such that the control circuit board 10 is positioned substantially perpendicular to the liquid crystal display panel 1.

[0150] This provision is provided to narrow the area of a picture frame. Here, the picture frame means a region formed between a profile of an outer frame of the liquid crystal display panel PNL and a profile of a display region AR. By narrowing this area, an advantageous effect that the area of a display portion relative to the outer frame can be increased is achieved.

[0151] <<Constitution of Pixel>>

[0152] Here, as mentioned above, in the liquid crystal display panel PNL, the display region portion AR is constituted of a large number of pixels 2 which are arranged in a matrix array and one of such pixels has the constitution shown in FIG. 3. Further, FIG. 4 is a cross-sectional view of FIG. 3 taken along a line IV-IV and FIG. 5 is a cross-sectional view of FIG. 3 taken along a line V-V.

[0153] In the drawing, the gate signal line GL and a reference voltage signal line CL which are extended in the x direction are formed on a main surface of the transparent substrate SUB1. A region which is surrounded by these respective signal lines GL, CL and the drain signal lines DL which are extended in the y direction as will be explained later is formed as a pixel region.

[0154] That is, in this embodiment, the reference voltage signal line CL is formed such that the reference voltage signal line CL runs between the gate signal lines GL and the pixel regions are formed respectively in the y direction using the reference voltage signal line CL as a boundary.

[0155] Due to such a constitution, the reference voltage signal lines CL which are arranged in parallel in the y

direction can be decreased in number to approximately half of the conventional liquid crystal display panel so that the regions which are closed by the reference voltage signal lines CL can be shared by the pixel region sides whereby the areas of the pixel regions can be increased.

[0156] In each pixel region, on the reference voltage signal line CL, three reference electrodes CT which are extended in the y direction integral with the reference voltage signal line CL are formed in an equidistantly spaced-apart manner. These respective reference electrodes CT are extended close to the gate signal line GL without being connected with the gate signal line GL. Among these reference electrodes CT, two reference electrodes CT at both sides are arranged close to the drain signal line DL and the remaining one reference electrode CT is positioned at the center.

[0157] Further, on the main surface of the transparent substrate SUB1 on which the gate signal line GL, the reference voltage signal line CL and the reference electrodes CT are formed in the above-mentioned manner, an insulation film GI which also covers these gate signal lines GL and the like and is made of a silicon nitride film, for example, is formed. This insulation film GI functions as an interlayer insulation film for ensuring the insulation of the gate signal line GL and the reference voltage signal line CL against the drain signal line DL which will be explained later, as a gate insulation film against a thin film transistor TFT, and as a dielectric film against a storage capacity Cstg.

[0158] On a surface of this insulation film GI, first of all, a semiconductor layer AS is formed in a formation region of the thin film transistor TFT. This semiconductor layer AS is, for example, made of amorphous Si and is formed on a portion of the gate signal line GL close to the drain signal line DL which will be explained later in a superposed manner. Due to such a constitution, a portion of the gate signal line GL also functions as the gate electrode of the thin film transistor TFT.

[0159] Then, on the surface of the insulation film GI, the drain signal line DL which is extended in the y direction and is arranged in parallel in the x direction is formed. This drain signal line DL is integrally provided with the drain electrode SD1 which is formed such that the drain electrode SD1 is extended to a portion of a surface of the semiconductor layer AS which constitutes the thin film transistor TFT.

[0160] Further, on the surface of the insulation film GI in the pixel region, the pixel electrode PX which is connected to a source electrode SD2 of the thin film transistor TFT is formed. This pixel electrode PX is extended in the y direction at respective centers of the reference electrodes CT. That is, one end of the pixel electrode PX also functions as a source electrode SD2 of the thin film transistor TFT, is extended in the y direction as it is, and is further extended in the x direction on the reference voltage signal line CL to form a U shape extending in the y direction.

[0161] Here, a portion of the pixel electrode PX which is superposed on the reference voltage signal line CL constitutes a storage capacity Cstg which uses the insulation film GI as a dielectric film between the portion and the reference voltage signal line CL. With the use of this storage capacity Cstg, an advantageous effect that video information can be stored for a long time in the pixel electrode PX when the thin film transistor TFT is turned off can be achieved.

[0162] A surface of the semiconductor layer AS which corresponds to an interface between the drain electrode SD1 and the source electrode SD2 of the above-mentioned thin film transistor TFT is doped with phosphorus (P) thus forming a high concentration layer. Due to such a constitution, respective electrodes have an ohmic contact. In this case, the high concentration layer is formed on the whole area of the surface of the semiconductor layer AS and hence, after forming respective electrodes, by etching the high concentration layer other than the electrode forming region using the electrodes as masks, the abovementioned constitution is obtained.

[0163] On the upper surface of the insulation film GI on which the thin film transistor TFT, the drain signal line DL, the pixel electrode PX and the storage capacity Cstg are formed, a protective film PSV made of a silicon nitride film, for example, is formed. Further, on an upper surface of the protective film PSV, an orientation film ORI1 is formed thus constituting a so-called lower-side substrate of the liquid crystal display panel PNL.

[0164] Here, both of the reference electrodes CT and the pixel electrode PX may be formed of an opaque material layer such as metal or at least one of them may be formed of a light-transmitting material layer such as ITO (indium-tin-oxide) or the like. In the latter case, an advantageous effect that the numerical aperture of the pixel can be enhanced is obtained.

[0165] Further, on a liquid-crystal-side portion of the transparent substrate (color filter substrate) SUB2 which constitutes an upper-side substrate, a black matrix BM which has aperture portions at portions thereof corresponding to respective pixel regions is formed.

[0166] Further, color filters FIL are formed such that the color filters FIL cover the aperture portions which are formed at portions of the black matrix BM corresponding to the pixel regions. Each color filter FIL has a color which is different from colors of the neighboring pixel regions in the x direction. Further, these color filters FIL respectively define boundary portions on the black matrix BM.

[0167] Further, on the surface on which the black matrix BM and the color filters FIL are formed, a flat film OC which is made of a resin film or the like is formed and an orientation film ORI2 is formed on the flat film OC.

[0168] Here, in this embodiment, when no electric field is generated between the pixel electrode PX and the reference electrode CT, a so-called normally black mode in which the liquid crystal exhibits the minimum light transmittivity is established.

[0169] Then, the maximum amplitude of video signals (voltage) supplied to the drain signal line DL is set to a value not more than a voltage (V90) which is necessary for setting the relative transmittivity of the liquid crystal layer LC to 90%.

[0170] Based on the fact that the liquid crystal display device of this embodiment adopts the normally black mode, the large reduction of the liquid crystal driving voltage and the suppression of the influence derived from the lowering of the contrast ratio can be achieved.

[0171] That is, FIG. 1 is a graph showing the relationship between the liquid crystal driving voltage (V) and the

relative brightness (%) in the normally black mode. In the normally black mode, although the white display brightness depends on the voltage, the white display brightness exhibits the saturation tendency in the vicinity of a voltage (Vmax) which gives the relative brightness of 100%. This implies that no substantial change occurs with respect to the brightness even when the liquid crystal is driven in the vicinity of the voltage (Vmax) which gives the relative brightness of 100%.

[0172] Accordingly, by suppressing the brightness to not more than 90% to provide the white display, the liquid crystal driving voltage can be largely reduced.

[0173] This implies that as the drain drive IC which supplies the video signals to the drain signal line DL, a drain drive IC with a small output can be selected and a heat generation quantity can be also reduced.

[0174] Further, the black display in this case is the non-current supply state and hence, the influence to the contrast ratio can be suppressed compared to the case of normally white mode (characteristics thereof being shown in FIG. 6).

[0175] (Embodiment 2)

[0176] This embodiment is characterized in that reference signals which are supplied to the reference electrodes CT of each pixel region via the reference voltage signal line CL are inverted every frame.

[0177] As shown in FIG. 7, this implies that the amplitude V of the video signals is determined in response to the reference signals which are inverted by a unit of a frame and hence, the amplitude of the video signals can be made small as a whole.

[0178] To consider a case in which the reference signals are set constant by a unit of a frame as shown in FIG. 8 for a comparison purpose, it is necessary for the video signals to take an amplitude V in the (+) side and an amplitude V in the (-) side in response to the reference signals.

[0179] Accordingly, this embodiment can reduce the amplitude of the video signal by half compared to FIG. 8.

[0180] This implies that as the drain drive IC, a drain drive IC with a small output can be selected and a heat generation quantity can be also reduced.

[0181] (Embodiment 3)

[0182] In this embodiment, out of the drain signal line DL and the reference voltage signal line CL, the signal line to which signals having a larger average voltage amplitude by a unit of a frame are supplied is set to have a resistance lower than that of the other signal line.

[0183] Although various drive waveforms which are inputted to the signal lines exhibit a shape approximating a rectangular shape as shown in FIG. 9(a) at an input end thereof, they exhibit a deformed waveform as shown in FIG. 9(b) at a remote end thereof due to the resistance of the signal lines or the parasitic capacity.

[0184] A uniform display is required on the entire region of the display surface of the liquid crystal display panel PNL and hence, it is necessary for the actual input signals to preliminarily increase the amplitude of the input voltage in

consideration of a distortion amount of this waveform. However, the driving voltage is required to be elevated further correspondingly.

[0185] Accordingly, with the use of the wiring which has the resistance lower than that of other signal line as the signal line to which the signals having the maximum average amplitude per a frame are applied, the distortion of the waveform on the signal line having the large amplitude is reduced without using any particularly large voltage signals.

[0186] In this case, in the drive which makes the reference signal (voltage) constant (see FIG. 8), it is advantageous to set the specific resistance of the wiring of the drain signal line DL lower than that of the reference voltage signal line CL.

[0187] For example, the drain signal line DL may be made of Al, an alloy including Al or a multi-layered structure made of these materials and the reference signal line may be made of Al, Cr, Ta, Mo, W, an alloy including at least one of these metals or a multi-layered structure made of these materials.

[0188] Further, the drain signal line DL may be made of Cr, an alloy including Cr or a multi-layered structure made of these materials and the reference signal line may be made of Cr, Ta, Mo, W, an alloy including at least one of these metals or a multi-layered structure made of these materials.

[0189] Further, the drain signal line DL may be made of Al, Cr, Mo, Ta, W, an alloy including at least one of these metals or a multi-layered structure made of these materials and the reference signal line may be made of ITO, In_2O_3 , SnO_2 .

[0190] Further, in the drive which inverts the reference voltage signal CL every frame, it is advantageous to set the specific resistance of the reference voltage signal line CL lower than that of the drain signal line DL.

[0191] For example, the drain signal line DL may be made of Al, Cr, Ta, Mo, W, an alloy including at least one of these metals or a multi-layered structure made of these materials and the reference signal line may be made of Al, Cr, an alloy including at least one of these metals or a multi-layered structure made of these materials.

[0192] Further, it is needless to say that the drain signal line DL and the reference voltage signal line CL are constituted of a multi-layered structure made of the same kind of material and the above-mentioned relationship is sufficed by increasing or decreasing a width of one of these lines, for example.

[0193] (Embodiment 4)

[0194] FIG. 10(a) is a view showing the cross section of FIG. 2 taken along a line x-x. The drain drive IC 6 made of a semiconductor chip has a surface on which an input bump and an output bump are formed face the transparent substrate SUB1 in an opposed manner (face-down) and respective bumps are connected to terminals of a wiring layer formed on the transparent substrate SUB1 surface (referred to as "FCA method" in this specification).

[0195] In this case, the drain drive ICs 6 ensure a gap of a value not less than a height of the bumps between the drain drive ICs and the transparent substrate SUB1 side at regions

which are defined between a group of input bumps and a group of output bumps which are arranged in parallel.

[0196] A stress buffer layer 31 is formed on the transparent substrate SUB1 side such that the stress buffer layer 31 fills the gap. With the provision of such a stress buffer layer 31 formed on the transparent substrate SUB1 side, the deflection of the drain drive ICs 6 (deflection which is bulged toward the transparent substrate SUB1 side at a center portion of the drain drive IC) can be absorbed.

[0197] Due to such a constitution, the stress generated in the drain drive IC 6 is hardly transmitted to the transparent substrate SUB1 side and hence, the local alignment displacement between the transparent substrate SUB1 and the transparent substrate SUB2 in the vicinity of the drain ICs 6 can be obviated.

[0198] Further, FIG. 10(b) is a constitutional view showing another embodiment and corresponds to FIG. 10b.

[0199] In FIG. 10(b), the stress buffer layer 31 is not limited to the region on which the drain drive IC 6 is mounted and is formed such that the stress buffer layer 31 is extended to the periphery of the drain drive IC 6. Further, a wiring layer (drain signal layer DL) which is connected to respective bumps of the drain drive IC 6 is formed on an upper surface of the stress buffer layer 31.

[0200] There may be a case that the above-mentioned protective film PSV formed on each pixel region is formed of a sequential laminated body which is comprised of an inorganic material layer made of a SiN film and an organic material layer made of resin. This is because that there is a case that the dielectric constant of the protective film PSV is required to be made small or a case that cracks or the like generated in the inorganic material layer are required to be covered with the organic material layer.

[0201] In such a case, by simultaneously forming the stress buffer layer 31 (the stress buffer layer 31 may be formed by extending the stress buffer layer) at the time of forming the organic material layer, the increase of the number of man-hours can be obviated.

[0202] Although this embodiment is explained with respect to the drain drive IC 6, the same goes for the gate drive IC 5 and hence, it is needless to say that the similar constitution may be adopted by the region where the gate drive IC 5 is mounted.

[0203] (Embodiment 5)

[0204] Although the explanation has been made that the transparent substrate SUB1 is made of the glass substrate in the previous embodiments, this embodiment particularly adopts a resin substrate made of resin as the transparent substrate SUB1.

[0205] The drain drive IC 6 and the gate drive ICs 5 are mounted on the transparent substrate SUB1. By using resin having the higher elastic property compared to glass as the substrate, any drawbacks derived from the stress generated in each drive IC can be solved.

[0206] By adopting at least one of the above-mentioned respective embodiments, the driving power of the drive ICs can be reduced and a heat generation quantity derived from the driving of the drive ICs can be reduced. Accordingly, as shown in FIG. 11, in regions TR close to the drive ICs in the

display region portion AR, it becomes possible to obviate the influence (discoloring) derived from the generation of heat.

[0207] (Embodiment 6)

[0208] As shown in FIG. 12, out of respective transparent substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, a light shielding film which is referred to as a black matrix BM is formed on the transparent substrate SUB2. Here, in the drawing, FIG. 12(a) is a plan view and FIG. 12(b) is a cross-sectional view of FIG. 12(a) taken along a line b-b.

[0209] As a spacer for ensuring a gap between the transparent substrate SUB1 and the transparent substrate SUB2, for example, support columns 33 which are formed by selectively etching a resin layer formed on the transparent substrate SUB2 side using a photolithography technique are used.

[0210] These support columns 33 can be arranged at given positions in the inside of the display portion which is formed as a mass of respective pixel regions. These support columns 33 are formed such that they are superposed on the black matrix BM.

[0211] This is because that the disorder of the orientation of the molecules of liquid crystal is liable to occur in the peripheries of the support columns 33 and the disorder can be easily observed with naked eyes (referred to as "domains").

[0212] In this embodiment, the black matrix BM has a width thereof increased in the vicinity of the drain drive ICs 6 and the gate drive ICs 5 than a width thereof at other portions.

[0213] The reason for providing such a constitution is that the alignment displacement of the transparent substrates SUB1, SUB2 is liable to occur in the vicinity of the respective drive ICs due to the generation of heat of the drive ICs in such locations and the domains are more liable to be visualized due to such alignment displacement.

[0214] The light shielding film is not limited to the black matrix BM and it is needless to say that any light shielding films for other purposes can be used as such a light shielding film.

[0215] (Embodiment 7)

[0216] This embodiment is characterized in that the abovementioned support columns in the inside of the display portion are arranged at a density of one support column per two to eight unit pixels.

[0217] Here, the unit pixel is defined such that 1 unit pixel is formed of a set made of RGB or a set of CMY.

[0218] Assume a case in which the above-mentioned support columns are arranged at a density of less than 1 support column per eight unit pixels. In this case, the upper and lower substrates are easily moved due to the stress and the alignment displacement is worsened due to the provision of the support columns. Further, the strength of the support columns cannot withstand the stress so that it gives rise to the non-uniformity of gap between the upper and lower substrates due to the plastic deformation.

[0219] Although the above-mentioned respective embodiments describe cases in which the respective embodiments are applied to a liquid crystal display device having a pixel constitution shown in **FIG. 13**, the respective embodiments are applicable to liquid crystal display devices having pixel constitutions which are explained hereinafter.

[0220] (Embodiment 8)

[0221] As shown in **FIG. 13**, in this embodiment, a drain signal line DL and a pixel electrode PX are positioned on the same layer and reference electrodes CT are formed as a layer above the drain signal line DL and the pixel electrode PX via a protective film PSV1. Further, the reference electrode CT is connected with a reference voltage signal line CL which is formed on the same layer as a gate signal line GL via a through hole TH. In the drawing, **FIG. 13(a)** is a plan view, **FIG. 13(b)** is a cross-sectional view of **FIG. 13(a)** taken along a line b-b, and **FIG. 13(c)** is a cross-sectional view of **FIG. 13(a)** taken along a line c-c.

[0222] The reference electrodes CT are formed such that the reference electrodes CT are superposed on the drain signal line D1 and hence, it becomes possible to prevent an unexpected behavior (domain) of the liquid crystal due to the an electric field generated between the drain signal line DL and the reference electrodes CT from being visualized or observed from outside.

[0223] That is, this embodiment adopts the constitution in which the reference electrodes CT perform the light shielding of the domains which are generated due to the electric field derived from the drain signal line DL.

[0224] Further, due to such a constitution, the electric field from the drain signal line DL is terminated to the reference electrode CT side whose potential is fixed so that the influence to the pixel region side can be suppressed.

[0225] The reference electrodes CT may be formed of an opaque conductive layer such as a metal layer or may be formed of a transparent conductive layer such as an ITO (Indium-Tin-Oxide) layer.

[0226] Here, when the reference electrodes CT are constituted of the transparent conductive layer, to make the reference electrodes CT have the function as a light shielding film which performs the light-shielding of visualization of the domain, it is necessary to adopt the normally white mode.

[0227] The normally white mode is formed by selecting material of the liquid crystal which can minimize the light transmittivity of the liquid crystal when the electric field is not generated between the pixel electrode CT and the reference voltage electrode CL.

[0228] The material of the transparent conductive layer is not limited to ITO. The transparent conductive layer may be made of In_2O_3 , SnO_2 , IZO, ZnO_2 , a mixture thereof or a laminated body thereof.

[0229] Further, in this embodiment, a protective film PSV2 is formed on upper surfaces of the reference electrodes CT and an orientation film (not shown in the drawing) is formed on an upper surface of the protective film PSV2.

[0230] Here, organic material such as resin or the like can be used as material of the protective film PSV2. In this case, the surface of the protective film PSV2 can be flattened.

[0231] (Embodiment 9)

[0232] This embodiment is characterized in that, in the constitution shown in the embodiment 8 (**FIG. 13**), the protective film PSV1 is formed of a sequential laminated body which is constituted of inorganic material made of SiN and organic material made of resin, for example.

[0233] In this case, an advantageous effect that the dielectric constant between the pixel electrode PX and the reference electrode CT can be suppressed to a low value.

[0234] (Embodiment 10)

[0235] This embodiment is characterized in that, in the constitution of the above-mentioned embodiment 8 (**FIG. 13**) provided that the reference electrodes CT are particularly constituted of metal layers, a protective film PSV2 is formed on upper surfaces of the reference electrodes CT such that the protective films PSV2 cover the reference electrodes CT and an orientation film is formed on the upper surface of the protective film PSV2.

[0236] When the reference electrodes CT are constituted of the metal layers, the metal layers face the liquid crystal in an opposed manner via the extremely thin orientation film so that the metal layers are liable to generate a chemical reaction with the liquid crystal and there arises an unfavorable phenomenon such as an electrolytic corrosion or the like.

[0237] Accordingly, by inserting an insulation film between the reference electrodes CT and the orientation film, the protection of the reference electrodes CT is achieved.

[0238] The material of the insulation film may be, for example, inorganic material such as SiN, SiO_2 or organic material such as resin.

[0239] (Embodiment 11)

[0240] In this embodiment, as shown in **FIG. 13**, a reference signal line CL which supplies reference signals to the reference electrodes CT is formed as the same layer as a gate signal line GT and is made of the same material (metal layer) as the gate signal line GT.

[0241] The reference signal line CL is arranged substantially in parallel with the gate signal line GL and is positioned substantially at the center between neighboring gate signal lines GL which are arranged close to each other.

[0242] Then, the reference electrodes CT are formed on the protective film PSV1 disposed above the surface of the transparent substrate SUB1 on which the reference signal line CL is formed via the insulation film GI and the protective film PSV1.

[0243] The connection of the reference signal line CL and the reference electrodes CT is established via a through hole TH which is formed in the protective film PSV1 and the insulation film GI substantially at the center of the pixel region.

[0244] The reference electrodes CT are formed of ITO films, for example, and are formed as three electrodes in total which are extended in the y direction and are arranged in parallel in the x direction in the drawing.

[0245] In this case, the center reference electrode CT is connected with the reference signal line CL via the through hole TH and the remaining two reference electrodes CT except for the above-mentioned reference electrode CT are respectively formed such that they are superposed on the video signal lines DL. Further, Upper and lower end portions of each reference electrode CT are connected to each other with the use of an ITO film which is superposed on the gate signal line GL.

[0246] Accordingly, the ITO film which is formed on the protective film PSV1 is formed such that the protective film PSV1 surrounds the pixel region, in other words, the ITO film is superposed on the drain signal line DL and the gate signal line GL, and has a width larger than the widths of these signal lines.

[0247] This ITO film is integrally formed with ITO films of other neighboring pixel regions.

[0248] Due to such a constitution, the ITO film can be formed in a grid array in the inside of the display region and hence, an advantageous effect that the resistance value of the ITO film per se can be reduced is obtained.

[0249] Further, since the reference signal line CL which supplies the reference signals to this ITO film is formed of a metal layer having a low resistance value, the generation of signal distortion of the reference signals supplied to the reference electrodes CT can be suppressed.

[0250] (Embodiment 12)

[0251] This embodiment is characterized in that, in the constitution of the above-mentioned embodiment 11, the protective film PSV1 is formed of a sequential laminated body which is constituted of inorganic material made of SiN and organic material made of resin, for example.

[0252] (Embodiment 13)

[0253] In the embodiments 11 and 12, the reference voltage signal line CL is formed of the metal layer and the reference electrodes CT are formed of light-transmitting conductive layers made of ITO or the like. However, so long as the resistance of the material layer of the reference voltage signal line CL is set smaller than the resistance of the material layer of the reference electrodes CT, the reference voltage signal line CL and the reference electrodes CT are not always limited to these materials. Due to such a constitution, the total resistance of the reference voltage signal line CL and the reference electrodes CT can be reduced and hence, stabilization of the potential of the reference signals supplied to respective reference electrodes CT can be ensured.

[0254] (Embodiment 14)

[0255] This embodiment is characterized in that, in the constitution of the embodiment 11 (FIG. 13), a normally black mode is adopted.

[0256] That is, when an electric field is not applied between the pixel electrode PX and the reference electrodes CT, the liquid crystal is set to exhibit the minimum light transmittivity (black display).

[0257] In this case, the ITO film which includes the reference electrode CT as a portion thereof functions as a light shielding film and hence, the light shielding film which

can sufficiently cover the gate signal line GL and the drain signal line DL can be formed.

[0258] This implies that it becomes possible to obtain an advantageous effect that it is unnecessary to form a light shielding film having the similar function such as a black matrix or the like in a separate step.

[0259] In this case, the material which forms the reference electrode as a portion thereof is not limited to ITO and may be In_2O_3 , SnO_2 , IZO, ZnO_2 , a mixed body thereof or a laminated body thereof.

[0260] (Embodiment 15)

[0261] In respective embodiments 11 to 14, the material layer which forms the reference electrode CT as a portion thereof is formed in a grid array in the inside of the display region and hence, the reference signals can be also supplied to this material layer.

[0262] Accordingly, in this embodiment, needless to say that the reference signals are supplied to the reference voltage signal line CL, the reference signals are also supplied to the material layer which forms the reference electrodes CT as a portion thereof. In this case, the pixel region is constituted such that the reference signals are supplied from the direction which intersects the extension direction of the reference signal line CL at a right angle.

[0263] That is, among peripheral sides of the material layer which forms the reference electrode CT as a portion thereof, the reference signals are supplied from either one or both of the peripheral sides which are in parallel to the x direction in the drawing.

[0264] In this case, as shown in FIG. 14, a strip-like metal layer 35 having a low resistance is superposed on one side of the material layer and the reference signals are supplied via this metal layer 35.

[0265] Due to such a constitution, the waveform distortion of the reference signals supplied to the reference electrodes CT in each pixel region can be alleviated.

[0266] It is needless to say that, in this embodiment, the material layer which includes the above-mentioned reference electrode CT as a portion thereof may be made of material having a high light transmittivity or a metal layer.

[0267] (Embodiment 16)

[0268] This embodiment is characterized in that, in either constitution of the above-mentioned embodiment 13 or 15, the reference signals are inverted every 1 frame (common inversion driving).

[0269] As mentioned previously, since the reference voltage signal line CL has the resistance which is set lower than the resistance of the reference electrodes CT, the waveform distortion of signals at the time of supplying the reference signals to the reference electrodes CT can be reduced.

[0270] Further, since this embodiment adopts the common inversion driving and hence, the output of the drain drive IC can be reduced so that a drive IC with a small output can be used as such a drain drive IC.

[0271] In this case, when the FCA method is adopted as a method for mounting the drain drive IC, the generation of

heat of the drain drive IC becomes small and hence, the use of the reliable drain drive IC is realized.

[0272] Further, due to such a constitution, along with the suppression of the signal distortions in the reference voltage signal line DL (Al, Cr, Ta, Mo, W, a mixed body thereof or a laminated body), the signal distortion in the drain signal line DL can be suppressed by using Al, Cr, a mixed body thereof or a laminated body thereof as the material of the drain signal line.

[0273] (Embodiment 17)

[0274] As shown in **FIG. 13**, in this embodiment, a through hole TH which is formed in the inside of the pixel region is substantially formed at the center of neighboring respective pixel electrodes PX and the connection of the reference voltage signal line CL and the reference electrode CT is established via this through hole TH.

[0275] Due to such a constitution, the probability of the occurrence of the short-circuiting of the through hole TH and the neighboring pixel electrode PX can be decreased.

[0276] (Embodiment 18)

[0277] As shown in **FIG. 13**, this embodiment is characterized in that a diameter of the through hole TH is set smaller than the width of the reference voltage signal line CL and is also set smaller than width of the reference electrode CT.

[0278] Due to such a constitution, the occurrence of disconnection at the through hole TH portion of the reference electrode CT can be reduced.

[0279] (Embodiment 19)

[0280] In this embodiment, as shown in **FIG. 15**, a material layer which includes a reference electrode CT as a portion thereof is formed on a protective film PSV1 via a reference voltage signal line CL and a protective film PSV1, and this material layer includes a strip-like portion 37 which is superposed along at least the reference voltage signal line CL and a reference electrode CT which is extended such that the reference electrode CT intersects this strip-like portion 37, and the material layer is connected with the reference voltage signal line CL via a through hole TH at the intersecting portion.

[0281] Due to such a constitution, the potential from the reference voltage signal line CL can be transmitted to the reference electrode CT with the low resistance and hence, the distortion of the reference potential can be further suppressed.

[0282] (Embodiment 20)

[0283] In this embodiment, as shown in **FIG. 16**, a material layer which includes the reference electrode CT as a portion thereof is formed on a protective film PSV1 via a reference voltage signal line CL and a protective film PSV1, and this material layer includes the reference electrode CT which is extended while intersecting at least the reference voltage signal line CL, the material layer has a width at the intersecting portion with the reference voltage signal line CL which is wider than the width at other portions, and the material layer is connected with the reference voltage signal line CL via the through hole TH at the portion where the width is widened.

[0284] Due to such a constitution, the disconnection of the reference electrode CT at the through hole TH portion can be obviated.

[0285] (Embodiment 21)

[0286] As shown in **FIG. 17**, this embodiment has a constitution similar to the constitution shown in **FIG. 15**. In this embodiment, first of all, a material layer which includes a reference electrode CT as a portion thereof is constituted of an opaque conductive member made of a metal layer.

[0287] Further, the material layer which is formed such that the material layer is superposed along a reference voltage signal line CL has a center axis thereof substantially aligned with a center axis of the reference voltage signal line CL and has a width thereof made smaller than a width of the reference voltage signal line CL.

[0288] Due to such a constitution, a light transmitting area in a pixel region can be increased so that the enhancement of the numerical aperture can be achieved.

[0289] (Embodiment 22)

[0290] In this embodiment, as shown in **FIG. 18**, a material layer which includes a reference electrode CT as a portion thereof is formed on a protective film PSV1 via a reference voltage signal line CL and a protective film PSV1, and this material layer includes a strip-like portion which is superposed along at least the reference voltage signal line CL and a reference electrode CT which is extended such that the reference electrode CT intersects this strip-like portion, and the material layer is connected with the reference voltage signal line CL via a through hole TH at the intersecting portion. Further, in the vicinity of the through hole TH, the reference electrode CT is formed such that the width thereof is gradually widened as the reference electrode CT approaches the through hole TH.

[0291] In this case, the reference electrode CT is formed of an opaque metal layer and the width of the above-mentioned strip-like portion which is superposed along the reference voltage signal line CL is made smaller than the width of the reference voltage signal line CL.

[0292] (Embodiment 23)

[0293] As shown in **FIG. 19**, this embodiment is characterized in that, in the constitution of the embodiment 11 (**FIG. 15**), for example, the material layer which includes the reference electrode which is formed while covering the gate signal line GL as a portion thereof is provided with an aperture (a region where the material layer is not formed) at a portion which faces a thin film transistor TFT in an opposed manner.

[0294] When a potential is applied to an upper portion of the thin film transistor TFT, a threshold value of the thin film transistor TFT is fluctuated (back channel). This drawback can be obviated with the provision of the above-mentioned aperture.

[0295] (Embodiment 24)

[0296] As shown in **FIG. 20**, this embodiment is characterized in that, in the constitution of the embodiment 11, for example, an aperture of the material layer which is formed at a portion which faces a thin film transistor TFT in an opposed manner is enlarged such that the aperture is

extended toward the drain signal line DL side along the gate signal line GL and a portion of the drain signal line DL is made to face the aperture in an opposed manner.

[0297] Due to such a constitution, the influence of a jump voltage from the potential of the reference electrode CT to a back channel of the thin film transistor TFT can be obviated.

[0298] (Embodiment 25)

[0299] In this embodiment, as shown in **FIG. 21**, an aperture of a material layer which is formed between a reference electrode CT which is superposed on a drain signal line DL and other neighboring reference electrode CT is expanded to a region where a thin film transistor TFT is formed and hence, the material layer is prevented from being superposed on the thin film transistor.

[0300] With such a provision, the influence of a jump voltage from the reference electrode CT to a back channel of the thin film transistor TFT can be obviated.

[0301] Further, since the fine or minute processing of the material layer is not necessary (compared with the embodiment 11, for example), the yield can be enhanced.

[0302] (Embodiment 26)

[0303] As shown in **FIG. 22**, this embodiment is characterized in that, in the constitution of the embodiment **25** (**FIG. 21**), the aperture of the material layer which is formed between the reference electrode CT which is superposed on the drain signal line DL and other neighboring reference electrode CT is extended over the region where the thin film transistor TFT is formed and reaches other neighboring pixel region with the gate signal line GL disposed therebetween.

[0304] Also in this case, since the fine or minute processing of the material layer is not necessary (compared with the embodiment **24**, for example), the yield can be enhanced.

[0305] With respect to the constitutions of the embodiment **23** to the embodiment **26**, the reference electrodes CT and the reference voltage signal line CL are formed as different layers. However, it is needless to say that the present invention is not limited to these constitutions and is applicable to a case in which the reference electrodes and the reference signal line are formed as the same layer integrally.

[0306] (Embodiment 27)

[0307] **FIG. 23** is, for example, a cross-sectional view of **FIG. 13** taken along a line XXIII-XXIII and shows a cross-section of a through hole TH for performing the connection between the reference voltage signal line CL and the reference electrode CT.

[0308] First of all, the reference voltage signal line CL is formed on a surface of a transparent substrate SUB1 and then, an insulation film GI made of a SiN film is formed on the substrate SUB1 such that the insulation film GI also covers the reference voltage signal line CL. This insulation film GI functions as a gate insulation film of a thin film transistor TFT. Further, protective films PSV1, PSV2 are formed on an upper surface of the insulation film GI and these protective films PSV1, PSV2 constitutes a sequential laminated body consisting of inorganic material made of a SiN film and organic material made of a resin film.

[0309] Then, a through hole TH which reaches the protective films PSV1, PSV2 and the insulation film GI and exposes a portion of the reference voltage signal line CL is formed. A SiO₂ film **40** is formed on the SiN film which constitutes the insulation film GI in the inside of the through hole TH and on the side wall of the SiN film which constitutes the protective film PSV1.

[0310] Due to such a constitution, a slanted surface on the side wall of the through hole TH can be formed of smooth surface so that a broken step due to steps of the reference electrode CT can be obviated.

[0311] For a comparison purpose, there is provided **FIG. 26** which is a cross-sectional view showing the state in which the above-mentioned SiO₂ film is not formed. As shown in the drawing, between the SiN film which constitutes the insulation film GI and the SiN film which constitutes the protective film PSV1 and between the SiN film which constitutes the protective film PSV1 and the resin film which constitutes the protective film PSV2, steps are formed.

[0312] Since the SiN film which constitutes the insulation film GI is made to have a function as the gate insulation film of the thin film transistor TFT, the density thereof becomes dense, while since the SiN film which constitutes the protective film PSV1 assigns priority to the enhancement of the throughput, the density thereof becomes coarser than the density of the insulation film GI.

[0313] In this manner, since respective materials of the laminated body exhibit different etching rates, it gives rise to steps shown in **FIG. 26**.

[0314] As a method for forming the above-mentioned SiO₂ film **40**, a method which performs ashing processing by introducing O₂ gas at the time of etching the SiN film, for example, may be adopted.

[0315] Further, as another method, a method which etches a resin layer by dry etching and performs such etching using gas containing O₂ may be adopted.

[0316] (Embodiment 28)

[0317] This embodiment constitutes another embodiment of the constitution of the above-mentioned through hole TH and **FIG. 24** is a view showing a cross section of the through hole TH.

[0318] Here, a resin film which constitutes a protective film PSV2 is formed such that the protective film PSV2 covers a side wall of a SiN film (protective film PSV1) formed as a layer below the protective film PSV2 and a side wall of a SiN film (insulation film GI) formed as a layer below the protective film PSV1 respectively.

[0319] Due to such a constitution, a step which is formed between the SiN film (insulation film GI) and the SiN film (protective film PSV1) can be covered with the resin film and the resin film is formed on the entire region of the side wall of the through hole TH and hence, the slanted surface can be formed of a smooth surface.

[0320] Accordingly, a broken step due to steps of the reference electrode CT which is connected to the reference voltage signal line CL via this through hole TH can be obviated.

[0321] As a method for forming the through hole TH, a following method is adopted. First of all, a through hole TH is formed in the SiN film constituting the insulation film GI and in the SiN film constituting the protective film PSV1 both of which are formed on the transparent substrate SUB1. A resin film constituting the protective film PSV2 is formed on the substrate such that the resin film also covers the through hole TH. A through hole TH having a diameter smaller than that of the previous through hole TH is formed in the resin film concentrically with the previous through hole TH.

[0322] In this case, it is needless to say that a resin film made of photolytic material or a resin film made of photo-hardening material can be used as such a resin film.

[0323] (Embodiment 29)

[0324] As shown in FIG. 25, in view of the fact that an insulation film which forms a through hole TH has a multi-layered structure, this embodiment interposes other conductive layer 42 for connecting a reference voltage signal line CL and a reference electrode CT.

[0325] That is, in a sequential laminated body which is constituted of an insulation film GI, a protective film PSV1 made of inorganic material and a protective film PSV2 made of organic material, the conductive layer 42 which is connected with a reference voltage signal line CL via a through hole TH which is formed in the insulation film GI is formed. Further, there is provided a reference electrode CT which is connected with the conductive layer 42 via the through hole TH formed in a protective film PSV which is formed of the sequential laminated body constituted of inorganic material and organic material.

[0326] Since the through hole TH has a shape which gradually narrows a diameter thereof toward a bottom portion of the through hole TH, by performing the connection of the reference voltage signal line CL and the reference electrode CT via the conductive layer 42 which has a larger exposure area through the through hole TH than that of the reference voltage signal line CL, the disconnection occurrence rate can be decreased and the contact resistance can be reduced.

[0327] When the reference electrode CT which is made of material exhibiting an unfavorable connection property with the reference voltage signal line CL, this drawback can be obviated by selecting the material of the conductive layer 42.

[0328] For example, a case in which the reference voltage signal line CL is made of Al-based material and the reference electrode CT is made of a light-transmitting conductive film such as ITO or the like is considered. In this case, by using Cr-based material as the conductive layer 42, the connection between the reference voltage signal line CL and the reference electrode CT is improved.

[0329] Further, by forming the conductive layer 42 simultaneous with the formation of the drain signal line DL, for example, the increase of the number of manufacturing man-hours can be obviated.

[0330] Although this embodiment discloses the connection between the reference voltage signal line CL and the reference electrode CT, the present invention is not limited to such a connection and includes a case in which respective conductive layers are connected to each other via a through hole.

[0331] (Embodiment 30)

[0332] FIG. 27(a) and FIG. 27(b) are plan views of respective embodiments of the arrangement state when through holes formed in respective pixel regions are observed in view of the whole display regions.

[0333] In each drawing, respective pixel regions which are in charge of three primary colors R, G, B in color display respectively are formed as neighboring regions. In the explanation made hereinafter, there exists a case that these respective pixels are expressed as a unit pixel in color display.

[0334] In FIG. 27(a), the through holes TH are formed in every one other pixel region, for example. Accordingly, there exist a case in which one through hole is formed in each unit pixel and a case in which two through holes are formed in each unit pixel.

[0335] In such cases, an advantageous effect that the numerical aperture is enhanced by an amount corresponding to the decrease of the number of the through holes which can be decreased.

[0336] With such a constitution, the pixel region is constituted, for example, as shown in FIG. 13. That is, the reference electrodes CT are arranged in a grid array on the display surface and the reference signals can be supplied to the reference electrodes CT via the reference voltage signal line CL.

[0337] In FIG. 27(b), one through hole TH is formed per unit pixel and the through hole is formed in the inside of the pixel region which is in charge of the color of G (green).

[0338] The pixel region which is in charge of the color of G (green) exhibits the higher light transmittivity than the pixel regions which are in charge of other colors. Accordingly, by forming the through hole TH in this region, the lowering of the numerical aperture caused by the formation of the through holes TH can be suppressed as much as possible.

[0339] (Embodiment 31)

[0340] This embodiment is, as shown in FIG. 28, characterized in that, in forming a through hole TH which is served for connecting a reference voltage signal line CL and a reference electrode CT, the shape of the through hole TH is formed such that the shape is expanded in the extension direction of the reference voltage signal line CL.

[0341] That is, the connection of the reference voltage signal line CL and the reference electrode CT above an insulation film (insulation film GI, protective films PSV1, PSV2) via the insulation film is performed via the through hole TH which is formed in the insulation film on a region within a width of the reference voltage signal line CL and is expanded in the extension direction of the reference voltage signal line CL.

[0342] Due to such a constitution, the contact area of the reference electrode CT with the reference voltage signal line CL can be increased so that an advantageous effect that the connection resistance can be largely reduced is obtained.

[0343] (Embodiment 32)

[0344] This embodiment is characterized by the provision of a capacitive element Cstg which is formed between a reference voltage signal line CL and a pixel electrode PX.

[0345] That is, as shown in **FIG. 29**, a reference electrode CT is formed such that the reference electrode CT is extended in the direction which intersects the reference voltage signal line CL via an insulation film and is connected with the reference voltage signal line CL via a through hole TH formed in the insulation film.

[0346] Pixel electrodes PX are positioned at both sides of the reference electrode CT. These pixel electrodes PX have extension portions 45 on the reference voltage signal line CL which are extended in the direction away from the through hole TH.

[0347] Due to the provision of these extension portions 45, capacitive elements Cstg having a capacity of not less than a given value are formed between the pixel electrode PX and the reference voltage signal line CL. Further, since the extension portions 45 are formed such that they are extended away from the through hole TH, an advantageous effect that the occurrence of short-circuiting between the pixel electrode PX and the reference voltage signal line CL can be obviated is obtained.

[0348] (Embodiment 33)

[0349] This embodiment is an improvement of the embodiment 32. As shown in **FIG. 30**, the pixel electrodes PX are positioned at both sides of the reference electrode CT which is connected with the reference voltage signal line CL via the through hole TH. Besides the extension portions 45, these pixel electrodes PX also include extension portions 46 on the reference voltage signal line CL which are extended in the direction toward the through hole TH and the length of the extension portions 46 is set shorter than the length of the extension portions 45 which are extended in the direction away from the through hole TH.

[0350] Due to such a constitution, advantageous effects that the interference between the extension portions 46 and the through hole TH can be obviated and the capacity of the capacitive elements Cstg can be increased are obtained.

[0351] (Embodiment 34)

[0352] This embodiment is characterized in that, as shown in **FIG. 31**, the above-mentioned reference voltage signal line CL is not formed so that the numerical aperture is enhanced.

[0353] As shown in **FIG. 31**, the reference electrodes CT are positioned as layers disposed above a gate signal line GL, a thin film transistor TFT, a drain signal line DL and a pixel electrode PX. Further, the reference electrodes CT are formed as portions of a conductive layer which is formed such that they are superposed on the gate signal line GL and the drain signal line DL. The supply of reference signals to the reference electrodes CT is performed via the conductive layer.

[0354] That is, the conductive layer is integrally formed with other conductive layer corresponding to other neighboring pixel region and hence, the conductive layer is formed such that it is extended to the periphery of a display region. Due to such a constitution, it becomes easy to supply the reference signals from the periphery of the conductive layer.

[0355] In this case, by performing the power supply via the metal layer 35 as shown in **FIG. 14**, for example, the reference signals can be uniformly supplied to the conductive layer.

[0356] In this embodiment, it is needless to say that the reference electrodes are not limited to the conductive layer having a light transmittivity such as an ITO film or the like and may be an opaque conductive layer such as a metal layer.

[0357] (Embodiment 35)

[0358] This embodiment is characterized by a constitution which ensures a capacitive element Cadd between a pixel electrode PX and reference electrodes CT in the state that the abovementioned reference voltage signal line CL is not formed.

[0359] That is, as shown in **FIG. 32**, a connecting portion 48 for pixel electrodes PX disposed at both sides of a reference electrode CT is provided and this connecting portion 48 is arranged to intersect the reference electrode CT, and the capacitive element Cadd is formed at an intersecting portion.

[0360] This reference electrode CT is integrally formed with a material layer which covers a gate signal line GL and each reference electrode CT has both ends thereof superposed on the material layer and capacitive elements Cadd are also formed in these superposed portions.

[0361] (Embodiment 36)

[0362] Further, as shown in **FIG. 33**, a connecting portion 49 may be formed on the material layer which forms the reference electrode CT as a portion thereof such that the connecting portion 49 is superposed on the connecting portion 48 for respective pixel electrodes PX.

[0363] (Embodiment 37)

[0364] This embodiment is characterized by forming a capacitive element Cstg and a capacitive element Cadd in one pixel region.

[0365] As shown in **FIG. 34**, an extension portion of a pixel electrode PX is superposed on a portion of a gate signal line GL via an insulation film GI so as to form the capacitive element Cadd. The extension portion of the pixel electrode PX is also superposed on an extension portion of a reference electrode CT via a protective film PSV so as to form the capacitive element Cstg. **FIG. 35** is a view showing a cross section of **FIG. 34** taken along a line 35-35.

[0366] (Embodiment 38)

[0367] Further, another embodiment which is provided for the comparison with the embodiment shown in **FIG. 35** is shown in **FIG. 36**. As shown in the drawing, when the protective film PSV is formed of a sequential laminated body (PSV1, PSV2) constituted of inorganic material and organic material, a capacity of the capacitive element Cstg can not be sufficiently ensured. Accordingly, the constitution which uses the capacitive element Cadd together with the capacitive element Cstg is advantageous.

[0368] Further, as shown in **FIG. 37** which corresponds to **FIG. 36**, it is needless to say that a protective film PSV3 may be further formed on an upper surface of the reference electrode CT.

[0369] (Embodiment 39)

[0370] Further, in the above-mentioned constitution, the capacitive element Cstg and the capacitive element Cadd are

substantially formed in the inside of the same region, that is, respective elements, Cstg, Cadd are formed in a superposed manner and hence, their occupying area can be made small so that numerical aperture can be enhanced.

[0371] (Embodiment 40)

[0372] Further, in the above-mentioned constitution, by making the area of the capacitive element Cadd smaller than the area of the capacitive element Cstg, while ensuring the necessary capacity, the holding role of the capacitive element Cstg which is electrically more stable than the capacitive element Cadd can be ensured so that the holding potential can be stabilized.

[0373] (Embodiment 41)

[0374] Further, in the above-mentioned constitution, the extension portion of the pixel electrode PX is constituted of a connecting portion with other neighboring pixel electrode PX and a portion which is superposed on a portion of the gate signal line GL (capacitive element Cadd forming portion). Accordingly, when a short-circuiting occurs at the capacitive element Cadd forming portion, for example, it becomes possible to cope with this short-circuiting by separating the portion which is superposed on the gate signal line from other portion with the use of laser beams, for example.

[0375] In this case, a fixed capacity can be ensured by the capacitive element Cstg so that the degrading of the quality of the pixel can be suppressed.

[0376] (Embodiment 42)

[0377] Further, in the case of the embodiment 41, by constituting a material layer which includes the reference electrode CT as a portion thereof via a light transmitting material layer, an advantageous effect that a short-circuiting which occurs at the capacitive element Cadd forming portion can be easily observed with naked eyes is obtained.

[0378] (Embodiment 43)

[0379] The advantageous effects as described in the abovementioned embodiments 37 to 42 are obtained in the same manner with respect to a constitution shown in FIG. 38 in which a reference signal line CL is formed and the reference signal line CL and reference electrodes CT are connected via a through hole TH.

[0380] (Embodiment 44)

[0381] FIG. 39 shows a constitution in which the constitution of the above-mentioned embodiment 37 or the embodiment 43 is applied to a so-called multi-domain method.

[0382] The multi-domain method is a method in which the directions of an electric field which is generated between a pixel electrode PX and a reference electrode CT are formed in two ways so that even when the observation is made from the direction different from the direction perpendicular to a display surface, the change of color tone is not generated.

[0383] As one embodiment which adopts such a multi-domain method, the pixel electrode and the reference electrodes are respectively formed in a zigzag shape by forming a plurality of bent portions along their respective extension directions.

[0384] In this embodiment, an example which constitutes a capacitive element Cadd is illustrated in FIG. 39. However, this embodiment is applicable to a case in which only a capacitive element Cstg is provided.

[0385] (Embodiment 45)

[0386] As shown in FIG. 40, this embodiment is characterized in that, in the constitution of the embodiment 44, a reference voltage signal line CL is formed in parallel with a gate signal line GL and the reference voltage signal line CL is connected with a reference electrode CT via a through hole TH formed in an insulation film.

[0387] (Embodiment 46)

[0388] As shown in FIG. 41, this embodiment is characterized in that, in the constitution of the embodiment 44, a drain signal line DL is formed in a zigzag shape in the running direction thereof corresponding to the shape of the reference electrode CT which is formed as a layer above the drain signal line DL.

[0389] Due to such a constitution, the reference electrode CT can cover the drain signal line DL with a uniform width thereof so that the electric field from the drain signal line DL can be reliably terminated to the reference electrode CT side.

[0390] (Embodiment 47)

[0391] As shown in FIG. 42, this embodiment is characterized in that, in the constitution of the above-mentioned embodiment 46, a reference voltage signal line CL is provided and a connecting portion of the reference electrode CT which is connected with the reference voltage signal line CL via a through hole TH has a width thereof widened.

[0392] (Embodiment 48)

[0393] This embodiment is characterized in that, in respective constitutions of the embodiment 23 to the embodiment 26, to obviate the occurrence of back channel of the thin film transistor TFT, an aperture is formed in a region of a conductive film which includes the reference electrode CT as a portion thereof above the thin film transistor TFT.

[0394] (Embodiment 49)

[0395] This embodiment is characterized in that, in respective constitutions of the embodiment 37 to the embodiment 48, as material of the reference electrode CT, any material selected from a group consisting of Al, Cr, Mo, Ta, W, or material made of an alloy thereof, or material formed by laminating some of these materials can be used.

[0396] Due to such a constitution, it is unnecessary to particularly form a light shielding film above the drain signal line DL and the reference electrode CT exhibits a low resistance so that the waveform distortion in the common inversion driving can be suppressed.

[0397] (Embodiment 50)

[0398] This embodiment is characterized in that, in respective constitutions of the embodiment 37 to the embodiment 48, as material of the reference electrode CT, any material selected from a group consisting of Al, Cr, Mo, Ta, W, or material made of an alloy thereof, or material formed by laminating some of these materials can be used.

[0399] Further, as material of the reference voltage signal line CL, material made of either Al or Cr, or material made of an alloy thereof, or material formed by laminating some of these materials can be used.

[0400] (Embodiment 51)

[0401] This embodiment is characterized in that, as the material of the reference electrode CT, any material selected from a group consisting of ITO, In_2O_3 , SnO_2 , IZO, ZnO_2 , or material made of an alloy thereof, or material formed by laminating some of these materials can be used.

[0402] In this case, when the above-mentioned material is served for covering terminal portions of the gate signal line GL, the drain signal line DL and the reference voltage signal line CL to prevent the electrolytic corrosion, the formation of the reference electrode can be performed simultaneous with such a covering so that the increase of man-hours for manufacturing can be obviated.

[0403] Further, in this case, at the time of repairing the capacitive element, the capacitive element can be directly observed with naked eyes through the reference electrode CT and hence, an advantageous effect that the positioning in laser cutting at the time of repairing is facilitated is obtained.

[0404] (Embodiment 52)

[0405] This embodiment is characterized in that, in the constitution of the embodiment 51, a so-called normally black mode is adopted.

[0406] Due to such a constitution, a reference electrode CT above the drain signal line functions as a light shielding film. Accordingly, compared to a case in which the liquid crystal display device is constituted in a normally white mode, for example, a drawback caused by leaking of light can be solved.

[0407] Here, the normally white mode implies the constitution in which the liquid crystal exhibits the maximum light transmittivity when an electric field is generated between a pixel electrode PX and the reference electrode CT.

[0408] (Embodiment 53)

[0409] This embodiment is characterized in that, in respective constitutions of the embodiments 51, 52, a voltage is applied between the reference electrode CT and pixel electrode PX in a so-called dot inversion driving.

[0410] In the above-mentioned respective constitutions, the reference electrode CT is made of the above-mentioned material (ITO, In_2O_3 , SnO_2 , IZO, ZnO_2 or the like) and hence, the resistance of the reference electrode CT is relatively high. In view of the above, this embodiment enhances the uniformity of the brightness of a display surface by performing the dot inversion.

[0411] (Embodiment 54)

[0412] This embodiment is characterized in that, among the above-mentioned respective constitutions, in the constitutions which forms the conductive layer including the reference electrode CT as a portion thereof above the thin film transistor TFT (constitution which is not provided with the aperture), the reference electrode CT is driven such that the potential thereof falls within a range from not less than (-5) V to not more than $(+10)$ V.

[0413] This is because that it is found that with the driving of the reference electrode CT within the above-mentioned range, the fluctuation of the threshold value of the thin film transistor TFT can be suppressed within an allowable range.

[0414] (Embodiment 55)

[0415] In the above-mentioned respective embodiments, the switching element which is formed in the inside of the pixel is not limited to the thin film transistor TFT and a switching element having other constitution is also applicable as such a switching element.

[0416] However, when the thin film transistor TFT is adopted as the switching element, the scanning signals supplied to the gate signal line is set to not less than $+12$ V to turn on the thin film transistor TFT and is set to not more than 5 V to turn off the thin film transistor TFT.

[0417] Accordingly, by driving the reference electrode CT while setting the potential of the reference electrode CT in a region which does not satisfy the above-mentioned conditions, an erroneous operation of the thin film transistor TFT which may be caused by the reference electrode CT can be prevented.

[0418] (Embodiment 56)

[0419] This embodiment is characterized in that, among the above-mentioned respective constitutions, in the constitutions which form the conductive layer including the reference electrode CT as a portion thereof above the thin film transistor TFT (constitution which is not provided with the aperture), the minimum value of the potential of the reference electrode is set to not less than -5 V in a so-called common inversion driving method.

[0420] Also with such a provision, the fluctuation of the threshold value of the thin film transistor TFT can be suppressed.

[0421] (Embodiment 57)

[0422] This embodiment is characterized in that, among the abovementioned respective constitutions, in the constitutions which form the conductive layer including the reference electrode CT as a portion thereof above the thin film transistor TFT (constitution which is not provided with the aperture), in driving the reference electrode with a substantially fixed potential, the potential is set within a range from not less than -5 V to not more than $+10$ V, and preferably, within a range from not less than -1 V to not more than $+7$ V. Also with such a provision, the fluctuation of the threshold value of the thin film transistor TFT can be suppressed.

[0423] (Embodiment 58)

[0424] This embodiment is characterized by the constitution in the vicinity of the connection between a gate signal line GL and a gate drive IC 5, for example.

[0425] As shown in FIG. 43, the constitution in the vicinity of the connection between the gate signal lines GL and the gate drive ICs 5 is, as mentioned previously, formed as a pattern which converges at the gate drive IC 5 side along with other neighboring gate signal line GL.

[0426] Here, this portion corresponds to a portion surrounded by a dashed line A shown in FIG. 58.

[0427] In this case, the reference voltage signal lines CL are arranged as the same layer as the gate signal lines GL between respective gate signal lines GL and when the reference voltage signal line CL is also pulled out to the gate drive IC 5 side, the reference voltage signal lines CL interfere with the gate signal lines GL at the region where respective gate signal lines GL are converged and hence, a short-circuiting is liable to occur.

[0428] Accordingly, in this embodiment, the reference voltage signal line CL is formed in other layer with respect to the gate signal lines GL via an insulation film and the reference voltage signal line CL and the reference electrodes CT are connected via a wiring layer 50 which is extended in the direction substantially perpendicular at a right angle to the gate signal line GL and a through hole formed in the insulation film in the region where respective gate signal lines GL are converged.

[0429] Due to such a constitution, the increase of a region which is referred to as a picture frame can be obviated.

[0430] That is, in the previous example, when the reference voltage signal lines CL are to be formed without generating short-circuiting in the region where respective gate signal lines GL are converged, a bending angle of respective gate signal lines at the converging portion must be set to a small value and hence, the gate drive ICs 5 must be mounted at a position remote from a display region AR.

[0431] When the pixels of this embodiment adopt the constitution shown in FIG. 13, for example, the wiring layer 50 may be a wiring layer which can be simultaneously formed with the drain signal lines DL.

[0432] Further, although this embodiment is directed to the constitution in the vicinity of the connection of the gate signal lines GL and the gate drive ICs 5, it is needless to say that this embodiment is applicable to the constitution in the vicinity of the connection between the drain signal lines DL and the drain drive ICs 6.

[0433] (Embodiment 59)

[0434] As shown in FIG. 44 which corresponds to FIG. 43(b), this embodiment is characterized in that the above-mentioned wiring layer 50 is integrally formed with the reference voltage signal lines CL.

[0435] (Embodiment 60)

[0436] This embodiment is characterized by the constitution in the pixel region in the constitution shown in FIG. 58. That is, gate signal lines GL and reference voltage signal lines CL are formed as the same layer and the reference voltage signal lines CL are connected with the reference electrodes CT which are formed on an upper surface of an insulation film by way of the insulation film via a through hole TH formed in the insulation film.

[0437] (Embodiment 61)

[0438] This embodiment is also characterized by the constitution of the pixel region in the constitution described in the embodiment 59.

[0439] (Embodiment 62)

[0440] FIG. 47 is a view which corresponds to FIG. 43. What differs from the constitution of FIG. 43 lies in that the reference voltage signal lines CL which are pulled out to the

wiring layer 50 are arranged every one other. In this case, it is needless to say that the arrangement of the reference voltage signal lines CL is not limited to the every one other arrangement and the every two other arrangement, the every three other arrangement or the like may be adopted.

[0441] Here, the reference electrodes CT are formed as portions of the material layer as mentioned above and this material layer is formed such that the material layer is connected with a material layer of other neighboring pixel region.

[0442] Due to such a constitution, in the region where respective gate signal lines GL are converged, the concentration of the signal lines can be obviated.

[0443] Although the reference voltage signal lines have been explained in this embodiment, it is needless to say that the embodiment is applicable to the holding capacitive lines.

[0444] (Embodiment 63)

[0445] This embodiment is, as shown in FIG. 48, characterized in that the above-mentioned wiring layer 50 is turned around the outside of a bundle of respective gate signal lines GL which are connected with one driver chip (drain drive IC 6, gate drive IC 5) and then is pulled out in the vicinity of the driver chip.

[0446] Due to such a constitution, it becomes possible to pull out the wiring layer 50 to the terminal side of the input side of the driver chip.

[0447] Here, a portion shown in FIG. 48 corresponds to a portion indicated by a frame B depicted by a dashed line in FIG. 58.

[0448] (Embodiment 64)

[0449] This embodiment is directed to other embodiment related with the embodiment shown in FIG. 48. As shown in FIG. 49, a wiring layer 50 which is pulled out in the vicinity of the driver chip is positioned below the driver chip.

[0450] (Embodiment 65)

[0451] This embodiment is characterized in that, in the constitutions of the above-mentioned respective embodiments, materials having following structural formulae are used as materials of orientation films ORI1, ORI2.

(1)
(2)

[0452] With the use of these orientation films ORI1, ORI2, the occurrence of image sticking (ionic image sticking) derived from the movement of ionic impurities in a liquid crystal layer can be suppressed.

[0453] Further, when the material of the formula (1) amounts to 30% to 70% for the sum of the material expressed by the formula (1) and the material expressed by the formula (2) in the orientation film, the occurrence of the ionic image sticking can be further suppressed.

[0454] Here, the ionic image sticking means, as shown in FIG. 50(a), a portion of brightness which protrudes from brightness corresponding to a middle level pattern at measure when white and black displays are performed in neighboring regions with a pattern at display for 1 hour and thereafter the display is performed with the middle level

pattern at measure and the change of brightness is detected over the white-display region and the black-display region.

[0455] In this case, with the use of the above-mentioned materials as the orientation films ORI1, ORI2, it becomes possible to suppress the intensity of the ionic image sticking shown in **FIG. 50(a)** to not more than 3 (preferably, not more than 2) so that the generation of the ionic image sticking can be prevented.

[0456] **FIG. 50(b)** shows that the black display with a pattern at display is used as a common portion and the white display is disposed at the right side of the black display.

[0457] The reason why the brightness distribution with the middle level pattern at measure of **FIG. 50(b)** differs from that of **FIG. 50(a)** is that a phenomenon in which ions move to the left side in the drawing is observed.

[0458] (Embodiment 66)

[0459] This embodiment is characterized in that, in the constitution shown in **FIG. 31**, for example, as shown in **FIG. 51(a)** which corresponds to **FIG. 31(b)**, reference electrodes CT are formed on a protective film PSV (an upper layer thereof being formed of a protective film PSV2 made of organic material) and an orientation film ORIL is formed on the protective film PSV such that the orientation film ORIL also covers the reference electrodes CT.

[0460] Further, recessed portions are formed at portions of an upper surface of the protective film PSV where the reference electrodes CT are formed.

[0461] Due to such a constitution, the step of the reference electrodes CT can be minimized so that the lowering of rubbing, the worsening of image sticking or the leaking of light caused by the insufficient orientation in the vicinity of the reference electrodes CT can be solved.

[0462] In this case, as shown in **FIG. 51(b)**, on the condition that the thickness of the electrodes is set to H (=300 nm) and the protruding height of the electrodes is set to Hi (=0, 90, 150, 300 nm), the state of the leaking of light was investigated with respect to respective electrodes. The result shown in **FIG. 52** was obtained. In the drawing, ○○ indicates the state which the leaking of light was obviated most favorably, ○ indicates the state in which the leaking of light was obviated favorably, and x indicates the state in which the leaking of light was not obviated favorably.

[0463] It is understood from the above result that the constitution which embeds the reference electrodes CT in the protective film PSV2 is preferable and the thickness H of the reference electrodes CT and the protruding height Hi of electrodes CT from the recessed portions should preferably have the relationship expressed by a following formula.

$$0 \leq (H - H_1)/H \leq 0.5 \quad (3)$$

[0464] This embodiment explains the case in which the orientation film ORI1 is directly formed on the surfaces of the reference electrodes CT. However, the embodiment is applicable to a case in which other insulation film is formed and the orientation film ORI1 is directly formed on the surface of the insulation film.

[0465] In this case, the height which appears on the surface of the other insulation film may be converted into the height Hi of the step of the reference electrodes CT.

[0466] Here, in this case, the electrodes are not limited to the reference electrodes CT and the above-mentioned height relationship is applicable to other electrodes and the reference electrodes CT are not limited to the light transmitting material layer or the opaque material layer.

[0467] (Embodiment 67)

[0468] This embodiment is characterized in that, in the above-mentioned respective embodiments, when the protective film PSV is formed of the sequential laminated body constituted of the protective film PSV1 made of inorganic material and the protective film PSV2 made of organic material, as material of the protective film PSV2, an acrylic-based film (highly transparent and positive-type photosensitive), a polyimide-based film (high heat resistance), a novolak-based film (easily colored), polyimide-epoxy copolymer (working also as an orientation film) or a laminated body thereof can be used.

[0469] Such a protective film PSV2 has a film thickness of 400 nm, a light transmittivity of 95% and the heat resistance of not less than 230° C.

[0470] Further, the protective film PSV2 exhibits the low contamination property to the liquid crystal and has the process resistance characteristics (capable of withstanding sputtering, an etchant, peeling-off liquid, an orientation film solvent, UV/O₃ cleaning).

[0471] (Embodiment 68)

[0472] It is confirmed that when the electric field is generated by applying the voltage between the pixel electrode PX and the reference electrode CT and the protective film PSV2 made of organic material is disposed between these electrodes, the driving voltage due to the protective film PSV2 has to be increased.

[0473] In this case, when the drivers, that is, the gate drive ICs 5 which supply scanning signals to the gate signal line GL or the drain drive ICs 6 which supply video signals to the drain signal line DL are directly mounted on the transparent substrate SUB1 (FCA method), it is necessary to take measures to cope with the generation of heat of the drive ICs.

[0474] Accordingly, inventors of the present invention have studied the relationship between the liquid crystal driving voltage Vmax which produces the maximum brightness in the normally black mode and the film thickness of the protective film PSV2 made of organic material, the distance between the pixel electrode Px and the reference electrode CT and the dielectric anisotropy of the liquid crystal.

[0475] First of all, following graphs shown in **FIG. 53** to **FIG. 55** are obtained. That is, the graph shown in **FIG. 53** indicates the relationship among the dielectric anisotropy of the liquid crystal, the distance between the pixel electrode PX and the reference electrode CT and the liquid crystal driving voltage Vmax. The graph shown in **FIG. 54** which indicates the relationship among the film thickness of the protective film PSV2 when the dielectric anisotropy of the liquid crystal is set to 10, the distance between the pixel electrode PX and the reference electrode CT and the liquid crystal driving voltage Vmax. The graph shown in **FIG. 55** which indicates the relationship among the film thickness of the protective film PSV2 when the dielectric anisotropy of the liquid crystal is set to 14.5, the distance between the

pixel electrode PX and the reference electrode CT and the liquid crystal driving voltage Vmax.

[0476] In view of the above, as shown in **FIG. 53**, the liquid crystal driving voltage Vmax can be reduced with the use of the liquid crystal material having the high dielectric anisotropy of the liquid crystal. Then, corresponding to the increase of the film thickness of the protective film PSV2, the liquid crystal driving voltage Vmax is increased, while corresponding to the increase of the distance between the pixel electrode PX and the reference electrode CT, the liquid crystal driving voltage Vmax is increased. These relationships are indicated in **FIG. 54** and **FIG. 55**.

[0477] Accordingly, the relationship expressed by a following formula (4) is led from the above-mentioned graph.

$$V_{max}=1.9d+0.4146W-0.2328\Delta\epsilon+2.8218 \quad (4)$$

[0478] Here, d is a film thickness (μm) of a protective film PSV2 made of organic material, W is a distance (μm) between a pixel electrode Px and a reference electrode CT and $\Delta\epsilon$ is a dielectric anisotropy of a liquid crystal.

[0479] From the above, it is preferable to use a cyano difluorine liquid crystal which is expressed by a structural formula shown in **FIG. 55** as the material of the liquid crystal having high dielectric anisotropy of a liquid crystal $\Delta\epsilon$. Further, it is preferable to use a trifluoro dioxane liquid crystal which is expressed by a structural formula shown in **FIG. 57** as the liquid crystal to realize the high dielectric anisotropy of a liquid crystal $\Delta\epsilon$ of not less than 14.5.

[0480] In any case, with the use of the liquid crystal which contains at least one of these liquid crystals, the liquid crystal driving voltage Vmax can be reduced.

[0481] (Embodiment 69)

[0482] In the constitution adopting the normally black mode, when the pixel electrode PX and the reference electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, the liquid crystal display can be realized by setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 7.5 V at one side of amplitude.

[0483] (Embodiment 70)

[0484] Further, in the constitution adopting the normally black mode, when the pixel electrode PX and the reference electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, the liquid crystal display can be realized by setting the film thickness d (μm) of a protective film PSV2, the distance W (μm) between the pixel electrode Px and the reference electrode CT and the dielectric anisotropy of the liquid crystal $\Delta\epsilon$ such that the liquid crystal driving voltage Vmax in the above-mentioned formula (4) becomes less than 15 V, performing a so-called common inversion, and setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 7.5 V at one side of amplitude.

[0485] This is because that, with the use of the common inversion driving, the output voltage of the drivers necessary for obtaining the same liquid crystal driving voltage can be reduced approximately by half.

[0486] (Embodiment 71)

[0487] Further, in the constitution adopting the normally black mode, when the pixel electrode PX and the reference electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, the liquid crystal display can be realized by setting the film thickness d (μm) of a protective film PSV2, the distance W (μm) between the pixel electrode PX and the reference electrode CT and the dielectric anisotropy of the liquid crystal $\Delta\epsilon$ such that the liquid crystal driving voltage Vmax in the above-mentioned formula (4) becomes less than 7.5 V and setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 7.5 V at one side of amplitude.

[0488] (Embodiment 72)

[0489] Further, in the constitution adopting the normally black mode, when the pixel electrode PX and the reference electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, the liquid crystal display can be realized by setting the maximum amplitude of voltage of video signals to not more than a voltage which is necessary for setting the relative transmittivity of the liquid crystal layer to 90% and by setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 7.5 V at one side of amplitude in the state that the liquid crystal driving voltage Vmax in the above-mentioned formula (4) is less than 9.375 V.

[0490] This is because that, in the normally black mode, since a curve B-V in the vicinity of the liquid crystal driving voltage Vmax becomes gentle, compared to the voltage necessary for obtaining the transmittivity of 100, as the voltage necessary for obtaining the transmittivity of 90%, it is sufficient to ensure 80% of the voltage necessary for obtaining the transmittivity of 100.

[0491] (Embodiment 73)

[0492] Further, in the constitution adopting the normally black mode, when the pixel electrode PX and the reference electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, the liquid crystal display can be realized by performing a so-called common inversion, setting the maximum amplitude of voltage of video signals to not more than a voltage which is necessary for setting the relative transmittivity of the liquid crystal layer to 90% and by setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 7.5 V at one side of amplitude in the state that the liquid crystal driving voltage Vmax in the above-mentioned formula (4) is less than 18.75 V.

[0493] (Embodiment 74)

[0494] Further, in the constitution adopting the normally black mode, when the pixel electrode PX and the reference electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, it becomes possible to cope with the generation of heat of the drain drivers by setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 5 V at one side of amplitude.

[0495] (Embodiment 75)

[0496] Further, in the constitution adopting the normally black mode, when the pixel electrode PX and the reference

electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, it becomes possible to cope with the generation of heat of the drivers by performing a so-called common inversion, and by setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 5 V at one side of amplitude, and by setting the film thickness d (μm) of a protective film PSV2, the distance W (μm) between the pixel electrode PX and the reference electrode CT and the dielectric anisotropy of the liquid crystal $\Delta\epsilon$ such that the liquid crystal driving voltage V_{max} in the above-mentioned formula (4) becomes less than 10 V.

[0497] (Embodiment 76)

[0498] Further, in the constitution adopting the normally black mode, when the pixel electrode PX and the reference electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, it becomes possible to cope with the generation of heat of the drivers by performing a so-called common inversion, and by setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 5 V at one side of amplitude, and by setting the film thickness d (μm) of a protective film PSV2, the distance W (μm) between the pixel electrode PX and the reference electrode CT and the dielectric anisotropy of the liquid crystal $\Delta\epsilon$ such that the liquid crystal driving voltage V_{max} in the above-mentioned formula (4) becomes less than 10 V.

[0499] (Embodiment 77)

[0500] Further, in the constitution adopting the normally black mode, when the pixel electrode PX and the reference electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, it becomes possible to cope with the generation of heat of the drivers by setting the maximum amplitude of voltage of video signals to not more than a voltage which is necessary for setting the relative transmittivity of the liquid crystal layer to 90% and by setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 5 V at one side of amplitude in the state that the liquid crystal driving voltage V_{max} in the above-mentioned formula (4) is less than 6.25 V.

[0501] (Embodiment 78)

[0502] Further, in the constitution adopting the normally black mode, when the pixel electrode PX and the reference electrodes CT constitute different layers from each other via the protective film PSV2 made of organic material, it becomes possible to cope with the generation of heat of the drivers by setting the maximum amplitude of voltage of video signals to not more than a voltage which is necessary for setting the relative transmittivity of the liquid crystal layer to 90% and by setting the amplitude of the output voltage of the drain drivers at the time of white display to not more than 5 V at one side of amplitude in the state that the liquid crystal driving voltage V_{max} in the above-mentioned formula (4) is less than 12.5 V.

[0503] As can be clearly understood from the above-mentioned description, according to the present invention, the liquid crystal display device which can suppress the local temperature elevation in the vicinity of the drivers is obtained.

[0504] The liquid crystal display device which can suppress the transmission of the stress of the drivers to the substrate is obtained.

[0505] The liquid crystal display device which can suppress the alignment displacement on a display surface in the vicinity of drivers is obtained.

[0506] The liquid crystal display device which can enhance the numerical aperture is obtained.

[0507] The liquid crystal display device which can narrow the so-called picture frame is obtained.

What is claimed is:

1. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are mounted in each pixel region,

said video signals from said drain signal line are generated by a driver chip mounted on said one substrate,

a light transmittivity of the liquid crystal layer is set to take a minimum value when a voltage is not applied between said pixel electrode and said reference electrode, and

a maximum amplitude of voltage of said video signals is set to a value not more than a voltage necessary for setting a relative transmittivity of said liquid crystal layer to 90%.

2. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode to which reference signals which become the reference to said video said video signals are supplied are mounted in each pixel region, and

reference signals which are supplied to said reference electrodes in said each pixel region are inverted by a unit of a frame.

3. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode to which reference signals which become the reference to said video said video signals are supplied are mounted in each pixel region,

said video signals from said drain signal line are generated by a driver chip mounted on said one substrate, and

out of said drain signal line and said reference signal line, one of said signal lines to which signals having a larger average voltage amplitude per 1 frame are supplied is set to have a lower resistance than the other of said signal lines.

4. A liquid crystal display device according to claim 3, wherein a voltage of said reference signals is set constant in each frame and a specific resistance of said drain signal line is set smaller than a specific resistance of said reference signal line.

5. A liquid crystal display device according to claim 3, wherein a voltage of said reference signals is inverted by a unit of a frame and a specific resistance of said reference signal line is set smaller than a specific resistance of said drain signal line.

6. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are mounted in each pixel region,

said video signals from said drain signal line are generated by a driver chip mounted on said one substrate, and

a stress buffer layer is interposed between said driver chip and said one substrate.

7. A liquid crystal display device, wherein a protective film which is made of an organic film and covers said switching element is formed on each pixel region and said stress buffer layer is made of material identical to material of said protective film.

8. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said

reference electrode and said pixel electrode are mounted in each pixel region,

said signals from respective signal lines are generated by a driver chip mounted on said one substrate, and

said one substrate is made of resin material.

9. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are mounted in each pixel region,

said signals from said respective signal lines are generated by a driver chip mounted on said one substrate,

support columns which ensure a gap formed between said one substrate and the other substrate which faces said one substrate in an oppose manner is mounted on a liquid-crystal-side surface of either one of said respective substrates, and

said support columns are arranged with the density of one or less per two neighboring pixel regions.

10. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are mounted in each pixel region,

said signals from said respective signal lines are generated by a driver chip mounted on said one substrate,

support columns which ensure a gap formed between said one substrate and the other substrate which faces said one substrate in an oppose manner is mounted on a liquid-crystal-side surface of either one of said respective substrates, and

said support columns are formed such that said one support column is allocated to neighboring two to eight pixel regions.

11. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are mounted in each pixel region,

said signals from said respective signal lines are generated by a driver chip mounted on said one substrate, support columns which ensure a gap formed between said one substrate and the other substrate which faces said one substrate in an oppose manner and a light shielding film which defines said pixel region are mounted on a liquid-crystal-side surface of either one of said respective substrates, and

said light shielding film has a width thereof set wider at a portion thereof which is close to said drive chip than other portions thereof.

12. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a plurality of reference electrodes which generate an electric field between said reference electrode and said pixel electrode are mounted in each pixel region, and

one of said respective reference electrodes is formed in a superposed manner on said drain signal line via an insulation film and has a width thereof set larger than a width of said drain signal line.

13. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a plurality of reference electrodes which generate an electric field between said reference electrodes and said pixel electrode are mounted in each pixel region, and

one of said respective reference electrodes is formed in a superposed manner on said drain signal line via an insulation film having a dielectric constant lower than a dielectric constant of inorganic material and has a width thereof set larger than a width of said drain signal line.

14. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a plurality of reference electrodes which generate an electric field between said reference electrode and said pixel electrode are mounted in each pixel region, and

at least one of said respective reference electrodes is formed in a superposed manner on said drain signal line via an insulation film made of a sequential laminated body consisting of an inorganic material layer and an organic material layer and has a width thereof set larger than a width of said drain signal line.

15. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a plurality of reference electrodes which generate an electric field between said reference electrode and said pixel electrode are mounted in each pixel region, and

said respective reference electrodes are made of metal layers and at least one of said respective reference electrodes is formed in a superposed manner on said drain signal line via an insulation film made of a sequential laminated body consisting of an inorganic material layer and an organic material layer and has a width thereof set larger than a width of said drain signal line.

16. A liquid crystal display device according to claim 15, wherein said insulation film is formed on an upper surface of said reference electrode such that said insulation film also covers said reference electrode and an orientation film is formed on an upper surface of said insulation film.

17. A liquid crystal display device according to claim 15, wherein said reference electrode which is superposed on said drain signal line is connected with said reference electrode corresponding to other pixel region which is arranged along said drain signal line on said drain signal line, and,

out of said substrates which are arranged to face each other in an opposed manner while sandwiching said liquid crystal layer therebetween, said liquid-crystal-side surface of said one substrate is not provided with a light shielding film on a portion thereof which faces said drain signal line in an opposed manner.

18. A liquid crystal display device according to claim 15 or 17, wherein out of said substrates which are arranged to face each other in an opposed manner while sandwiching said liquid crystal layer therebetween, said liquid-crystal-side surface of said one substrate is provided with a light shielding film on a portion thereof which faces said switching element in an opposed manner.

19. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a plurality of reference electrodes which generate an electric field between said reference electrode and said pixel electrode are mounted in each pixel region,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode, and

said respective reference electrodes are made of transparent conductive layers and at least one of said respective reference electrodes is formed in a superposed manner on said drain signal line via an insulation film made of a sequential laminated body consisting of an inorganic material layer and an organic material layer and has a width thereof set larger than a width of said drain signal line.

20. A liquid crystal display device according to claim 19, wherein said reference electrode which is superposed on said drain signal line is connected with said reference electrode corresponding to other pixel region which is arranged along said drain signal line on said drain signal line, and,

out of said substrates which are arranged to face each other in an opposed manner while sandwiching said liquid crystal layer therebetween, said liquid-crystal-side surface of said one substrate is not provided with a light shielding film on a portion thereof which faces said drain signal line in an opposed manner.

21. A liquid crystal display device according to claim 19 or 20, wherein out of said substrates which are arranged to face each other in an opposed manner while sandwiching said liquid crystal layer therebetween, said liquid-crystal-side surface of said one substrate is provided with a light shielding film on a portion thereof which faces said switching element in an opposed manner.

22. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region,

said reference signal line is formed on a lower layer of an insulation film made of a sequential laminated body

consisting of an inorganic material layer and an organic material layer, said reference electrode is formed on an upper layer of said insulation film and said reference signal line and said reference electrode are connected to each other via a through hole formed in said insulation film, and

said reference electrode is made of a light-transmitting transparent conductive layer and said reference signal line is made of a conductive layer having a resistance lower than a resistance of said reference electrode.

23. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region, and

said gate signal line, said drain signal line and said reference electrode are respectively formed as layers which are different from each other via insulation films.

24. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a holding capacity signal line which forms a capacity between said holding capacity signal line and

said pixel electrode are mounted in each pixel region, and said gate signal line, said drain signal line and said holding capacity signal line are respectively formed as layers which are different from each other via insulation films.

25. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region,

said video signals from said drain signal line are generated by a driver chip mounted on one of said substrates, and

said gate signal line, said drain signal line and said reference electrode are respectively formed as layers which are different from each other via insulation films.

26. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a holding capacity signal line which forms a capacity between said holding capacity signal line and said pixel electrode are mounted in each pixel region,

said video signals from said drain signal line are generated by a driver chip mounted on one of said substrates, and

said gate signal line, said drain signal line and said holding capacity signal line are respectively formed as layers which are different from each other via insulation films.

27. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region,

said reference electrode is formed on an upper layer of said reference signal line by an insulation film and has a first strip-like portion which is superposed at least along said reference signal line and a second strip-like portion which is extended such that said second strip-like portion intersects said first strip-like portion, and said reference electrode is connected with said reference signal line via a through hole formed in said insulation film at an intersecting portion between said first and second strip-like portions.

28. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are

supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region,

said reference electrode is formed on an upper layer of said reference signal line by an insulation film and has a strip-like portion which is extended such that said strip-like portion intersects at least said reference signal line, said reference electrode has a width thereof set wider at portion thereof which intersects said reference signal line than other portions thereof, and said reference electrode is connected with said reference signal line via a through hole formed in said insulation film at said portion where said width of said reference electrode is set wider.

29. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region,

said reference electrode is made of opaque conductive material formed on an upper layer of said reference signal line by an insulation film and has a first strip-like portion which is superposed at least along said reference signal line and has a width thereof set narrower than a width of said reference signal line and a second strip-like portion which is extended such that said second strip-like portion intersects said first strip-like portion, and said reference electrode is connected with said reference signal line via a through hole formed in said insulation film at an intersecting portion between said first and second strip-like portions.

30. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region,

said reference electrode is formed as a layer disposed above said gate signal line and said drain signal line via an insulation film,

a conductive layer which is integrally formed with a conductive layer which is superposed on at least said

gate signal line and is superposed along said drain signal line is formed as a portion of said reference electrode, and

said conductive layer which is superposed on said gate signal line forms an aperture at least in a portion thereof which faces said switching element in an opposed manner.

31. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region,

said reference electrode is formed as a layer disposed above said gate signal line and said drain signal line via an insulation film,

a conductive layer which is integrally formed with a conductive layer which is superposed along at least said gate signal line and is superposed along said drain signal line is formed as a portion of said reference electrode, and

said conductive layer which is superposed on said gate signal line forms an aperture in a portion thereof which faces said switching element in an opposed manner, and said aperture is formed such that said aperture is extended toward said drain signal line side along said gate signal line, and a portion of said drain signal line is formed such that said portion faces said aperture in an opposed manner.

32. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are mounted in each pixel region,

said reference electrode is formed as a layer disposed above said gate signal line and said drain signal line via an insulation film, and

a conductive layer which is integrally formed with a conductive layer which is superposed along at least said gate signal line and is superposed along said drain signal line is formed as a portion of said reference electrode, and an aperture of said conductive layer

formed between said reference electrode and other reference electrode arranged close to said reference electrode is formed such that said aperture extends over a region where said switching element is formed.

33. A liquid crystal display device according to claim 32, wherein said aperture of said conductive layer is formed such that said aperture extends over said region where said switching element is formed and reaches said neighboring other pixel region with said gate signal line arranged theretwixen.

34. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a wiring layer, a first insulation film which is made of SiN and also covers said wiring layer, a second insulation film which is made of SiN having a density lower than a density of said first insulation film and is formed on said first insulation film and a third insulation film which is made of organic material and is formed on said second insulation film are mounted, and a through hole which penetrates said insulation films from said third insulation film to said said first insulation film and exposes a portion of said wiring layer is formed, and

a SiO₂ film is formed on side walls of said first insulation film and said second insulation film in said through hole.

35. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, a wiring layer, a first insulation film which is made of inorganic material and also covers said wiring layer, a second insulation film which is made of inorganic material having a density lower than a density of said first insulation film and is formed on said first insulation film and a third insulation film which is made of organic material and is formed on said second insulation film are mounted, and a through hole which penetrates said insulation films from said third insulation film to said first insulation film and exposes a portion of said wiring layer is formed, and

said third insulation film is formed on side walls of said first insulation film and said second insulation film in said through hole.

36. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween, a wiring layer, a laminated body which is made of a plurality of insulation films and also covers said wiring layer are mounted, and a through hole which exposes a portion of said wiring layer is formed in said laminated body,

a first conductive layer which is connected to said wiring layer via said through hole is formed on a surface of at

least one of a plurality of said insulation films except for said insulation film which constitutes an uppermost layer, and

a second conductive layer which is connected to said first conductive layer via said through hole is formed on a surface of said laminated body.

37. A liquid crystal display device according to claim 36, wherein said first conductive layer is made of material which exhibits a favorable connection with said wiring layer and said second conductive layer.

38. A liquid crystal display device being characterized in that

to each one of pixel regions which are arranged in a matrix array on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are provided,

said reference electrode of each pixel region is constituted such that said reference signals are supplied via a conductive layer which is formed as the same layer as said reference electrode and from said reference signal line which is formed as the layer different from said reference electrode via a through hole, and

said through hole is formed in said pixel region which corresponds to G (green color).

39. A liquid crystal display device being characterized in that

to each one of pixel regions on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are provided,

said reference electrode is connected to said reference signal line which is formed in a layer different from said reference electrode via an insulation layer via a through hole formed in said insulation layer, and

said through hole is formed in a shape which is flared in the extending direction of said reference signal line.

40. A liquid crystal display device being characterized in that

to each one of pixel regions on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel elec-

trode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is arranged in a spaced-apart manner from said pixel electrode and to which reference signals from a reference signal line are supplied are provided,

as said reference electrode, an electrode which is formed in the direction which intersects said reference signal line via an insulation film and is connected to said reference signal line via a through hole is provided, and

as said pixel electrodes, pixel electrodes which are positioned at both sides of said reference electrode which is connected to said reference signal line by said through hole are provided, and said pixel electrodes have extension portions which are extended in the direction away from said through hole on said reference signal line.

41. A liquid crystal display device according to claim 40, wherein said pixel electrodes which are positioned at both sides of said reference electrode connected to said reference signal line via said through hole have extension portions which are extended in the direction approaching said through hole on said reference signal line, and said extension portion is formed that a length thereof is shorter than said extension portion which is extended in the direction away from said through hole.

42. A liquid crystal display device being characterized in that

to each one of pixel regions on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said reference electrode is positioned as a layer disposed above said gate signal line, said switching element, said drain signal line and said pixel electrode and is constituted of a portion of a conductive layer which is formed on said gate signal line and said drain signal line in a superposed manner, and

the supply of reference signals to said reference electrode is performed via said conductive layer.

43. A liquid crystal display device being characterized in that

to each one of pixel regions on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said reference electrode is positioned as a layer disposed above said gate signal line, said switching element, said

drain signal line and said pixel electrode and is constituted of a portion of a conductive layer which is formed on said gate signal line and said drain signal line in a superposed manner, and

said reference electrode is superposed on said pixel electrode at a portion of said conductive layer which intersects said reference electrode.

44. A liquid crystal display device according to claim 43, wherein said conductive layer includes a strip-like portion which intersects one said reference electrode and said respective pixel electrodes which are positioned at both sides of said one reference electrode include connecting portions which are connected at portions thereof which are superposed on said strip-like portions.

45. A liquid crystal display device according to claim 43, wherein said conductive layer which is formed on said gate signal line in an superposed manner has a width thereof wider than a width of said gate signal line, at least two pixel electrodes are formed and said respective pixel electrodes are connected via connecting portions thereof which are arranged such that said connecting portions intersect the reference electrode which is positioned between said respective pixel electrodes, and said respective pixel electrodes have both ends thereof superposed on portions of said conductive layer which is formed by superposition on said gate signal line.

46. A liquid crystal display device being characterized in that

to each one of pixel regions on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said gate signal line, said pixel electrode and said reference electrode are formed as respectively different layers from said one substrate side, an extension portion of said pixel electrode is superposed on a portion of said gate signal line via a first insulation film and is simultaneously superposed on said extension portion of said reference electrode via a second insulation film, and said extension portion of said reference electrode forms a portion which covers said gate signal line.

47. A liquid crystal display device according to claim 46, wherein said second insulation film is constituted of a sequential laminated body made of inorganic material and organic material.

48. A liquid crystal display device according to claim 46, wherein a superposed area of said extension portion of said pixel electrode with said gate signal line is set smaller than a superposed area of said extension portion of said pixel electrode with said extension portion of said reference electrode.

49. A liquid crystal display device according to claim 46, wherein a capacity of said extension portion of said pixel electrode with said gate signal line is set smaller than a

capacity of said extension portion of said pixel electrode with said extension portion of said reference electrode.

50. A liquid crystal display device according to claim 46, wherein said extension portion of said pixel electrode is constituted of a portion thereof which is connected to other pixel electrode and a portion thereof which is superposed on a portion of said gate signal line.

51. A liquid crystal display device according to claim 46, wherein said reference signal line is formed as the same layer as said gate signal line and said reference signal line is connected to said reference electrode via a through hole formed in said first insulation film and said second insulation film.

52. A liquid crystal display device being characterized in that

to each one of pixel regions formed on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said pixel electrode and said reference electrode respectively have bent portions relative to the extension directions thereof for making the directions of electric fields formed between said pixel electrodes and between said reference electrodes different from each other, and

said gate signal line, said pixel electrode and said reference electrode are formed as respectively different layers from said one substrate side.

53. A liquid crystal display device being characterized in that

to each one of pixel regions formed on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said pixel electrode and said reference electrode respectively have bent portions relative to the extension directions thereof for making the directions of electric fields formed between said pixel electrodes and between said reference electrodes different from each other,

said gate signal line, said pixel electrode and said reference electrode are formed as respectively different layers from said one substrate side,

an extension portion of said pixel electrode is superposed on a portion of said gate signal line via a first insulation film, and

said extension portion of said pixel electrode is superposed on an extension portion of said reference electrode via a second insulation film, and said extension portion of said reference electrode constitutes a portion which covers said gate signal line.

54. A liquid crystal display device according to claim 52 or **53** wherein said reference signal line is formed as the same layer as said gate signal line and said reference signal line is connected to said reference electrode via a through hole formed in said first insulation film and said second insulation film.

55. A liquid crystal display device according to claim 52 or **53** wherein said reference electrode is formed on said drain signal line in a superposed manner, and said drain signal line is provided with a bent portion corresponding to said bent portion provided to said reference electrode.

56. A liquid crystal display device according to claim 55 wherein said reference signal line is formed as the same layer as said gate signal line and said reference signal line is connected to said reference electrode via a through hole formed in said first insulation film and said second insulation film.

57. A liquid crystal display device being characterized in that

to each one of pixel regions formed on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said reference electrode is positioned as a layer disposed above said switching element and a conductive layer which is integrally formed with said reference electrode is formed such that said conductive layer covers said switching element, and

said reference electrode is driven within a range of potential other than a potential for turning on or off said switching element.

58. A liquid crystal display device according to claim 57, wherein said switching element is constituted of a thin film transistor and said reference electrode is driven at said potential thereof which falls in a range from not less than -5 V to not more than +10 V.

59. A liquid crystal display device being characterized in that to each one of pixel regions formed on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a thin film transistor which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said thin film transistor, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said reference electrode is positioned as a layer disposed above said thin film transistor and a conductive layer which is integrally formed with said reference electrode is formed such that said conductive layer covers said thin film transistor, and

a potential of said reference voltage is inverted every one frame and a minimum value thereof is set to not less than -5 V.

60. A liquid crystal display device being characterized in that

to each one of pixel regions formed on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a thin film transistor which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said thin film transistor, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said reference electrode is positioned as a layer disposed above said thin film transistor and a conductive layer which is integrally formed with said reference electrode is formed such that said conductive layer covers said thin film transistor, and

a potential of said reference electrode is maintained substantially constant and is set within a range from not less than -5 V to not more than +10 V.

61. A liquid crystal display device according to claim 60, wherein said potential of said reference electrode is set within a range from not less than -1 V to not more than +7 V.

62. A liquid crystal display device being characterized in that

to a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a plurality of first signal lines which are extended in one direction and are arranged in parallel in the direction which intersects said one direction at a right angle and second signal lines each of which is arranged between said first signal lines and in parallel with said first signal lines are provided,

said each first signal line and neighboring first signal lines are formed into a group and one ends of respective grouped first signal lines are converged to each other and are connected to a bump of a semiconductor chip,

said second signal lines are formed such that said second signal lines are extended to a region where said first signal lines are converged and are pulled out by other wiring layer, and

said second signal lines are formed as a layer different from said respective first signal lines via an insulation film and said wiring layer is extended in the direction which intersects said one direction at a right angle.

63. A liquid crystal display device according to claim 62, wherein to each one of said pixel regions formed in a matrix

array on said liquid-crystal-side surface of said one substrate, a switching element which is driven in response to the supply of scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided, and

said first signal line is constituted of said gate signal line, said second signal line is constituted of a signal line which is connected with said reference electrode, and said wiring layer is constituted of a wiring layer which is formed as the same layer as said drain signal line.

64. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

respective regions which are surrounded by gate signal lines which are extended in the x direction and are arranged in parallel in the y direction and drain signal lines which are extended in the y direction and are arranged in parallel in the x direction are formed as said pixel regions,

a switching element which is operated in response to the supply of scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is connected to a reference signal line running in parallel to said gate signal line in the inside of said pixel region and generates an electric field between said reference electrode and said pixel electrode are provided to said each pixel region,

said reference electrode is formed as a layer different from said gate signal line, said drain signal line and said reference signal line via an insulation film and is formed such that said reference electrode is connected with said reference electrode of other neighboring pixel electrode,

said gate signal line and neighboring gate signal lines which are disposed via said reference electrode are formed into a group and one ends of respective grouped gate signal lines are converged to each other and are connected to an output bump of a semiconductor chip,

said reference signal lines are formed such that said signal lines are extended to a region where said gate signal lines are converged and are pulled out by other wiring layer, and

said other wiring layer is extended in the y direction and is integrally formed with said reference signal line.

65. A liquid crystal display device according to claim 64, wherein a plurality of said semiconductor chips are arranged in the y direction and said other wiring layer runs between an input bump and said output bump of said each semiconductor chip.

66. A liquid crystal display device being characterized in that

on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

respective regions which are surrounded by gate signal lines which are extended in the x direction and are arranged in parallel in the y direction and drain signal lines which are extended in the y direction and are arranged in parallel in the x direction are formed as said pixel regions,

a switching element which is operated in response to the supply of scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which is connected to a reference signal line running in parallel to said gate signal line in the inside of said pixel region and generates an electric field between said reference electrode and said pixel electrode are provided to said each pixel region,

said reference electrode is formed as a layer different from said gate signal, said drain signal line and said reference signal line via an insulation film and is formed such that said reference electrode is connected with said reference electrode of other neighboring pixel electrode,

said gate signal line and neighboring gate signal lines which are disposed via said reference electrode are formed into a group and one ends of respective grouped gate signal lines are converged and are connected to a bump of a semiconductor chip each other, and

among said reference signal lines, every several other signal lines which are arranged in the x direction are extended to a region where said gate signal lines are converged and are pulled out by other wiring layer,

67. A liquid crystal display device according to claim 66, wherein a plurality of said semiconductor chips are arranged in parallel in the y direction and said other wiring layer runs between an input bump and an output bump of said each semiconductor chip.

68. A liquid crystal display device according to claim 66, wherein said other wiring layer is extended toward said semiconductor chip side while turning around the outside of a bundle of said respective gate signals which is connected to said semiconductor chip and is connected to a terminal formed on a periphery of said one substrate through a lower side of said semiconductor chip.

69. A liquid crystal display device being characterized in that orientation films are formed on respective liquid-crystal-side surfaces of respective substrates which face each other in an opposed manner while sandwiching a liquid crystal therebetween, and said orientation films has a structural formula expressed by a following formula (1). (1)

70. A liquid crystal display device being characterized in that orientation films are formed on respective liquid-crystal-side surfaces of respective substrates which face each other in an opposed manner while sandwiching a liquid crystal therebetween, and said orientation films has a structural formula expressed by a following formula (2). (2)

71. A liquid crystal display device being characterized in that orientation films are formed on respective liquid-crystal-side surfaces of respective substrates which face each other in an opposed manner while sandwiching a liquid crystal therebetween, and, in said respective orientation films, materials having structural formulae expressed by

following formulae (1), (2) are contained such that said substance of said formula (1) amounts to 30% to 70% for the sum of said material expressed by said formula (1) and said material expressed by said formula (2). (2)

72. A liquid crystal display device being characterized in that on a liquid-crystal-side surface of one substrate out of respective substrates which face each other in an opposed manner while sandwiching a liquid crystal therebetween, an insulation film made of organic material, an electrode and an orientation film are sequentially formed, and

a film thickness of said electrode is set to not more than 200 nm.

73. A liquid crystal display device being characterized in that on a liquid-crystal-side surface of one substrate out of respective substrates which face each other in an opposed manner while sandwiching a liquid crystal therebetween, an insulation film made of organic material, an electrode and an orientation film are sequentially formed, and

said electrode has at least a portion thereof positioned in a recessed portion formed in said insulation film.

74. A liquid crystal display device according to claim 73, wherein assuming a film thickness of said electrode as H_1 , a height of said electrode protruded from said recessed portion as H_2 , a following formula (3) is established.

$$0 \leq (H_2 - H_1)/H_1 \leq 0.5 \quad (3)$$

75. A liquid crystal display device being characterized in that on a liquid-crystal-side surface of one substrate out of respective substrates which face each other in an opposed manner while sandwiching a liquid crystal therebetween, a first insulation film made of organic material, an electrode, a second insulation film and an orientation film are sequentially formed,

said electrode has at least a portion thereof positioned in a recessed portion formed in said first insulation film, and

assuming a film thickness of said electrode as H_1 , a height of a step of said electrode relative to said second insulation in the state that said step is exposed on a surface as H_2 , a following formula (3) is established.

$$0 \leq (H_2 - H_1)/H_1 \leq 0.5 \quad (3)$$

76. A liquid crystal display device being characterized in that on a liquid-crystal-side surface of one substrate out of respective substrates which face each other in an opposed manner while sandwiching a liquid crystal therebetween, a wiring layer, an insulation film made of organic material, an electrode which intersects said wiring layer, and an orientation film are sequentially formed, and

said electrode has portions thereof other than a portion thereof which intersects said wiring layer positioned in a recessed portion formed in said insulation layer.

77. A liquid crystal display device being characterized in that on a liquid-crystal-side surface of one substrate out of respective substrates which face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference

electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed on a protective film which covers said switching element, and said protective film is constituted of a sequential laminated body made of an inorganic material layer and an organic material layer, and

said liquid crystal includes at least one of cyano difluorine liquid crystal or trifluoro dioxane liquid crystal as a component thereof.

78. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body made of said pixel electrode, an inorganic material layer and an organic material layer, and

an amplitude of an output voltage of video signals to said drain signal line is set to not more than 7.5 V at one side thereof.

79. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body

made of said pixel electrode, an inorganic material layer and an organic material layer,

assuming a film thickness (μm) of a protective film PSV2 made of organic material as d, a distance (μm) between a pixel electrode Px and a reference electrode CT as W and a dielectric anisotropy of a liquid crystal as $\Delta\epsilon$, said d, W and $\Delta\epsilon$ are set such that Vmax expressed by a following formula (4) becomes smaller than 15 V,

$$V_{max}=1.9d+0.4146W-0.2328\Delta\epsilon+2.8218 \quad (4)$$

the supply of reference signals to said reference electrode is inverted every frame, and

an amplitude of an output voltage of video signals to said drain signal line is set to not more than 7.5 V at one side thereof.

80. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body made of said pixel electrode, an inorganic material layer and an organic material layer,

assuming a film thickness (μm) of a protective film PSV2 made of organic material as d, a distance (μm) between a pixel electrode Px and a reference electrode CT as W and a dielectric anisotropy of a liquid crystal as $\Delta\epsilon$, said d, W and $\Delta\epsilon$ are set such that Vmax expressed by a following formula (4) becomes smaller than 7.5 V,

$$V_{max}=1.9d+0.4146W-0.2328\Delta\epsilon+2.8218 \quad (4)$$

and

an amplitude of an output voltage of video signals to said drain signal line is set to not more than 7.5 V at one side thereof.

81. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference

electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body made of said pixel electrode, an inorganic material layer and an organic material layer,

assuming a film thickness (μm) of a protective film PSV2 made of organic material as d, a distance (μm) between a pixel electrode Px and a reference electrode CT as W and a dielectric anisotropy of a liquid crystal as $\Delta\epsilon$, said d, W and $\Delta\epsilon$ are set such that Vmax expressed by a following formula (4) becomes smaller than 9.375 V,

$$V_{max}=1.9d+0.4146W-0.2328\Delta\epsilon+2.8218 \quad (4)$$

and

a relative transmittivity of a liquid crystal layer at a maximum output voltage of said video signals to said drain signal line is set to not more than 90%.

82. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body made of said pixel electrode, an inorganic material layer and an organic material layer,

the supply of reference signals to said reference electrode is inverted every frame,

assuming a film thickness (μm) of a protective film PSV2 made of organic material as d, a distance (μm) between a pixel electrode Px and a reference electrode CT as W and a dielectric anisotropy of a liquid crystal as $\Delta\epsilon$, said d, W and $\Delta\epsilon$ are set such that Vmax expressed by a following formula (4) becomes smaller than 18.75 V,

$$V_{max}=1.9d+0.4146W-0.2328\Delta\epsilon+2.8218 \quad (4)$$

and

a relative transmittivity of a liquid crystal layer at a maximum output voltage of said video signals to said drain signal line is set to not more than 90%.

83. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

the supply of said video signals from said drain signal line is performed by a driver chip mounted on one substrate,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body made of said pixel electrode, an inorganic material layer and an organic material layer, and

an amplitude of an output voltage of video signals to said drain signal line is set to not more than 5V at one side thereof.

84. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

the supply of said video signal from said drain signal line is performed by a driver chip mounted on one substrate,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body made of said pixel electrode, an inorganic material layer and an organic material layer,

assuming a film thickness (μm) of a protective film PSV2 made of organic material as d, a distance (μm) between a pixel electrode Px and a reference electrode CT as W and a dielectric anisotropy of a liquid crystal as $\Delta\epsilon$, said d, W and $\Delta\epsilon$ are set such that V_{max} expressed by a following formula (4) becomes smaller than 10 V,

$$V_{max}=1.9d+0.4146W-0.2328\Delta\epsilon+2.8218 \quad (4)$$

the supply of reference signals to said reference electrode is inverted every frame, and

an amplitude of an output voltage of video signals to said drain signal line is set to not more than 5 V at one side thereof.

85. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

the supply of said video signal from said drain signal line is performed by a driver chip mounted on one substrate,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body made of said pixel electrode, an inorganic material layer and an organic material layer,

assuming a film thickness (μm) of a protective film PSV2 made of organic material as d, a distance (μm) between a pixel electrode Px and a reference electrode CT as W and a dielectric anisotropy of a liquid crystal as $\Delta\epsilon$, said d, W and $\Delta\epsilon$ are set such that V_{max} expressed by a following formula (4) becomes smaller than 5 V,

$$V_{max}=1.9d+0.4146W-0.2328\Delta\epsilon+2.8218 \quad (4)$$

the supply of reference signals to said reference electrode is inverted every frame, and

an amplitude of an output voltage of video signals to said drain signal line is set to not more than 5 V at one side thereof.

86. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

the supply of said video signal from said drain signal line is performed by a driver chip mounted on one substrate,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body

made of said pixel electrode, an inorganic material layer and an organic material layer,

assuming a film thickness (μm) of a protective film PSV2 made of organic material as d, a distance (μm) between a pixel electrode Px and a reference electrode CT as W and a dielectric anisotropy of a liquid crystal as $\Delta\epsilon$, said d, W and $\Delta\epsilon$ are set such that Vmax expressed by a following formula (4) becomes smaller than 6.25 V,

$$V_{max}=1.9d+0.4146W-0.2328\Delta\epsilon+2.8218 \quad (4)$$

and

the relative transmittivity of a liquid crystal layer at a maximum output voltage of said video signals to said drain signal line is set to not more than 90%.

87. A liquid crystal display device being characterized in that

to each pixel region on a liquid-crystal-side surface of one substrate out of substrates which are arranged to face each other in an opposed manner while sandwiching a liquid crystal therebetween,

a switching element which is operated in response to scanning signals from a gate signal line, a pixel electrode to which video signals from a drain signal line are supplied via said switching element, and a reference electrode which generates an electric field between said reference electrode and said pixel electrode are provided,

the supply of said video signal from said drain signal line is performed by a driver chip mounted on one substrate,

said liquid crystal is set to have a minimum light transmittivity in the state that said electric field is not generated between said pixel electrode and said reference electrode,

said reference electrode is formed via a protective film which is constituted of a sequential laminated body made of said pixel electrode, an inorganic material layer and an organic material layer,

assuming a film thickness (μm) of a protective film PSV2 made of organic material as d, a distance (μm) between a pixel electrode Px and a reference electrode CT as W and a dielectric anisotropy of a liquid crystal as $\Delta\epsilon$, said d, W and $\Delta\epsilon$ are set such that Vmax expressed by a following formula (4) becomes smaller than 12.5 V,

$$V_{max}=1.9d+0.4146W-0.2328\Delta\epsilon+2.8218 \quad (4)$$

the supply of reference signals to said reference electrode is inverted every frame, and

the relative transmittivity of a liquid crystal layer at a maximum output voltage of said video signals to said drain signal line is set to not more than 90%.

* * * * *

专利名称(译)	液晶显示装置		
公开(公告)号	US20020067322A1	公开(公告)日	2002-06-06
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摘要(译)

液晶显示装置可以抑制驱动器附近的液晶的局部温度上升。在基板之间的一个基板的液晶侧表面上，在将液晶夹在其间的同时以相对的方式彼此面对地布置，开关元件响应于来自栅极信号线的扫描信号而操作，通过开关元件向漏极信号线提供视频信号的像素电极，在参考电极和像素电极之间产生电场的参考电极安装在液晶侧表面的每个像素区域上。来自漏极信号线的视频信号由安装在一个基板上的驱动器芯片产生。当在像素电极和参考电极之间未施加电压时，将液晶层的透光率设定为最小值。视频信号的最大电压幅度被设定为不大于将液晶层的相对透射率设定为90%所需的电压的值。

